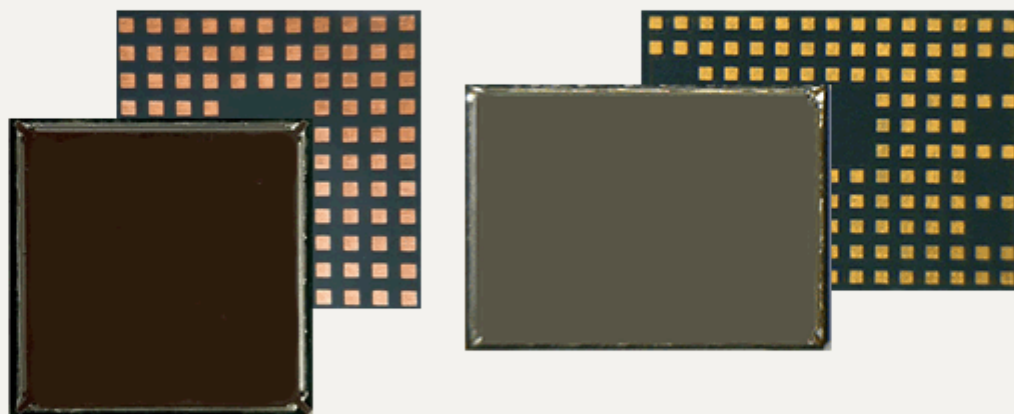


Cinterion[®] TX62/TX82

Hardware Interface Description

Version: 01.200d

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1 Introduction

This document¹ describes the hardware of the Cinterion® TX62/TX82 module variants optimized for global coverage as they support a comprehensive set of bands required for global deployment. It helps you quickly retrieve interface specifications, electrical and mechanical details and information on the requirements to be considered for integrating further components.

1.1 Product Variants

This document applies to the following Thales module variants:

- Cinterion® TX62-W (as of v01.200)
- Cinterion® TX62-W-B (as of v01.000)
- Cinterion® TX62-W-C (as of v01.000)
- Cinterion® TX82-W (as of v01.200)
- Cinterion® TX82-W-B (as of v01.200 Engineering Samples)

The following table shows the differences between the product variants. Wherever necessary a note is made to differentiate between the product variants.

Table 1: Differences between product variants

| Feature | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B |
|---------------------------|----------------|----------------|---|----------------|----------------|
| Dimensions (mm) | 15.3x15.3x 2.9 | 15.3x20.9x2.28 | 15.3x20.9x2.92 | 15.3x20.9x2.28 | 15.3x20.9x2.92 |
| GSM (2G) | -- | -- | -- | Supported | Supported |
| 450MHz bands (Bd31, Bd72) | -- | -- | Supported | -- | -- |
| RF Output Power Class | Class 5 | Class 3 | Class 2 for 450MHz bands Class 3 for all other bands | Class 5 | Class 3 |

Note: TX82-W-B is still at an early development stage and not yet officially available.

1. The document is effective only if listed in the appropriate Release Notes as part of the technical documentation delivered with your Thales product.

1.2 Key Features at a Glance

| Feature | Implementation |
|---|--|
| <i>General</i> | |
| Frequency bands (see Section 2.2.1) | <p>GSM (TX82-W and TX82-W-B): 850/900/1800/1900</p> <p>LTE Cat M1 (TX82-W, TX82-W-B, TX62-W, TX62-W-B): 700 (Bd12, Bd13, Bd28, Bd85), 800 (Bd18, Bd19, Bd20, Bd26, Bd27), 850 (Bd5), 900 (Bd8), AWS-3 (Bd66), AWS-1 (Bd4), 1800 (Bd3), 1900 (Bd2, Bd25), 2100 (Bd1)</p> <p>LTE Cat NB1/2: (TX82-W, TX82-W-B, TX62-W, TX62-W-B): 600 (Bd71; not supported with TX82-W-B), 700 (Bd12, Bd13, Bd28, Bd85), 800 (Bd18, Bd19, Bd20, Bd26), 850 (Bd5), 900 (Bd8), AWS-3 (Bd66), AWS-1 (Bd4), 1800 (Bd3), 1900 (Bd2, Bd25), 2100 (Bd1)</p> <p>LTE Cat M1 (TX62-W-C): 450 (Bd31, Bd72), 700 (Bd28), 800 (Bd20), 900 (Bd8), 1800 (Bd3), 2100 (Bd1)</p> <p>LTE Cat NB1/2 (TX62-W-C): 450 (Bd31, Bd72), 700 (Bd28), 800 (Bd20), 900 (Bd8), 1800 (Bd3), 2100 (Bd1)</p> <p>Note: With TX62-W-C support for LTE Cat NB1/2 is by default deactivated, but may be activated on demand.</p> |
| GSM class | Small MS |
| Output power (according to Release 7) | <p>GSM/GPRS (TX82-W and TX82-W-B): Class 4 (+33dBm \pm2dB) for GSM850 and GSM900 Class 1 (+30dBm \pm2dB) for GSM1800 and GSM1900 Class E2 (+27dBm \pm 3dB) for GSM850 8-PSK and GSM 900 8-PSK Class E2 (+26dBm +3 /-4dB) for GSM 1800 8-PSK and GSM1900 8-PSK</p> |
| Output power (according to 3GPP Release 13) | <p>TX62-W and TX82-W: LTE Cat M1: Class 5 (+20dBm \pm2dB) for all supported LTE Cat M1 bands</p> <p>LTE Cat NB1/2: Class 5 (+20dBm \pm2dB) for all supported LTE Cat NB1/2 bands</p> <p>TX62-W-B and TX82-W-B: LTE Cat M1: Class 3 (+23dBm \pm2dB) for all supported LTE Cat M1 bands</p> <p>LTE Cat NB1/2: Class 3 (+23dBm \pm2dB) for all supported LTE Cat NB1/2 bands</p> <p>TX62-W-C: LTE Cat M1: Class 2 (+26dBm \pm2dB) for LTE CAT M1 bands Bd31, Bd72 Class 3 (+23dBm \pm2dB) for all other supported LTE Cat M1 bands</p> <p>LTE Cat NB1/2: Class 3 (+23dBm \pm2dB) for all supported LTE Cat NB1/2 bands</p> <p>Note: The duty cycle of Cat M1 UL signal is less than 50%.</p> |

1.2 Key Features at a Glance

| Feature | Implementation |
|--|---|
| Power supply (see Section 2.1.2 and Section 3.4) | <p>TX82-W:</p> <ul style="list-style-type: none"> - LTE and GSM: 3.1V to 4.6V - LTE with GSM deactivated: 2.8V to 4.6V <p>TX82-W-B:</p> <ul style="list-style-type: none"> - LTE and GSM: 3.1V to 4.5V - LTE with GSM deactivated: 2.9V to 4.5V <p>TX62-W:</p> <ul style="list-style-type: none"> - LTE: 2.55V to 4.8V <p>TX62-W-B:</p> <ul style="list-style-type: none"> - LTE: 2.5V to 4.5V <p>TX62-W-C:</p> <ul style="list-style-type: none"> - LTE: 3.2V to 4.2V |
| Operating temperature (board temperature) (see Section 3.5) | <p>Normal operation: -30°C to +85°C</p> <p>Extended operation: -40°C to +90°C</p> |
| Physical (see Section 4.1) | <p>Dimensions:</p> <p>TX62-W: 15.3 mm x 15.3 mm x 2.9 mm</p> <p>TX82-W, TX82-W-B, TX62-W-B and TX62-W-C: 15.3 mm x 20.9 mm x 2.28 mm</p> <p>TX82-W-B, and TX62-W-C: 15.3 mm x 20.9 mm x 2.92 mm</p> <p>Weight:</p> <p>TX62-W: approx. 1g</p> <p>TX82-W, TX82-W-B, TX62-W-B and TX62-W-C: approx. 1.7g</p> |
| RoHS (see Section 5.1) | All hardware components fully compliant with EU RoHS Directive |
| LTE features | |
| 3GPP Release 14 | <p>LTE Cat M1 (HD-FDD) DL: max. 300kbps, UL: max. 1.1Mbps</p> <p>LTE Cat NB1 (HD-FDD) DL: max. 27kbps, UL: max. 63kbps</p> <p>LTE Cat NB2 (HD-FDD) DL: max. 124kbps, UL: max. 158kbps</p> |

1.2 Key Features at a Glance

| Feature | Implementation |
|--|---|
| <i>GSM/GPRS/EGPRS features</i> | |
| Data transfer | GPRS (TX82-W and TX82-W-B): <ul style="list-style-type: none"> • Multislot Class 10 • Full PBCCH support • Mobile Station Class B • Coding Scheme 1 – 4 EGPRS (TX82-W and TX82-W-B): <ul style="list-style-type: none"> • Multislot Class 10 • EDGE E2 power class for 8 PSK • Downlink coding schemes – CS 1-4, MCS 1-9 • Uplink coding schemes – CS 1-4, MCS 1-9 • SRB loopback and test mode B • 8-bit, 11-bit RACH • PBCCH support • 1 phase/2 phase access procedures • Link adaptation and IR • NACC, extended UL TBF • Mobile Station Class B |
| SMS | Point-to-point MT and MO Text and PDU mode Storage: SIM card plus SMS locations in mobile equipment |
| <i>GNSS Features</i> | |
| Modes (see Section 2.3) | Standalone GNSS (GPS, GLONASS, BeiDou, Galileo) |
| Protocol | NMEA (for GNSS related sentences) |
| General | Automatic power saving modes |
| <i>Software</i> | |
| AT commands | Hayes 3GPP TS 27.007, TS 27.005, Thales AT commands for RIL compatibility |
| Embedded processing platform (optional) | Embedded processing option with API. Memory space available for embedded applications is 512KB for application code, 512KB for File System and 672KB for RAM. Please take into account that the application code is copied into RAM. For more details, please consult software documentation. |
| SIM Application Toolkit | SAT Release 99 |
| Firmware update | Firmware update from external application over ASC0 and ASC1 interface. |
| <i>Interfaces</i> | |
| Module interface | Surface mount device with solderable connection pads (SMT application interface). Land grid array (LGA) technology ensures high solder joint reliability and allows the use of an optional module mounting socket. For more information on how to integrate SMT modules see also [5] . This application note comprises chapters on mounting and application layout issues as well as on additional SMT application development equipment. |
| USB (see Section 2.1.3) | USB 2.0 High Speed (480Mbit/s) device interface, Full Speed (12Mbit/s) compliant |

1.2 Key Features at a Glance

| Feature | Implementation |
|---|--|
| 2 serial interfaces (see Section 2.1.4 and Section 2.1.5) | ASC0: <ul style="list-style-type: none"> 8-wire modem interface with status and control lines, unbalanced, asynchronous Adjustable baud rates: 300bps to 921,600bps Supports RTS0/CTS0 hardware flow control (as configuration option). ASC1: <ul style="list-style-type: none"> 4-wire, unbalanced asynchronous modem interface Adjustable baud rates: 300bps to 921,600bps Supports RTS1/CTS1 hardware flow control (as configuration option). |
| UICC interface (see Section 2.1.6) | Supported SIM/USIM cards: 1.8V |
| eUICC interface (see Section 2.1.7) | Supports embedded MFF-XS UICC interface (as an option). |
| GPIO interface (see Section 2.1.8) | TX62-W: 6 I/O pins of the application interface programmable as GPIO. Programming can be done via AT commands. TX82-W, TX82-W-B, TX62-W-B and TX62-W-C: 7 I/O pins of the application interface programmable as GPIO. Programming can be done via AT commands. With the embedded processing option 12 (TX62-W) or 13 (TX82-W, TX82-W-B, TX62-W-B and TX62-W-C) I/O pads are programmable as GPIOs and may be shared with other functions (ASC0, ASC1/SPI, fast shutdown, and status). |
| Status (see Section 2.1.11.1) | Supports status indication LED. |
| Fast shutdown (see Section 2.1.11.3) | Supports fast shutdown interrupt signal. |
| ADC Input | Analog-to-Digital Converter with one unbalanced analog inputs |
| SIM switch (see Section 2.1.11.4) | Supports signal to switch between two externally connected SIMs. |
| Antenna interface pads (see Section 2.2) | 50Ω. GSM/LTE Main antenna, GNSS antenna |
| I ² C interface (see Section 2.1.9) | I ² C interface only available with embedded processing option. |
| SPI interface (see Section 2.1.10) | SPI interface only available with embedded processing option. |
| Power on/off, Reset | |
| Power on/off | Switch-on by hardware signal ON Switch-off by AT command and hardware signal FST_SHDN Automatic switch-off in case of critical voltage conditions |
| Reset | Orderly shutdown and reset by AT command Emergency reset by hardware signal EMERG_RST |

1.2 Key Features at a Glance

| Feature | Implementation |
|--|--|
| <i>Special features</i> | |
| Approval (see Section 5) | RED, CE, FCC, ISED, UL, RoHS, and REACH compliant GCF, PTCRB |
| Phonebook | SIM and phone |
| Cinterion® IoT Suite services | <p>(Optionally) supports an IoT Suite client based on the LWM2M protocol. The client can be configured to collect diagnostic information about the module and cellular network and to send it periodically to the Cinterion® IoT Suite server platform, where it can be visualized for further analysis.</p> <p>Communication to Thales Device Management Hub is realized using a resource-efficient protocol specifically designed by Thales in order to keep the energy and data usage to a minimum. The protocol behavior may be influenced by means of configuration.</p> <p>Additionally, the service provides device control functionality. This includes remote flash file system management, module firmware over-the-air updates (FOTA) and remote configuration.</p> <p>The Cinterion® IoT Suite also generates alarms when a specific module or network parameter changes or exceeds a threshold. Alarms can be sent to the platform as soon as possible disregarding the connection interval. For more information, please refer to [7] and [8].</p> |
| <i>Evaluation kit (For ordering information see Section 7.1)</i> | |
| LGA DevKit | LGA DevKit designed to test Thales LGA modules. For more information see also LGA DevKit . |
| Evaluation module | TX62/TX82 module soldered onto a dedicated PCB that can be connected to the an approval adapter in order to be mounted onto the DSB75 or DSB-Mini. |
| DSB75 | DSB75 Development Support Board designed to test and type approve Thales modules and provide a sample configuration for application engineering. A special adapter is required to connect the TX62/TX82 evaluation module to the DSB75. |

1.3 TX62/TX82 System Overview

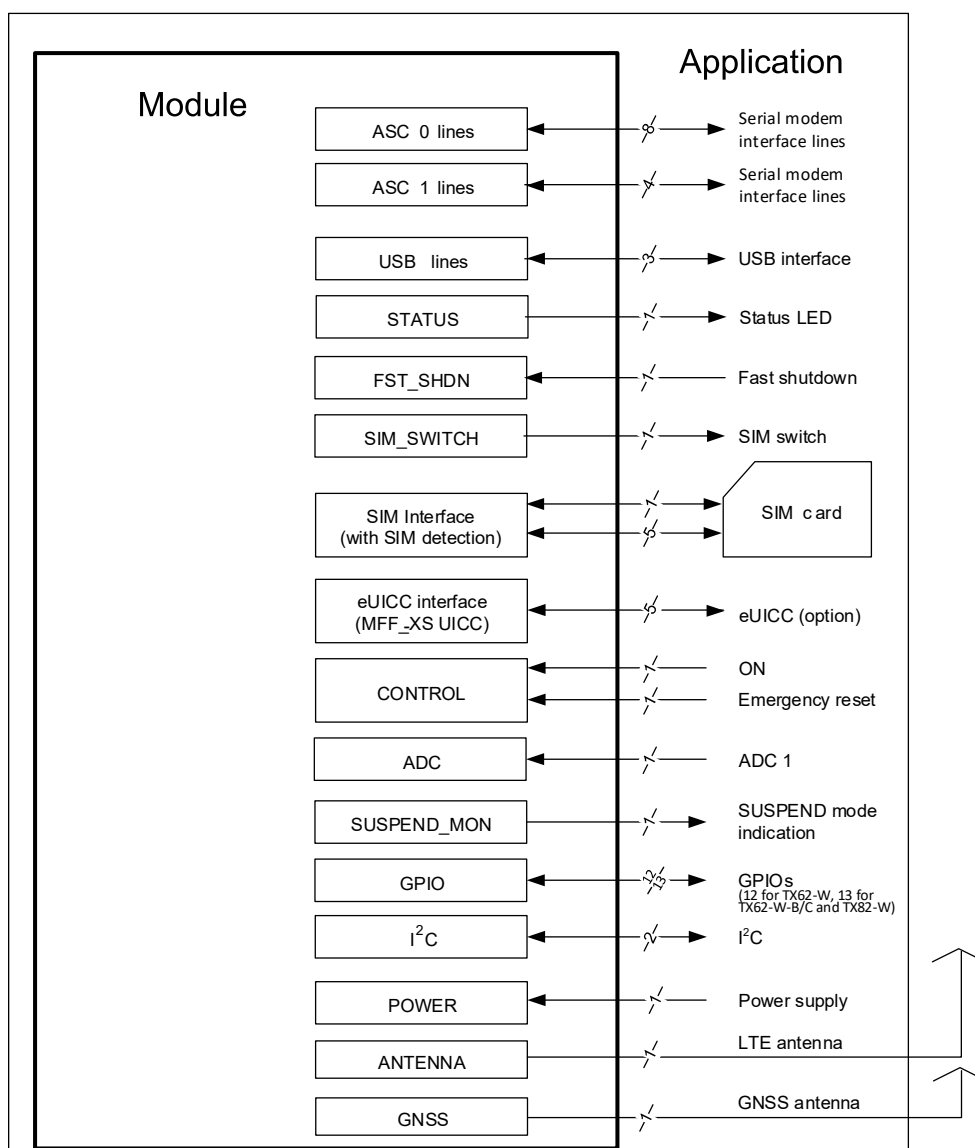


Figure 1: TX62/TX82 system overview

Please note that the I²C function and some GPIO lines are available with the embedded processing option only. Also, some GPIO lines may be shared with further functions that are also only available with the embedded processing option. For details see [Section 2.1](#), and [Section 2.1.8.1](#).

1.4 Circuit Concept

1.4 Circuit Concept

Figure 2, Figure 3, Figure 4, Figure 5 and Figure 6 show block diagrams for the TX62/TX82 module variants, and illustrate the major functional components:

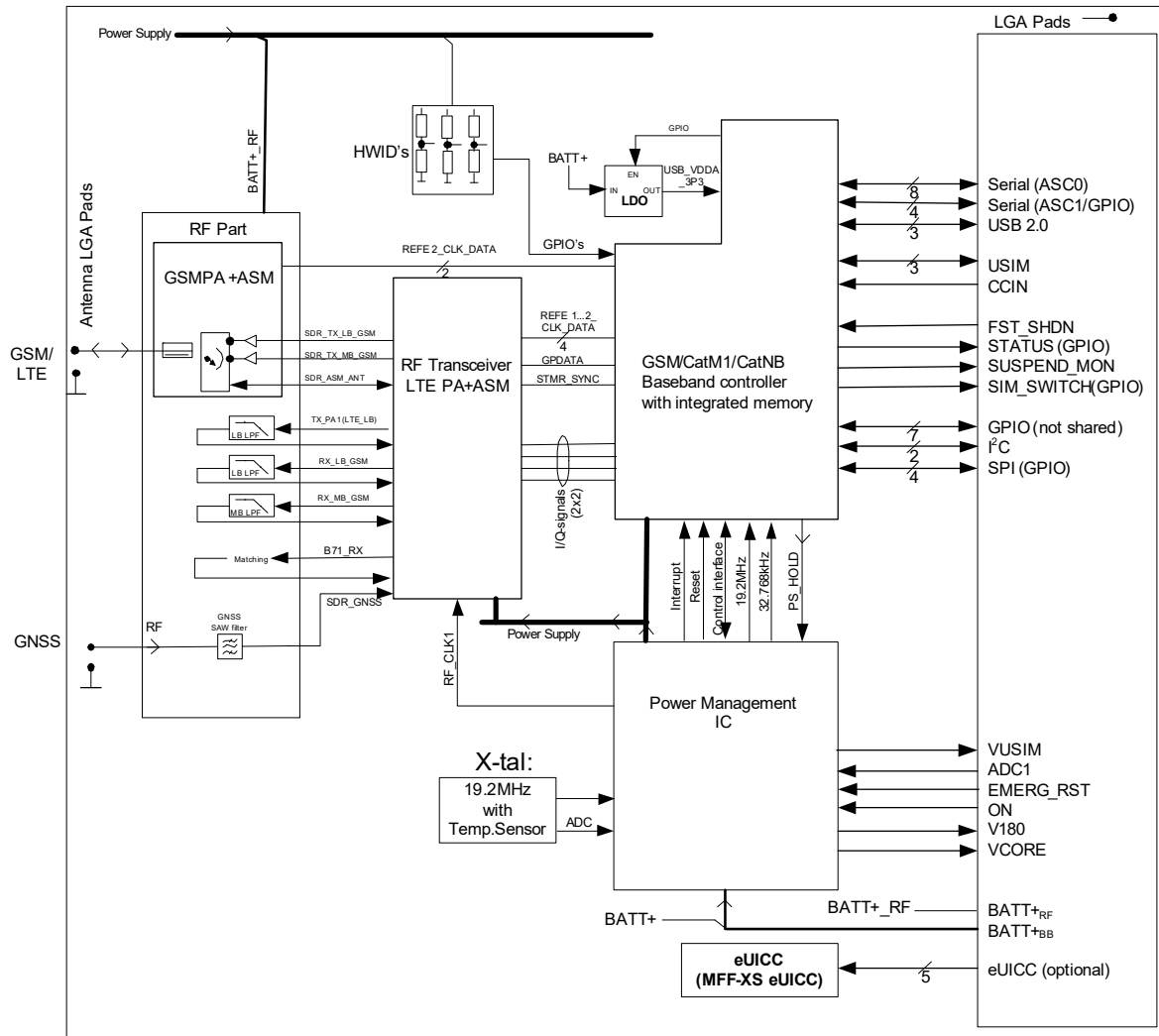


Figure 2: TX82-W block diagram

1.4 Circuit Concept

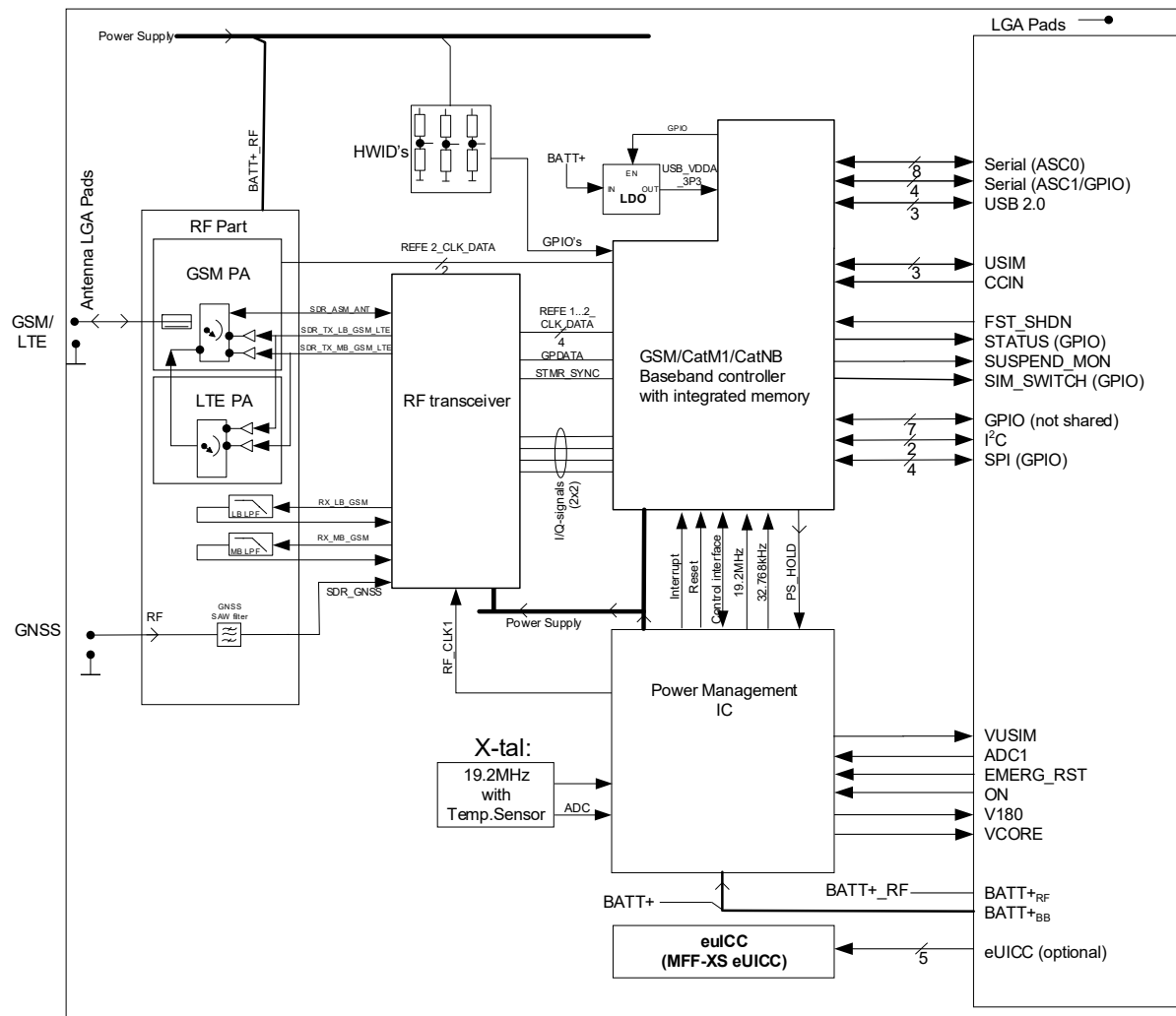


Figure 3: TX82-W-B block diagram

1.4 Circuit Concept

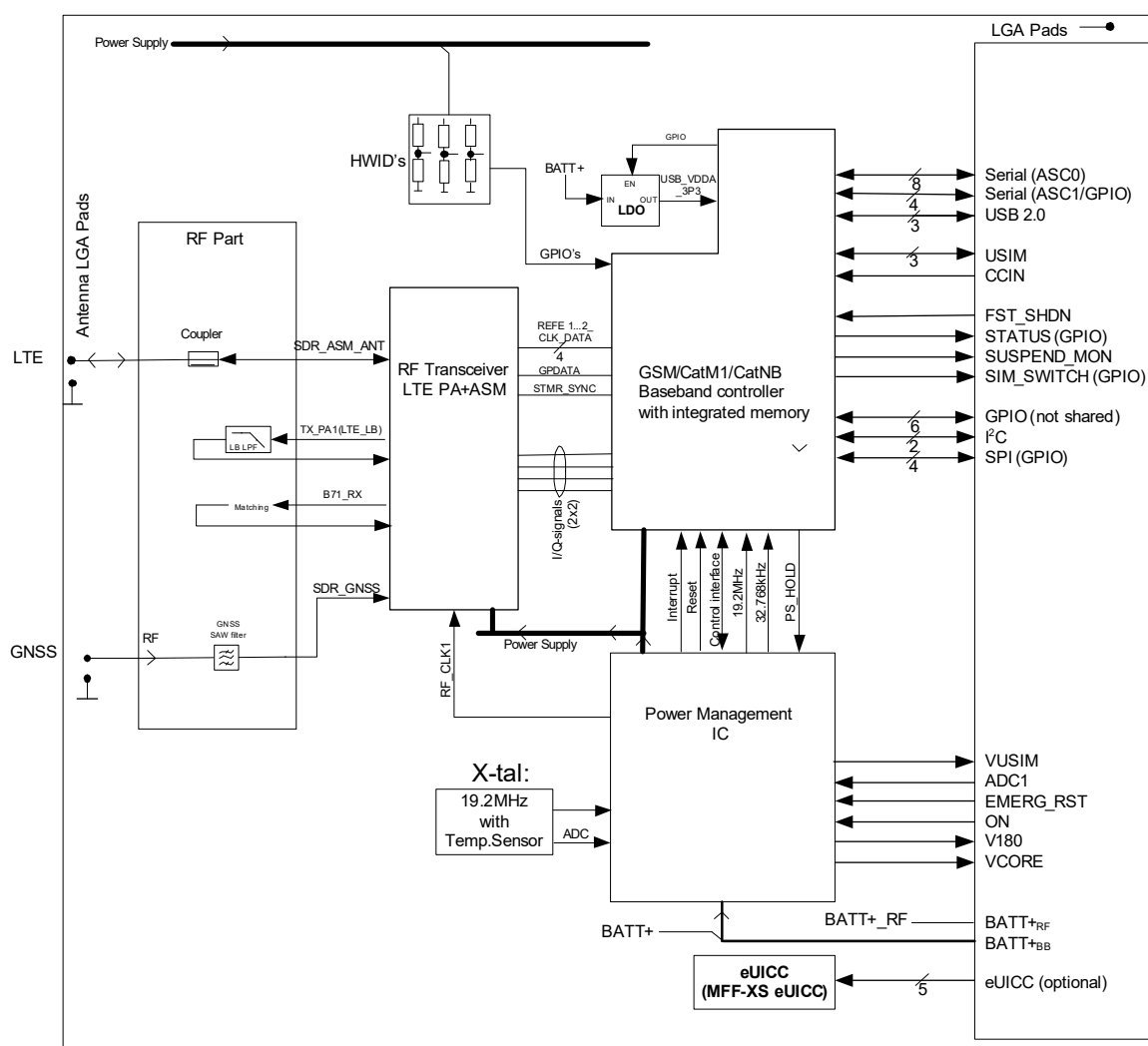


Figure 4: TX62-W block diagram

1.4 Circuit Concept

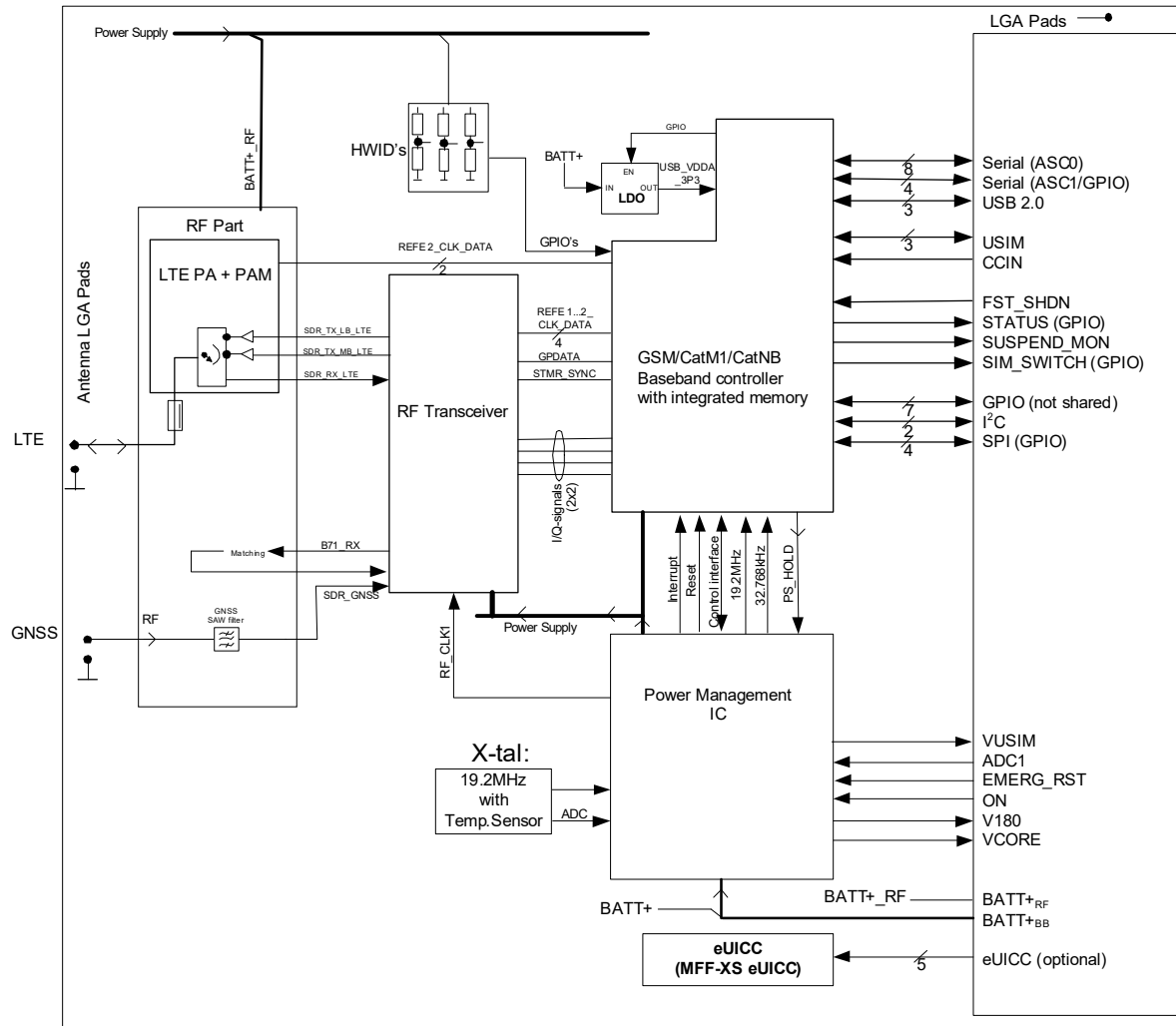


Figure 5: TX62-W-B block diagram

1.4 Circuit Concept

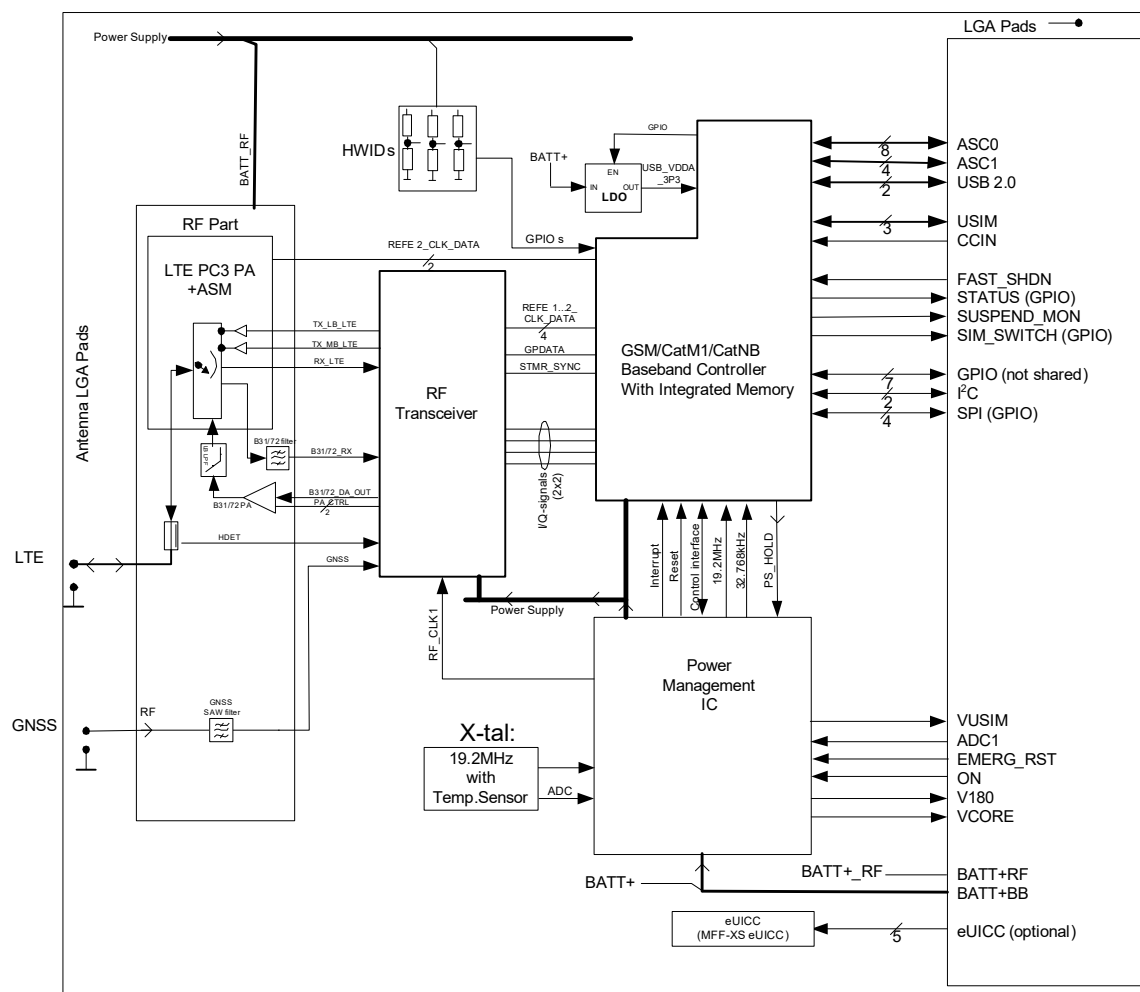


Figure 6: TX62-W-C block diagram

Please note that the I²C function and some GPIO lines are available with the embedded processing option only. Also, some GPIO lines may be shared with further functions that are also only available with the embedded processing option. For details see [Section 2.1](#), and [Section 2.1.8.1](#).

2 Interface Characteristics

TX62/TX82 is equipped with an SMT application interface that connects to the external application. The SMT application interface incorporates the various application interfaces as well as the RF antenna interface.

2.1 Application Interface

2.1.1 Pad Assignment

The SMT application interface on the TX62/TX82 provides connecting pads to integrate the module into external applications. The pads listed in [Table 2](#) apply only to TX82-W, TX82-W-B, TX62-W-B and TX62-W-C. [Table 3](#) lists the common pads of TX62/TX82. [Figure 8](#) (bottom view) and [Figure 7](#) (top view) show the connecting pads' numbering plan of TX62-W (pads inside dark violet rectangle) as well as TX82-W, TX82-W-B, TX62-W-B and TX62-W-C (pads inside light violet rectangle).

As a rule all pads should be soldered for mechanical stability and heat dissipation.

Signal pads that are not used, i.e., marked as “rfu” (reserved for future use) or “nc” (not connected), need to be soldered, but should not have an electrical connection to the external application or GND. Also, pads marked as “rfu” are further qualified as “dnu” (do not use), indicating that they are currently not supported, but internally connected for possible future usage. In addition, pads mentioned in squared brackets (I2CDAT and I2CCLK pads, SPI pads, as well as shared GPIO pads) are available with the embedded processing option only.

Please note that the reference voltages listed in [Table 4](#) are the values measured directly on the TX62/TX82 module. They do not apply to the accessories connected.

Note: Thales strongly recommends to provide test points for certain signal lines to and from the module while developing SMT applications – for debug, test and/or trace purposes during the manufacturing process. In this way it is possible to detect soldering (and other) problems. Please refer to [\[5\]](#) and [\[6\]](#) for more information on test points and how to implement them. The signal lines for which test points should be provided for are marked as “Test point recommended” in [Table 4](#).

Table 2: Overview: Pad assignments TX82-W, TX82-W-B, TX62-W-B and TX62-W-C additional pads¹

| Pad no. | Signal name | Pad no. | Signal name | Pad no. | Signal name |
|---------|-------------|---------|-------------|---------|-------------|
| B5 | GND | E18 | nc | L5 | nc |
| B6 | nc | E19 | nc | L6 | nc |
| B18 | nc | G5 | nc | L18 | nc |
| B19 | GND | G6 | rfu (dnu) | L19 | nc |
| C5 | nc | G18 | nc | M5 | GND |
| C6 | nc | G19 | nc | M6 | nc |
| C18 | nc | J5 | nc | M18 | nc |
| C19 | nc | J6 | nc | M19 | GND |
| E5 | nc | J18 | nc | | |
| E6 | GPIO6 | J19 | nc | | |

1. rfu = reserved for future use, i.e., currently not supported; dnu = do not use; nc = internally not connected

2.1 Application Interface

Table 3: Overview: Pad assignments common to TX62/TX82^{1 2}

| Pad no. | Signal name | Pad no. | Signal name | Pad no. | Signal name |
|---------|--------------------|---------|---------------------------------|---------|----------------------|
| B7 | GND | E12 | rfu (dnu) | J15 | V180 |
| B8 | GND | E13 | rfu (dnu) | J16 | GND |
| B9 | GNSS_ANT | E14 | GND | J17 | CC2_VPP |
| B10 | GND | E15 | EMERG_RST | K7 | nc |
| B11 | GND | E16 | VCORE | K8 | RTS1 [GPIO18/SPI_CS] |
| B12 | RF_OUT | E17 | nc | K9 | STATUS [GPIO5] |
| B13 | GND | F7 | GND | K10 | FST_SHDN |
| B14 | GND | F8 | GPIO25 | K11 | nc |
| B15 | rfu (dnu) | F9 | SUSPEND_MON | K12 | RING0 |
| B16 | GND | F10 | GND | K13 | DTR0 |
| B17 | GND | F11 | rfu (dnu) | K14 | DCD0 |
| C7 | rfu (dnu) | F12 | rfu (dnu) | K15 | CCCLK |
| C8 | SIM_SWITCH [GPIO8] | F13 | rfu (dnu) | K16 | rfu (dnu) |
| C9 | GND | F14 | GND | K17 | CC2_CLK |
| C10 | GND | F15 | ADC1 | L7 | nc |
| C11 | GND | F16 | nc | L8 | TXD1 [GPIO17/MISO] |
| C12 | GND | F17 | GND | L9 | VUSB_IN |
| C13 | GND | G7 | nc | L10 | rfu (dnu) |
| C14 | GND | G8 | GPIO20 | L11 | DSR0 |
| C15 | GND | G9 | nc | L12 | RTS0 |
| C16 | GND | G10 | GND | L13 | CTS0 |
| C17 | nc | G14 | GND | L14 | CCVCC |
| D7 | rfu (dnu) | G15 | BATT ³ _{RF} | L15 | CCRST |
| D8 | GPIO22 | G16 | BATT ³ _{RF} | L16 | CC2_VCC |
| D9 | nc | G17 | nc | L17 | CC2_RST |
| D10 | GND | H7 | nc | M7 | GND |
| D11 | GND | H8 | GPIO23 | M8 | GND |
| D12 | GND | H9 | [I2CDAT] | M9 | USB_DP |
| D13 | GND | H10 | [I2CCLK] | M10 | USB_DN |
| D14 | GND | H14 | GND | M11 | GND |
| D15 | ON | H15 | BATT ³ _{BB} | M12 | RXD0 |
| D16 | nc | H16 | BATT ³ _{BB} | M13 | TXD0 |
| D17 | nc | H17 | nc | M14 | CCIO |
| E7 | GPIO7 | J7 | nc | M15 | CCIN |
| E8 | GPIO21 | J8 | CTS1 [GPIO19/SPI_CLK] | M16 | CC2_IO |
| E9 | rfu (dnu) | J9 | RXD1 [GPIO16/MOSI] | M17 | GND |
| E10 | GND | J10 | GND | | |
| E11 | rfu (dnu) | J14 | rfu (dnu) | | |

1. rfu = reserved for future use, i.e., currently not supported; dnu = do not use; nc = internally not connected

2. Pads mentioned in squared brackets (I2CDAT and I2CCLK pads, SPI pads as well as shared GPIO pads) are available with the embedded processing option only.

3. Available with TX82-W, TX82-W-B, TX62-W-B, TX62-W-C. Internally not connected with TX62-W.

2.1 Application Interface

| | 19 | 18 | 17 | 16 | 15 | 14 | 13 | 12 | 11 | 10 | 9 | 8 | 7 | 6 | 5 |
|---|-----|-----------|---------|---------------------------------|---------------------------------|-------|----------------------------|-----------|-----------|-----------|---------------------------|------------------------------|-----------|-------|-----|
| M | GND | nc | GND | CC2_IO | CCIN | CCIO | TXD0 | RXD0 | GND | USB_DN | USB_DP | GND | GND | nc | GND |
| L | nc | nc | CC2_RST | CC2_VCC | CCRST | CCVCC | CTS0 | RST0 | DSR0 | rfu (dnu) | VUSB_IN | TXD1 [GPIO17/ MISO] | nc | nc | nc |
| K | | | CC2_CLK | rfu (dnu) | CCCLK | DCD0 | DTR0 | RING0 | nc | FST_SHDN | STATUS [GPIO5] | RTS1 [GPIO18/ SPI_CS] | nc | | |
| J | nc | nc | CC2_VPP | GND | V180 | nc | Reserved for future use | | | GND | RXD1 [GPIO16/ MOSI] | CTS1 [GPIO19/ SPI_CLK] | nc | nc | nc |
| H | | | nc | BATT _{BB} ⁺ | BATT _{BB} ⁺ | GND | | | | [I2CCCLK] | [I2CDAT] | GPIO23 | nc | | |
| G | nc | nc | nc | BATT _{RF} ⁺ | BATT _{RF} ⁺ | GND | Marking | | | GND | nc | GPIO20 | nc | | |
| F | | | GND | nc | ADC1 | GND | rfu (dnu) | rfu (dnu) | rfu (dnu) | GND | SUSPEND_MON | GPIO25 | GND | | |
| E | nc | nc | nc | VCORE | EMERG_RST | GND | rfu (dnu) | rfu (dnu) | rfu (dnu) | GND | rfu (dnu) | GPIO21 | GPIO7 | GPIO6 | nc |
| D | | | nc | nc | ON | GND | GND | GND | GND | GND | nc | GPIO22 | rfu (dnu) | | |
| C | nc | nc | nc | GND | GND | GND | GND | GND | GND | GND | GND | SIM_SWITCH [GPIO8] | rfu (dnu) | nc | nc |
| B | GND | rfu (dnu) | GND | GND | nc | GND | GND | RF_OUT | GND | GND | GNSS_ANT | GND | GND | nc | GND |

Figure 7: TX62/TX82 top view: Pad assignments

2.1 Application Interface

| | 5 | 6 | 7 | 8 | 9 | 10 | 11 | 12 | 13 | 14 | 15 | 16 | 17 | 18 | 19 |
|---|-----|-----------|-----------|------------------------------|---------------------------|-----------|---|-----------|-----------|-------|---------------------|---------------------|---------|-----|------|
| M | GND | nc | GND | GND | USB_DP | USB_DN | GND | RXD0 | TXD0 | CCIO | CCIN | CC2_IO | GND | nc | GND |
| L | nc | nc | nc | TXD1 [GPIO17/ MISO] | VUSB _IN | rfu (dnu) | DSR0 | RST0 | CTS0 | CCVCC | CCRST | CC2_VCC | CC2_RST | nc | nc |
| K | | | nc | RTS1 [GPIO18/ SPI_CS] | STATUS [GPIO5] | FST_SHDN | nc | RING0 | DTR0 | DCD0 | CCCLK | rfu (dnu) | CC2_CLK | | |
| J | nc | nc | nc | CTS1 [GPIO19/ SPI_CLK] | RXD1 [GPIO16/ MOSI] | GND | Reserved for future use Marking | | | nc | V180 | GND | CC2_VPP | nc | nc |
| H | | | nc | GPIO23 | [I2CDAT] | [I2CCLK] | | | | GND | BATT+ _{BB} | BATT+ _{BB} | nc | | |
| G | nc | rfu (dnu) | nc | GPIO20 | nc | GND | | | | GND | BATT+ _{RF} | BATT+ _{RF} | nc | | |
| F | | | GND | GPIO25 | SUSPEND _MON | GND | rfu (dnu) | rfu (dnu) | rfu (dnu) | GND | ADC1 | nc | GND | | |
| E | nc | GPIO6 | GPIO7 | GPIO21 | rfu (dnu) | GND | rfu (dnu) | rfu (dnu) | rfu (dnu) | GND | EMERG _RST | VCORE | nc | nc | nc |
| D | | | rfu (dnu) | GPIO22 | nc | GND | GND | GND | GND | GND | ON | nc | nc | | |
| C | nc | nc | rfu (dnu) | SIM SWITCH [GPIO8] | GND | GND | GND | GND | GND | GND | GND | GND | nc | nc | nc |
| B | GND | nc | GND | GND | GNSS _ANT | GND | GND | RF_OUT | GND | GND | nc | nc | GND | GND | ADC2 |

Figure 8: TX62/TX82 bottom view: Pad assignments

2.1.2 Signal Properties

Table 4: Signal properties


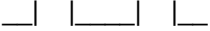
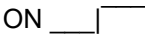
| Function | Signal name | IO | Signal form and level | Comment |
|--------------|--|----|--|---|
| Power supply | BATT+ _{BB} BATT+ _{RF} | I | <p><i>Normal voltage range:</i></p> <p>TX82-W (LTE and GSM): $V_{Imin} = 3.1\text{ V} \dots V_{Imax} = 4.6\text{ V}$ during Tx burst on board</p> <p>$I_{max} = 2\text{ A}$, during Tx burst (GSM) </p> <p>$N\text{ Tx} = n * 577\mu\text{s}$ peak current every 4.616ms</p> <p>TX82-W (LTE with GSM deactivated): $V_{Imin} = 2.8\text{ V} \dots V_{Imax} = 4.6\text{ V}$</p> <p>TX82-W-B (LTE and GSM): $V_{Imin} = 3.1\text{ V} \dots V_{Imax} = 4.5\text{ V}$ during Tx burst on board</p> <p>$I_{max} = 2\text{ A}$, during Tx burst (GSM) </p> <p>$N\text{ Tx} = n * 577\mu\text{s}$ peak current every 4.616ms</p> <p>TX82-W-B (LTE with GSM deactivated): $V_{Imin} = 2.9\text{ V} \dots V_{Imax} = 4.5\text{ V}$</p> <p>TX62-W (LTE): $V_{Imin} = 2.55\text{ V} \dots V_{Imax} = 4.8\text{ V}$</p> <p>TX62-W-B (LTE): $V_{Imin} = 2.5\text{ V} \dots V_{Imax} = 4.5\text{ V}$</p> <p>TX62-W-C (LTE): $V_{Imin} = 3.2\text{ V} \dots V_{Imax} = 4.2\text{ V}$</p> <p>All products: $V_{Inorm} = 3.8\text{ V}$</p> <p>$I_{Power\ Down} = 14\mu\text{ A}$</p> <p><i>Extended voltage range:</i></p> <p>All products: $V_{Imin} = 2.5\text{ V} \dots V_{Imax} = 4.8\text{ V}$</p> | <p>Lines of BATT+ and GND must be connected in parallel for supply purposes because higher peak currents may occur.</p> <p>BATT+_{BB} at solder pads needs an additional low ESR 47μF capacitor (e.g, X7R MLCC, taking DCbias into account).</p> <p>BATT+_{RF} at solder pads needs an additional low ESR 150μF capacitor (e.g, X7R MLCC, taking DCbias into account) - except for TX62-W, as in this case BATT+RF is internally not connected.</p> <p>A minimum ESR value <70mΩ is recommended.</p> <p>Minimum voltage must not fall below the specified normal minimum voltage including drops, ripple, spikes. Else the module may perform an uncontrolled shutdown.</p> <p>However, if using the extended voltage range, i.e., down to 2.5V or up to 4.8V, the module remains fully functional and safe while possibly no longer being fully compliant with 3GPP or other wireless standards. Please note that the module is in this case switched on at a voltage of >2.65V.</p> <p>Please note that if both voltage domains and power supply lines are referred to - i.e., BATT+_{BB} and BATT+_{RF} - BATT+ is used throughout the document.</p> |
| Power supply | GND | | Ground | Application Ground |

Table 4: Signal properties

| Function | Signal name | IO | Signal form and level | Comment |
|-------------------------|-------------|----|---|--|
| External supply voltage | V180 | O | <p>Normal operation: $V_{O\text{norm}} = 1.80V \pm 2\%$ $I_{O\text{max}} = 10\text{mA}$</p> <p>SLEEP mode Operation: $V_{O\text{Sleep}} = 1.80V \pm 3.7\%$ $I_{O\text{max}} = 10\text{mA}$</p> <p>SUSPEND mode Operation: $V_{O\text{Suspend}} = 0V$</p> <p>$C_{I\text{max}} = 1\mu\text{F}$</p> | <p>V180 has to be used for the power indication circuit.</p> <p>V180 can also be used to supply level shifters at the interfaces.</p> <p>Test point recommended¹.</p> |
| | VCORE | O | <p>Normal Operation: $V_{O\text{nom}} = 1.128V \pm 2\%$ $I_{O\text{max}} = 10\text{mA}$</p> <p>SLEEP Mode Operation: $V_{O\text{sleep}} = 0.5V \dots 1.304V \pm 3\%$ $I_{O\text{max}} = 10\text{mA}$</p> <p>SUSPEND Mode Operation: $V_{O\text{suspend}} = 0V$</p> <p>$C_{I\text{max}} = 100\text{nF}$</p> | Test point recommended. |
| Ignition | ON | I | <p> $V_{IH\text{max}} = \text{BATT}^{+}_{\text{BB}}$ $V_{IH\text{min}} = 1.3V$ $V_{IL\text{max}} = 0.5V$ High level pulse width > 30ms </p> <p>ON </p> | <p>This signal switches the module on.</p> <p>The ON signal is low to high edge sensitive triggered, and requires a 10k pull down resistor.</p> <p>Test point recommended.</p> |
| Status | STATUS | O | <p> $V_{OL\text{max}} = 0.45V$ at $I = 4.5\text{ mA}$ $V_{OH\text{min}} = 1.20V$ at $I = 2.5\text{ mA}$ $V_{OH\text{max}} = 1.95V$ </p> | <p>If unused keep lines open.</p> <p>With the embedded processing option this line is also available as GPIO: STATUS --> GPIO5</p> |
| Fast shut-down | FST_SHDN | I | <p> $V_{IL\text{max}} = 0.5V$ $V_{IH\text{min}} = 1.3V$ $V_{IH\text{max}} = 1.95V$ </p> <p>$C_{I\text{max}} = 50\text{pF}$</p> | <p>If unused keep lines open.</p> <p>Fast shutdown period <15ms.</p> |

2.1 Application Interface

Table 4: Signal properties


| Function | Signal name | IO | Signal form and level | Comment |
|-----------------------------|-------------|-----|---|--|
| Emergency reset | EMERG_RST | I | $R_I \approx 1\text{k}\Omega$, $C_I \approx 1\text{nF}$ (internal low pass filter) $V_{IH\text{min}} = 1.3\text{V}$ $V_{IL\text{max}} = 0.5\text{V}$ at $\sim 1\mu\text{A}$  low impulse width > 800ms | This line must be driven low by an open drain or open collector driver connected to GND. If unused keep lines open. Test point recommended. |
| USB | VUSB_IN | I | $V_{I\text{min}} = 4\text{V}$ $V_{I\text{max}} = 5.25\text{V}$ Active and suspend current: $I_{\text{max}} < 100\mu\text{A}$ | All electrical characteristics according to USB Implementers' Forum, USB 2.0 Specification. If unused keep lines open. |
| | USB_DN | I/O | Full and high speed signal characteristics according USB 2.0 Specification. | Used for tracing purposes only. Test points recommended. |
| | USB_DP | | | |
| Serial Modem Interface ASC0 | RXD0 | O | $V_{OL\text{max}} = 0.45\text{V}$ at $I = 4.5\text{ mA}$ $V_{OH\text{min}} = 1.20\text{V}$ at $I = 2.5\text{ mA}$ $V_{OH\text{max}} = 1.95\text{V}$ | If unused keep lines open. RTS0 can be used to wakeup the module from SLEEP mode, but not from SUSPEND/PSM mode. |
| | CTS0 | O | | |
| | DSR0 | O | | |
| | DCD0 | O | | |
| | RING0 | O | | |
| | TXD0 | I | $V_{IL\text{max}} = 0.5\text{V}$ $V_{IH\text{min}} = 1.3\text{V}$ $V_{IH\text{max}} = 1.95\text{V}$ | Test points recommended for RXD0, TXD0, RTS0, and CTS0. |
| | RTS0 | I | | |
| | DTR0 | I | | |
| Serial Modem Interface ASC1 | RXD1 | O | $V_{OL\text{max}} = 0.45\text{V}$ at $I = 4.5\text{ mA}$ $V_{OH\text{min}} = 1.20\text{V}$ at $I = 2.5\text{ mA}$ $V_{OH\text{max}} = 1.95\text{V}$ | If unused keep lines open. |
| | CTS1 | O | | |
| | TXD1 | I | $V_{IL\text{max}} = 0.5\text{V}$ $V_{IH\text{min}} = 1.3\text{V}$ $V_{IH\text{max}} = 1.95\text{V}$ | Test points recommended for RXD1, TXD1, RTS1, and CTS1. With embedded processing option ASC1 lines are shared with SPI interface lines, see Section 2.1.8 . |
| | RTS1 | I | | |

Table 4: Signal properties

| Function | Signal name | IO | Signal form and level | Comment |
|-------------------------|----------------|--------|--|---|
| SIM card detection | CCIN | I | Internal pull down resistor: 100k $R_I \approx 110k\Omega$ $V_{ILmax} = 0.5V$ $V_{IHmin} = 1.3V$ $V_{IHmax} = 1.95V$ | CCIN = High, SIM card inserted. If unused keep line open. |
| 1.8V SIM Card Interface | CCVCC | O | $V_{Omin} = 1.5V$ $V_{Otyp} = 1.8V$ $V_{Omax} = 2V$ $I_{Omax} = -60mA$ | Maximum cable length or copper track to SIM card holder should not exceed 100mm. |
| | CCRST CCCLK | O O | $V_{OLmax} = 0.45V$ at $I = 4.5\text{ mA}$ $V_{OHmin} = 1.20V$ at $I = 2.5\text{ mA}$ $V_{OHmax} = 1.95V$ | For more information on how to connect the SIM interface pads including possible external capacitors and ESD protection please refer to Section 2.1.6 . |
| | CCIO | I/O | $V_{OLmax} = 0.45V$ at $I = 4.5\text{ mA}$ $V_{OHmin} = 1.20V$ at $I = 2.5\text{ mA}$ $V_{OHmax} = 1.95V$ $V_{ILmax} = 0.5V$ $V_{IHmin} = 1.3V$ $V_{IHmax} = 1.95V$ | |

Table 4: Signal properties

| Function | Signal name | IO | Signal form and level | Comment |
|----------------------|-------------|-----|--|---|
| 1.8V eUICC interface | CC2_VPP | -- | Used for single wire protocol (SWP NFC) in MFF-XS eUICC. | SWP NFC is currently not supported and deactivated for the eUICC. Thus, there are two options: If an external SWP master is connected nevertheless (or for future use) the CC2_VPP line should be pulled up by an external 10k resistor to VCC. If there is no plan to use SWP the CC2_VPP line can be grounded. |
| | CC2_VCC | I | $V_{Imin} = 1.62V$ $V_{Ityp} = 1.8V$ $V_{Imax} = 1.98V$ | Maximum cable length or copper track should be no longer as 100mm to eUICC interface. |
| | CC2_CLK | I | $V_{ILmax} = 0.2 \cdot CC2_VCC$ (at $I_{OLmax} = -200\mu A$) $V_{ILmin} = -0.3V$ (at $I_{OLmax} = -200\mu A$) $V_{IHmax} = CC2_VCC + 0.3V$ (at $I_{OHmax} = +20\mu A$) $V_{IHmin} = 0.8 \cdot CC2_VCC$ (at $I_{OHmax} = +20\mu A$) | The signals CC2_RST, CC2_IO, CC2_CLK and CC2_VCC are protected against ESD with a special diode array. |
| | CC2_RST | I | $V_{ILmax} = 0.2 \cdot CC2_VCC$ (at $I_{OLmax} = -20\mu A$) $V_{ILmin} = -0.3V$ (at $I_{OLmax} = -20\mu A$) $V_{IHmax} = CC2_VCC + 0.3V$ (at $I_{OHmax} = +20\mu A$) $V_{IHmin} = 0.7 \cdot CC2_VCC$ (at $I_{OHmax} = +20\mu A$) | If unused keep lines open. |
| | CC2_IO | I/O | $V_{ILmax} = 0.2 \cdot CC2_VCC$ (at $I_{IH} = +1mA/+20\mu A$) $V_{ILmin} = -0.3V$ (at $I_{IH} = +1mA/+20\mu A$) $V_{IHmin} = 0.7 \cdot CC2_VCC$ (at $I_{IH} = -20/+20\mu A$) $V_{IHmax} = CC2_VCC + 0.3V$ (at $I_{IH} = -20/+20\mu A$) $V_{OLmax} = 0.15 \cdot CC2_VCC$ (at $I_{OL} = -1mA$) $V_{OHmin} = 0.7 \cdot CC2_VCC$ (at $I_{IH} = -20/+20\mu A$) $V_{OHmax} = CC2_VCC + 0.3V$ (at $I_{IH} = -20/+20\mu A$) | |
| SIM switch | SIM_SWITCH | O | $V_{OLmax} = 0.45V$ at $I = 4.5 mA$ $V_{OHmin} = 1.20V$ at $I = 2.5 mA$ $V_{OHmax} = 1.95V$ | If unused keep lines open. With embedded processing option SIM_SWITCH is shared with GPIO8, see Section 2.1.8 . |

Table 4: Signal properties

| Function | Signal name | IO | Signal form and level | Comment |
|-----------------------------------|------------------------------------|-----|---|---|
| I ² C | I2CDAT | I/O | No internal pull up resistors | If unused keep lines open. |
| | I2CCLK | O | $V_{OLmax} = 0.45V$ at $I_{max} = -4.5mA$ $V_{OHmax} = 1.95V$ $V_{ILmax} = 0.5V$ $V_{IHmin} = 1.3V$ $V_{IHmax} = 1.95V$ Note: $I_{max} = I_{max\ external} + I_{pull\ up}$ | Compatible with I ² C Bus Specification Version 5.0. Multimaster is not supported. The value of the pull-up depends on the capacitive load of the whole system (I ² C Slave + lines). Only available with embedded processing option. |
| GPIO | GPIO6-GPIO7, GPIO20-GPIO23, GPIO25 | I/O | $V_{OLmax} = 0.45V$ at $I = 4.5\ mA$ $V_{OHmin} = 1.20V$ at $I = 2.5\ mA$ $V_{OHmax} = 1.95V$ $V_{ILmax} = 0.5V$ $V_{IHmin} = 1.3V$ $V_{IHmax} = 1.95V$ | If unused keep lines open. GPIO6 only available on TX82-W, TX82-W-B, TX62-W-B and TX62-W-C. Further GPIOs shared with other functions are available with embedded processing option (see Section 2.1.8). |
| SPI | SPI_CLK | O | $V_{OLmax} = 0.45V$ at $I = 4.5mA$ | Shared with ASC1 function (see Section 2.1.8). Only available with embedded processing option. |
| | SPI_MOSI | O | $V_{OHmin} = 1.20V$ at $I = 2.5mA$ | |
| | SPI_MISO | I | $V_{OHmax} = 1.95V$ | |
| | SPI_CS | O | $V_{ILmax} = 0.5V$ $V_{IHmin} = 1.3V$ $V_{IHmax} = 1.95V$ | |
| ADC (Analog-to-Digital Converter) | ADC1 | I | $R_I = 10M\Omega$ $V_I = 0.1V \dots 1.875V$ (valid range) $V_{IHmax} = 1.910V$ Resolution 64.979uV | If unused keep line open. |
| SUSPEND mode indicator | SUSPEND_MON | O | $V_{OLmax} = 0.45V$ at $I = 4.5\ mA$ $V_{OHmin} = 1.20V$ at $I = 2.5\ mA$ $V_{OHmax} = 1.95V$ | High=Normal mode, Low=SUSPEND mode. If unused keep lines open. |

1. Thales strongly recommends to provide test points for certain signal lines to and from the module while developing SMT applications – for debug, test and/or trace purposes during the manufacturing process. In this way it is possible to detect soldering (and other) problems. Please refer to [5] and [6] for more information on test points and how to implement them. The signal lines for which test points should be provided for are marked as “Test point recommended” in the above table.

2.1.2.1 Absolute Maximum Ratings

The absolute maximum ratings stated in [Table 5](#) are stress ratings under any conditions. Stresses beyond any of these limits will cause permanent damage to TX62/TX82.

Table 5: Absolute maximum ratings

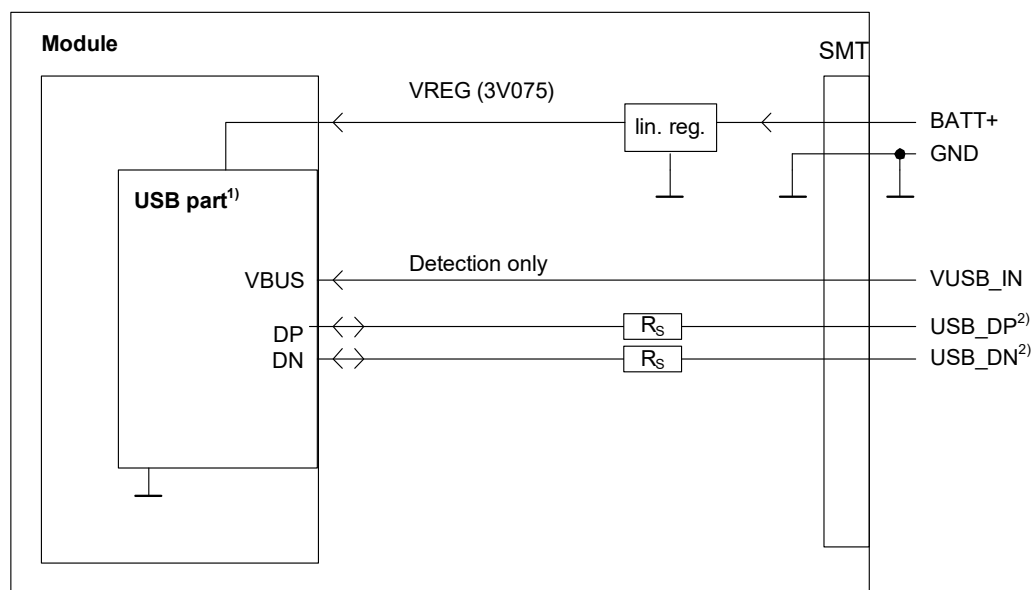
| Parameter | | Min | Max | Unit |
|---|------------------------|------|--------|------|
| Supply voltage BATT+ _{BB} (no service) | | -0.5 | +6.0 | V |
| Supply voltage BATT+ _{RF} (not available with TX62-W) | (TX82-W; no service) | -0.5 | +6.0 | V |
| | (TX82-W-B; no service) | -0.5 | +5.0 | V |
| | (TX62-W-B; no service) | -0.5 | +6.0 | V |
| | (TX62-W-C; no service) | -0.5 | +5.0 | V |
| Voltage at all digital lines in Power Down mode | | -0.5 | +0.5 | V |
| Voltage at digital lines 1.8V domain in normal operation ¹ | | -0.3 | +2.09 | V |
| Current at digital lines in normal operation | | -5 | +5 | mA |
| Voltage at SIM interface, CCVCC 1.8V in normal operation | | -0.3 | +2.0 | V |
| Current at SIM interface in normal 1.8V operation | | - | -600 | mA |
| Voltage at ADC line in normal operation | | -0.5 | +1.910 | V |
| V180 in normal operation | | -0.3 | +2.09 | V |
| Current at V180 in normal operation | | - | -600 | mA |
| VCORE in normal operation | | +0.5 | +1.304 | V |
| Current at VCORE in normal operation | | - | -1200 | mA |
| Voltage at USB lines | | -0.5 | 5.75 | V |

1. A maximum rating of 1.95V (for $V_{IH,max}$) is recommended for all digital lines. Exceeding this value however will not necessarily harm the module as long as the rating remains below the absolute maximum rating of 1.95+0.14V, but it will decrease the safety margin in case of short spikes or ripple.

2.1.3 USB Interface

TX62/TX82 supports a USB 2.0 High Speed (480Mbit/s) device interface that is Full Speed (12Mbit/s) compliant.

The external application is responsible for supplying the VUSB_IN line. This line is used for cable detection only. The USB part (driver and transceiver) is supplied by means of BATT+. This is because TX62/TX82 is designed as a self-powered device compliant with the “Universal Serial Bus Specification Revision 2.0”¹.



¹) All serial (including R_s) and pull-up resistors for data lines are implemented.

²) If the USB interface is operated in High Speed mode (480MHz), it is recommended to take special care routing the data lines USB_DP and USB_DN. Application layout should in this case implement a differential impedance of 90 ohms for proper signal integrity.

Figure 9: USB circuit

To properly connect the module's USB interface to the external application, a USB 2.0 compatible connector and cable or hardware design is required. For more information on the USB related signals see [Table 4](#). Furthermore, the USB modem driver distributed with TX62/TX82 needs to be installed.

1. The specification is ready for download on <https://www.usb.org/document-library/usb-20-specification>

2.1.4 Serial Interface ASC0

TX62/TX82 offers an 8-wire unbalanced, asynchronous modem interface ASC0 conforming to ITU-T V.24 protocol DCE signaling. The electrical characteristics do not comply with ITU-T V.28. The significant levels are 0V (for low data bit or active state) and 1.8V (for high data bit or inactive state). For electrical characteristics please refer to [Table 4](#). For an illustration of the interface line's startup behavior see [Figure 11](#).

TX62/TX82 is designed for use as a DCE. Based on the conventions for DCE-DTE connections it communicates with the customer application (DTE) using the following signals:

- Port TXD @ application sends data to the module's TXD0 signal line
- Port RXD @ application receives data from the module's RXD0 signal line

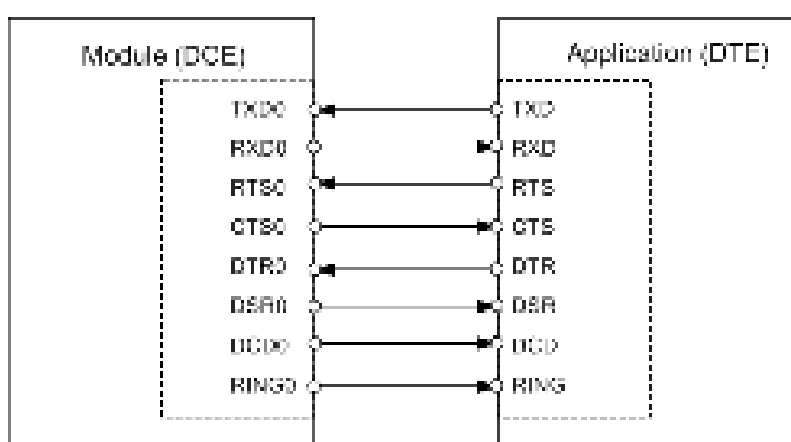
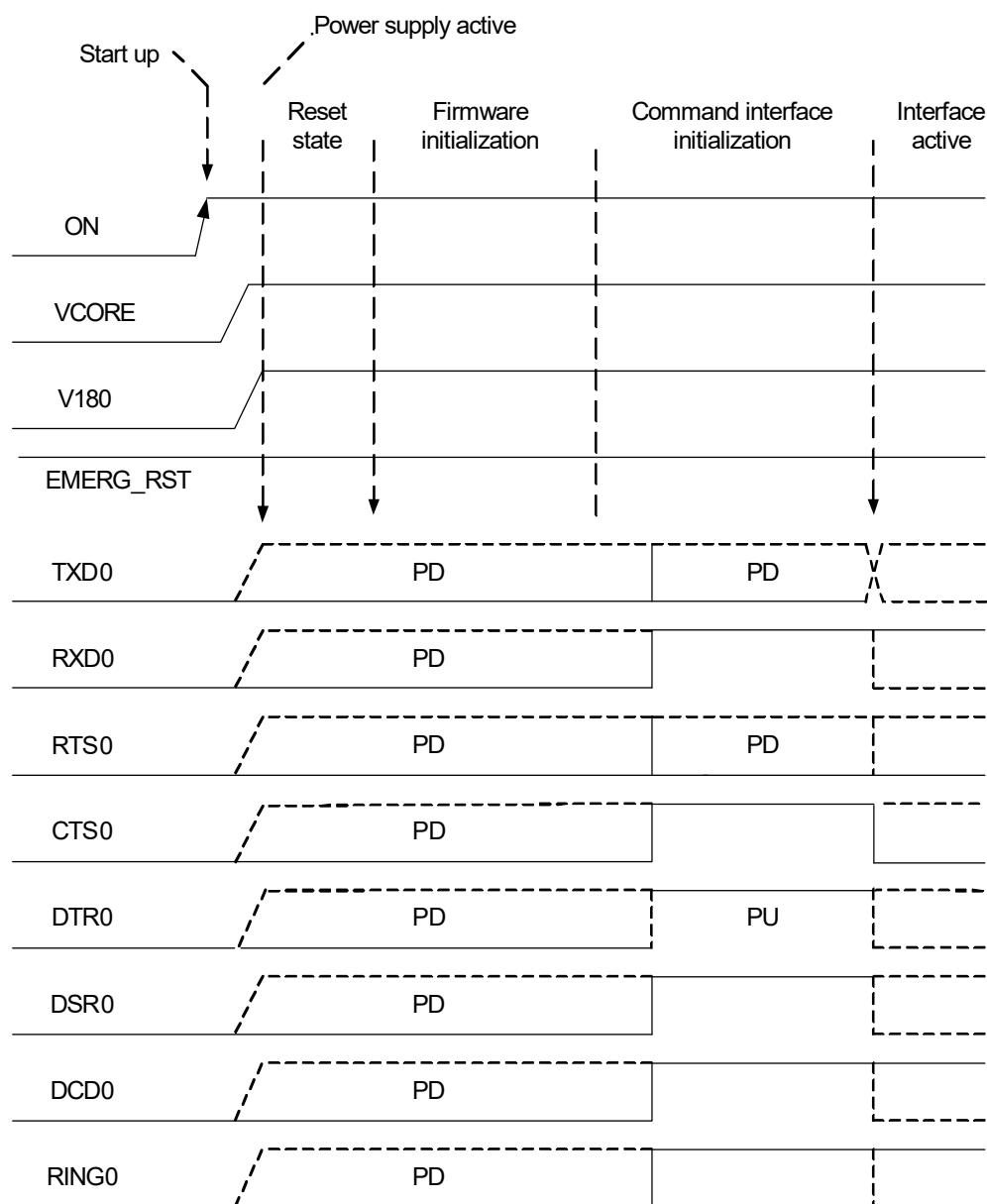


Figure 10: Serial interface ASC0

Features:

- Includes the data lines TXD0 and RXD0, the status lines RTS0 and CTS0 and, in addition, the modem control lines DTR0, DSR0, DCD0 and RING0.
- The RING0 signal serves to indicate incoming calls and other types of URCs (Unsolicited Result Code). It can also be used to send pulses to the host application, for example to wake up the application from power saving state.
- By default configured to 8 data bits, no parity and 1 stop bit.
- ASC0 can be operated at fixed bit rates from 300bps up to 921,600bps.
- Supports RTS0/CTS0 hardware flow control as a configuration option (see [\[1\]](#)). The hardware hand shake line RTS0 has an internal pull down resistor causing a low level signal, if the line is not used and open. Although hardware flow control is recommended, this allows communication by using only RXD and TXD lines.
- Wake up from SLEEP mode by RTS0 activation (high to low transition; see [Section 3.3.1.1](#)).

The following figure shows the startup behavior of the asynchronous serial interface ASC0.



Dotted lines indicate possible alternative signal states - depending on externally provided signal states. For pull-up and pull-down values see [Table 18](#).

Figure 11: ASC0 startup behavior

2.1.5 Serial Interface ASC1

TX62/TX82 provides a 4-wire unbalanced, asynchronous modem interface ASC1 conforming to ITU-T V.24 protocol DCE signaling. The electrical characteristics do not comply with ITU-T V.28. The significant levels are 0V (for low data bit or active state) and 1.8V (for high data bit or inactive state). For electrical characteristics please refer to [Table 4](#). For an illustration of the interface line's startup behavior see [Figure 13](#).

TX62/TX82 is designed for use as a DCE. Based on the conventions for DCE-DTE connections it communicates with the customer application (DTE) using the following signals:

- Port TXD @ application sends data to module's TXD1 signal line
- Port RXD @ application receives data from the module's RXD1 signal line

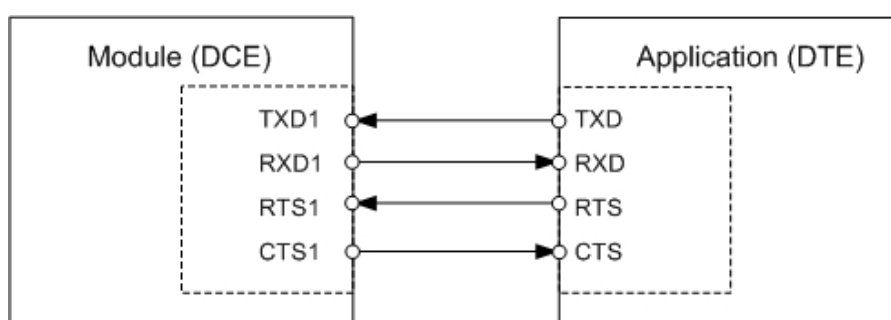


Figure 12: Serial interface ASC1

Features

- Includes only the data lines TXD1 and RXD1 plus RTS1 and CTS1 for hardware hand-shake.
- Configured for 8 data bits, no parity and 1 or 2 stop bits.
- ASC1 can be operated at fixed bit rates from 300bps to 921,600bps.
- Supports RTS1/CTS1 hardware flow as a configuration option (see [\[1\]](#)). The hardware hand shake line RTS0 has an internal pull down resistor causing a low level signal, if the line is not used and open. Although hardware flow control is recommended, this allows communication by using only RXD and TXD lines.

The following figure shows the startup behavior of the asynchronous serial interface ASC1.

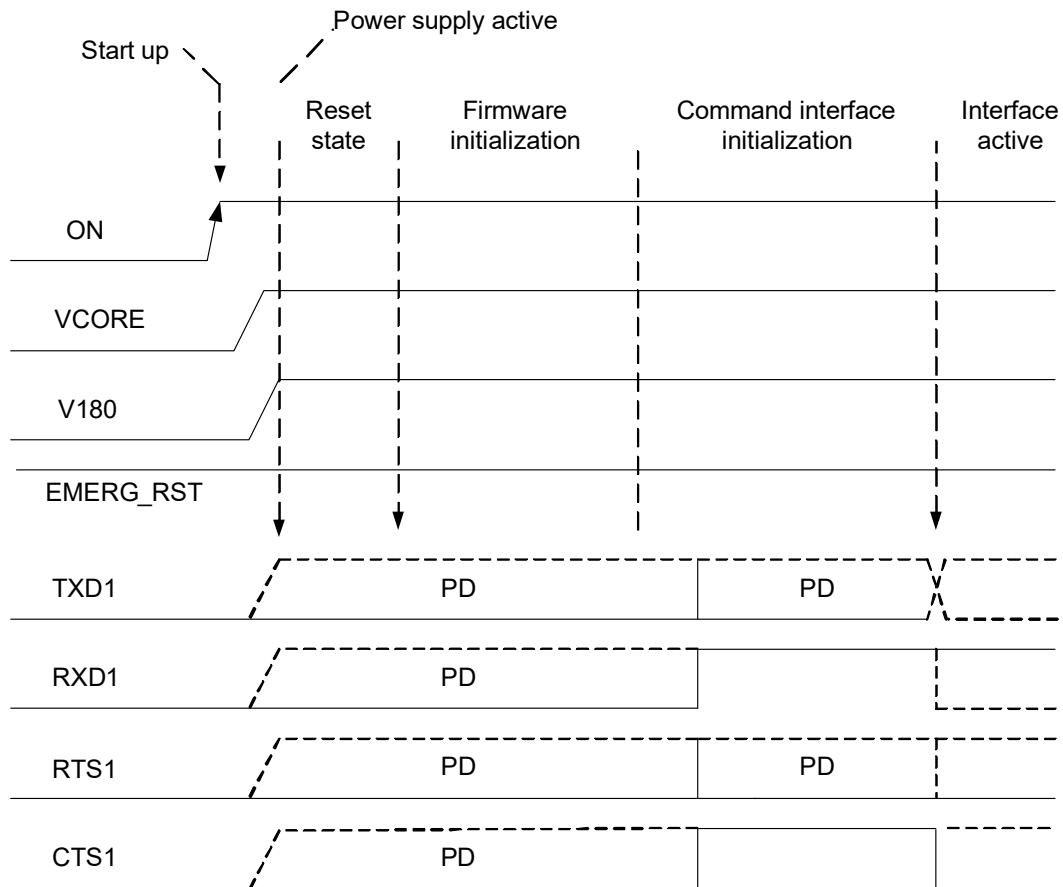


Figure 13: ASC1 startup behavior

2.1.6 UICC/SIM/USIM Interface

TX62/TX82 has an integrated UICC/SIM/USIM interface compatible with the 3GPP 31.102 and ETSI 102 221. This is wired to the host interface in order to be connected to an external SIM card holder. Five pads on the SMT application interface are reserved for the SIM interface.

The UICC/SIM/USIM interface supports 1.8V SIM cards. Please refer to [Table 4](#) for electrical specifications of the UICC/SIM/USIM interface lines.

The CCIN signal serves to detect whether a tray (with SIM card) is present in the card holder. Using the CCIN signal is mandatory for compliance with the GSM 11.11 recommendation if the mechanical design of the host application allows the user to remove the SIM card during operation. To take advantage of this feature, an appropriate SIM card detect switch is required on the card holder. For example, this is true for the model supplied by Molex, which has been tested to operate with TX62/TX82 and is part of the Thales reference equipment submitted for type approval. See [Section 7.1](#) for Molex ordering numbers.

Table 6: Signals of the SIM interface (SMT application interface)

| Signal | Description |
|--------|--|
| GND | Separate ground connection for SIM card to improve EMC. Thales recommends to use pad J16 or pad M17 as ground connection. |
| CCCLK | UICC clock |
| CCVCC | SIM supply voltage. |
| CCIO | Serial data line, input and output. |
| CCRST | UICC reset |
| CCIN | Input on the baseband processor for detecting a SIM card tray in the holder. If the SIM is removed during operation the SIM interface is shut down immediately to prevent destruction of the SIM. The CCIN signal is by default low and must change to high level if a SIM card is inserted. The CCIN signal is mandatory for applications that allow the user to remove the SIM card during operation. The CCIN signal is solely intended for use with a SIM card. It must not be used for any other purposes. Failure to comply with this requirement may invalidate the type approval of TX62/TX82. |

Note: No guarantee can be given, nor any liability accepted, if loss of data is encountered after removing the SIM card during operation. Also, no guarantee can be given for properly initializing any SIM card that the user inserts after having removed the SIM card during operation. In this case, the application must restart TX62/TX82.

The figure below shows a circuit to connect an external SIM card holder.

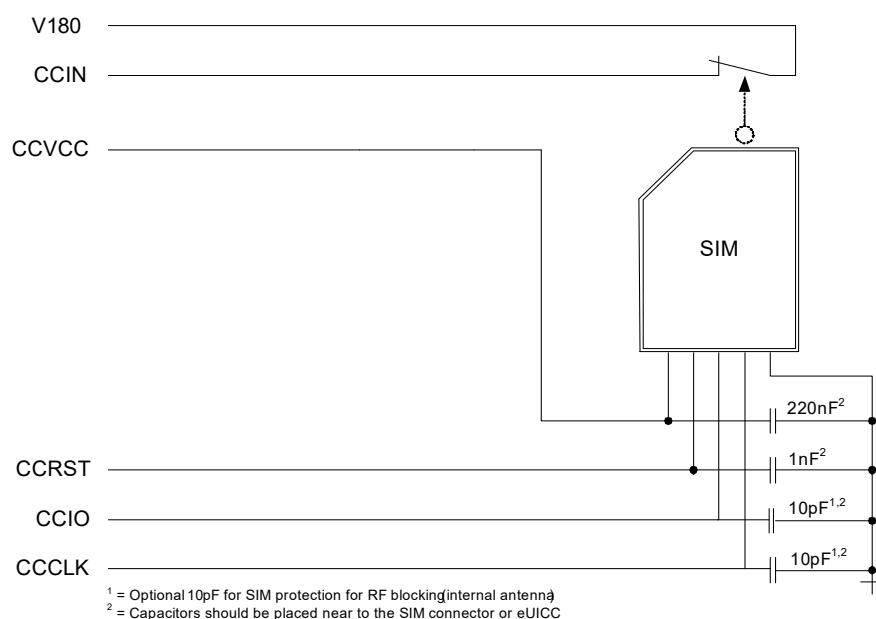


Figure 14: External UICC/SIM/USIM card holder circuit

The total cable length between the SMT application interface pads on TX62/TX82 and the pads of the external SIM card holder must not exceed 100mm in order to meet the specifications of 3GPP TS 51.010-1 and to satisfy the requirements of EMC compliance.

To avoid possible cross-talk from the CCCLK signal to the CCIO signal be careful that both lines are not placed closely next to each other. A useful approach is using a GND line to shield the CCIO line from the CCCLK line.

An example for an optimized ESD protection for the SIM interface is shown in [Section 2.1.6.1](#).

It is possible to connect the UICC/USIM/SIM interface lines to an external SIM card multiplexer controlled by the module's SIM_SWITCH signal. Thus, it becomes possible to switch between two networks/subscriptions each with its own UICC, and maybe different connection speeds. See also [Section 2.1.11.4](#).

2.1.6.1 Enhanced ESD Protection for SIM Interface

To optimize ESD protection for the SIM interface it is possible to add ESD diodes (e.g., NUP4114) to the SIM interface lines as shown in the example given in [Figure 15](#).

The example was designed to meet ESD protection according ETSI EN 301 489-1/7: Contact discharge: $\pm 4\text{kV}$, air discharge: $\pm 8\text{kV}$.

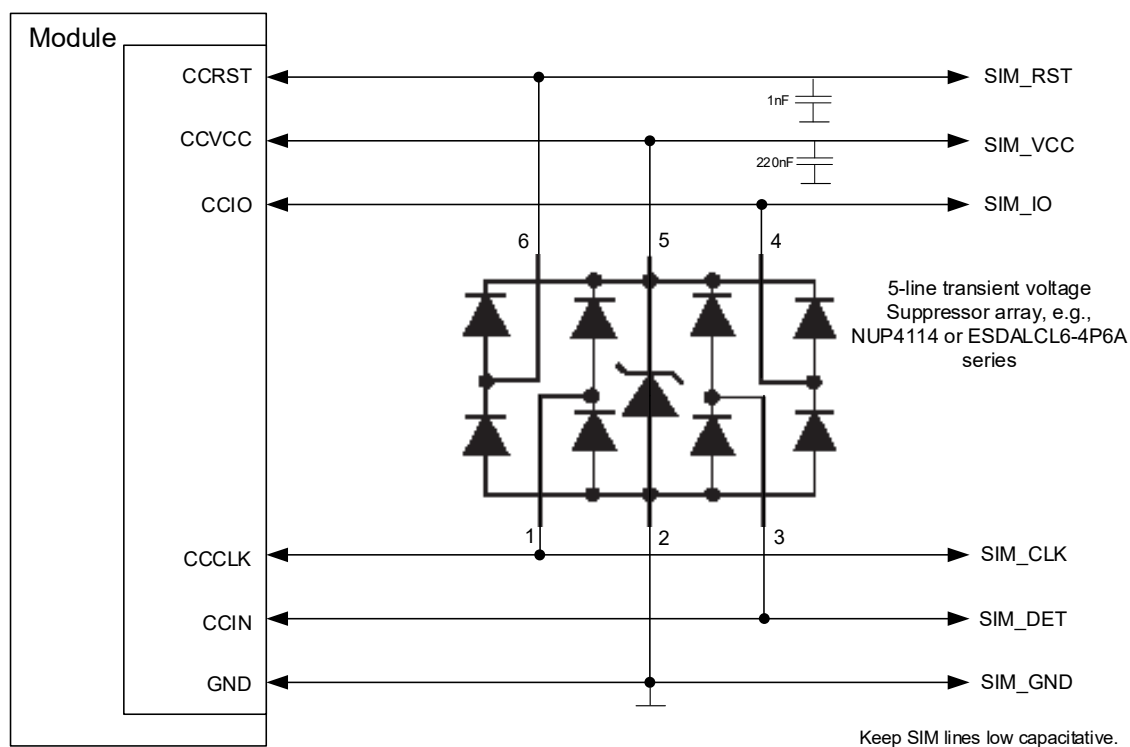


Figure 15: SIM interface - enhanced ESD protection

The capacitors shown in [Figure 14](#) must be placed close to the SIM Connector.

2.1.7 eUICC Interface

As an option TX62/TX82 supports an eUICC in MFF-XS format. This MFF-XS eUICC is located under the shielding, is only connected to specific module pads, and has no physical connections with other circuits inside the module. [Figure 16](#) shows an example of how to connect the eUICC to the module's SIM interface lines as well as a switch to select whether to use the internal MFF-XS eUICC or an external plug-in SIM card. [Figure 17](#) shows an example for a direct connection to the module's SIM interface lines.

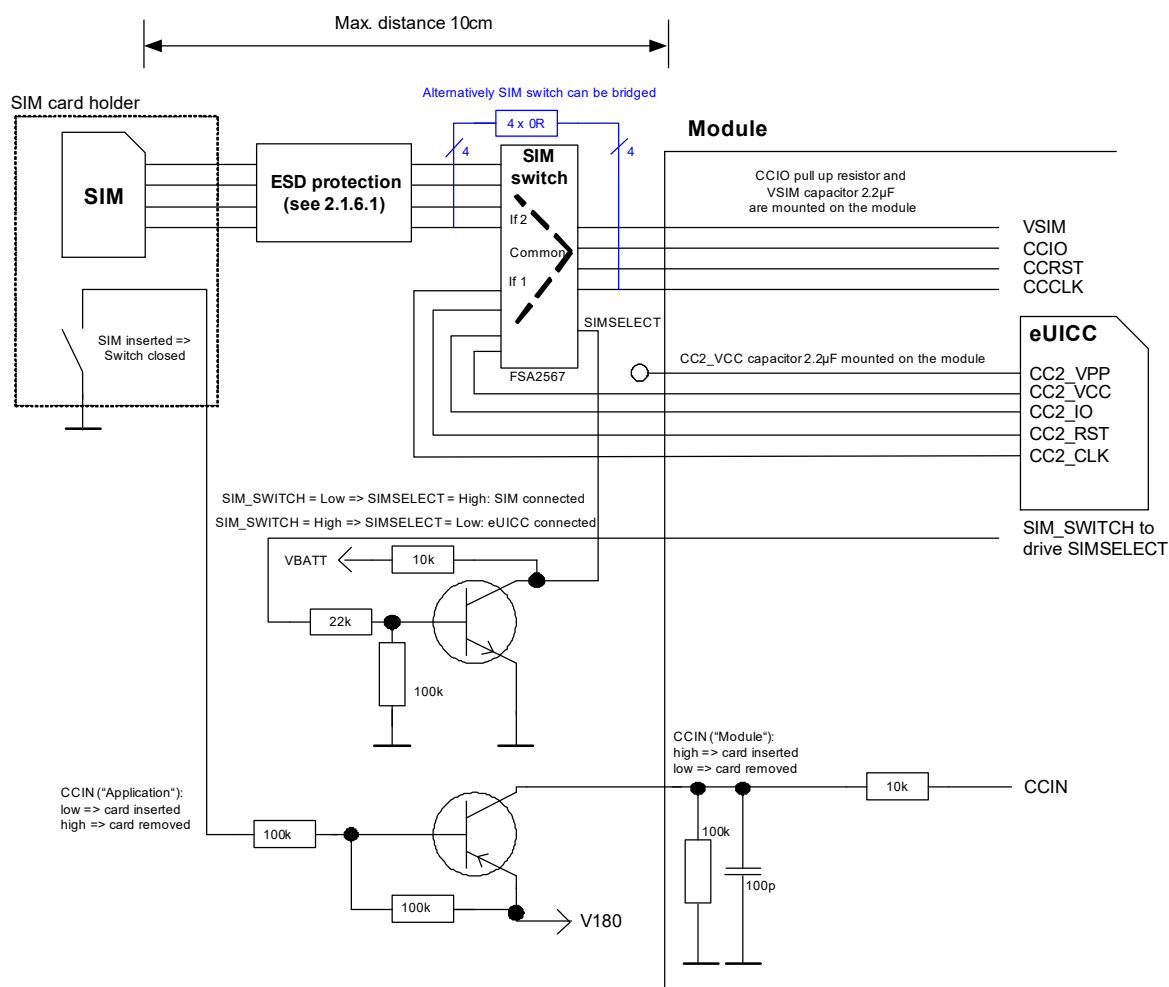


Figure 16: eUICC interface with switch for external SIM

The eUICC interface comprises five lines (plus ground) as listed below in [Table 7](#).

Table 7: Signals of the eUICC interface option (SMT application interface)

| Signal | Description |
|---------|--|
| CC2_RST | Chip Card Reset |
| CC2_CLK | Chip Card Clock |
| CC2_IO | Chip Card I/O (data line) |
| CC2_VPP | - |
| CC2_VCC | Operation voltage for SIM Card (=1.8V) |
| GND | eUICC Ground |

If using a SIM switch to change between usage of an external SIM and an eUICC as shown in [Figure 16](#), the module needs to be prepared for this dual mode by AT command.

By default, dual mode is disabled, and usage of the first SIM slot, i.e., the external SIM interface, is configured - as shown by the following AT command result:

```
AT^SCFG?
...
^SCFG: "SIM/CS","0"
^SCFG: "SIM/DualMode","0"
...
OK
```

To configure and use the eUICC, dual mode has to be enabled, and usage of the second SIM slot, i.e., the eUICC, needs to be specified - as shown by the following AT command sequence:

```
AT^SCFG="SIM/DualMode","1"
^SCFG: "SIM/DualMode","1"

OK
at^scfg="SIM/CS","3"
^SCFG: "SIM/CS","3"

OK
```

For details on these AT commands please refer to [\[1\]](#).

[Figure 17](#) shows a direct connection of the internal eUICC to the module's SIM interface lines. In this case no dual mode is possible.

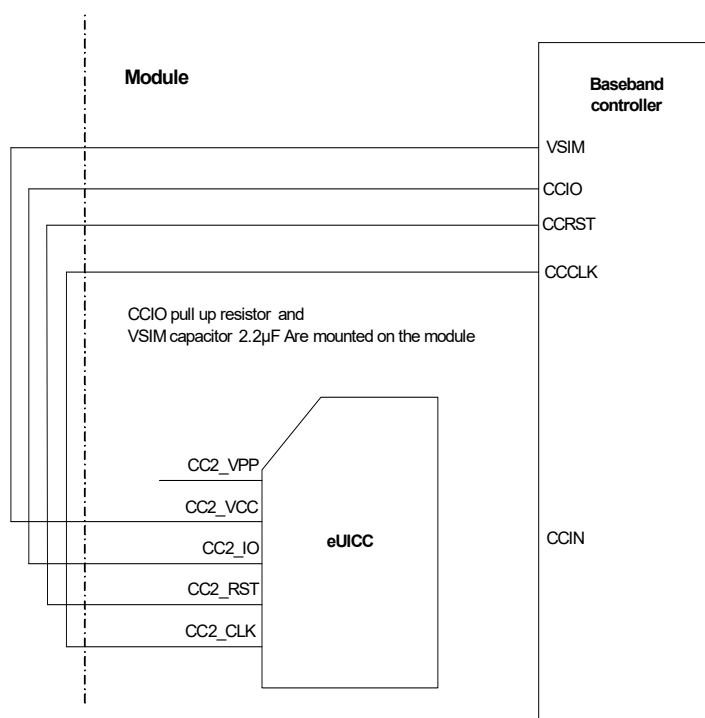


Figure 17: eUICC interface without SIM switch

2.1 Application Interface

In case the module is mounted onto the LGA DevKit, a direct connection to the eUICC can be achieved by bridging the following pads on the backside of the LGA DevKit: PAD 249 to 17, PAD 248 to 19, PAD 247 to 21, PAD 246 to 20, as also shown in [Figure 18](#).

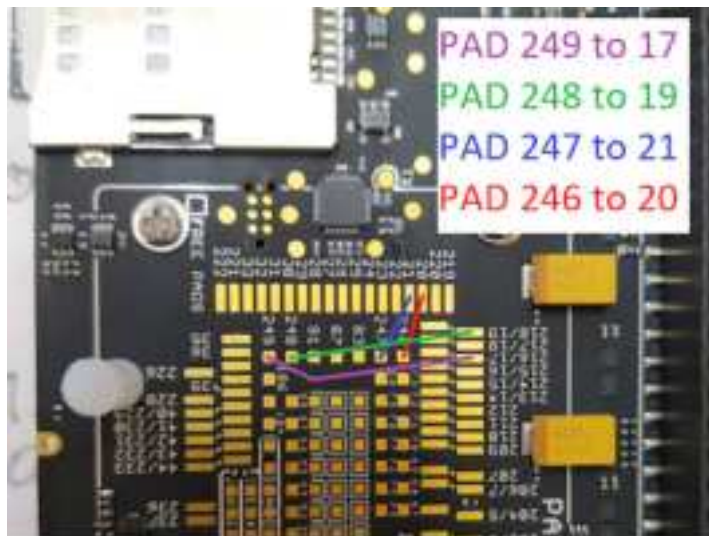


Figure 18: Interface bridging

2.1.8 GPIO

TX82-W, TX82-W-B, TX62-W-B and TX62-W-C have 7 GPIOs (GPIO6-7,20-23,25) and TX62-W has 6 GPIOs (GPIO7,20-23,25) for external hardware devices. Each GPIO can be configured for use as input or output. All settings are AT command controlled. The configuration is non-volatile and available after module restart.

The IO port driver has to be opened before using and configuring GPIOs. Before changing the configuration of a GPIO pin (e.g. input to output) the pin has to be closed. If the GPIO pins are not configured or the pins/driver were closed, the GPIO pins are high-Z with pull down resistor.

If a GPIO is configured to input, the pin has high-Z without pull resistor.

The following figure shows the start up behavior of the GPIOs interface.

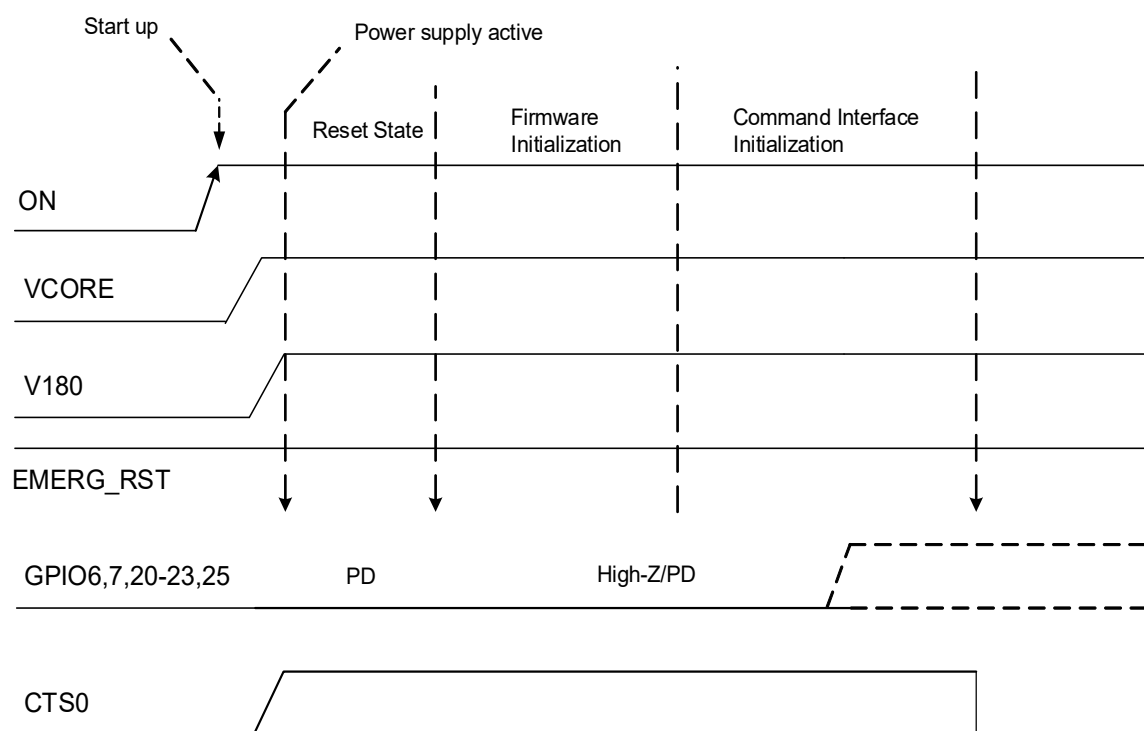


Figure 19: GPIO start up behavior

With the embedded processing option of TX62/TX82 additional GPIOs are provided and can be used - see below [Section 2.1.8.1](#).

2.1.8.1 GPIOs Available with Embedded Processing Option

The embedded processing option of TX62/TX82 provides a GPIO interface with 13 configurable GPIO lines. Some GPIO lines are shared with other interfaces or functions, and are shown in the following table with their default assignments being marked green.

Table 8: GPIO lines and alternative assignments

| GPIO | Status LED | ASC1 | SPI | SIM Switch |
|-----------------------|------------|------|---------|------------|
| GPIO5 | STATUS | | | |
| GPIO6 ¹ | | | | |
| GPIO7 | | | | |
| GPIO8 | | | | SIM_SWITCH |
| (GPIO16) ² | | RXD1 | MOSI | |
| (GPIO17) ² | | TXD1 | MISO | |
| (GPIO18) ² | | RTS1 | SPI_CS | |
| (GPIO19) ² | | CTS1 | SPI_CLK | |
| GPIO20 | | | | |
| GPIO21 | | | | |
| GPIO22 | | | | |
| GPIO23 | | | | |
| GPIO25 | | | | |

1. Only available with TX82-W, TX82-W-B, TX62-W-B and TX62-W-C.

2. Not configurable as GPIO line with the embedded processing option.

After startup, the above mentioned alternative GPIO line assignments can be configured through embedded applications (see [9]), or in the case of GPIO5 and GPIO8 also through AT command. The configuration is non-volatile and available after module restart.

2.1.9 I²C Interface

The embedded processing option of TX62/TX82 provides an inter-integrated circuit interface. I²C is a serial, 8-bit oriented data transfer bus for bit rates up to 400kbps in Fast mode. It consists of two lines, the serial data line I2CDAT and the serial clock line I2CCLK. The module acts as a single master device, e.g. the clock I2CCLK is driven by the module. I2CDAT is a bi-directional line. Each device connected to the bus is software addressable by a unique 7-bit address, and simple master/slave relationships exist at all times. The module operates as master-transmitter or as master-receiver. The customer application transmits or receives data only on request of the module.

The I²C bus can be configured and activated via embedded application. For more information see [\[9\]](#).

The I²C interface can be powered via the V180 line of TX62/TX82. If connected to the V180 line, the I²C interface will properly shut down when the module enters the Power Down mode.

In the application I2CDAT and I2CCLK lines need to be connected to a positive supply voltage via a pull-up resistor. For electrical characteristics please refer to [Table 4](#).

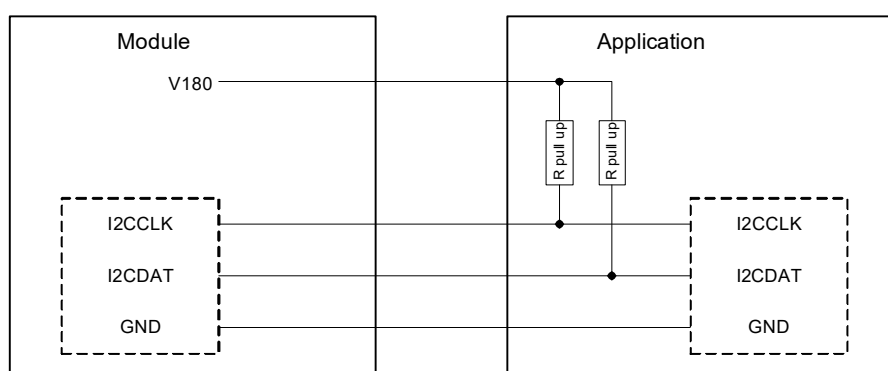


Figure 20: I²C interface connected to V180

Note 1: Good care should be taken when creating the PCB layout of the host application: The traces of I2CCLK and I2CDAT should be equal in length and as short as possible.

2.1.10 SPI Interface

The embedded processing option of TX62/TX82 provides an SPI interface where four GPIO interface lines can be configured as Serial Peripheral Interface (SPI). The SPI is a synchronous serial interface allowing the module to control external sensors or components. The SPI interface supports only master mode. The transmission rates are up to 6.5Mbit/s. The SPI interface comprises the two data lines MOSI and MISO, the clock line SPI_CLK as well as the chip select line SPI_CS.

The GPIO lines are also shared with the ASC1 signal lines as shown in [Section 2.1.8.1](#).

The SPI interface can be configured and activated via embedded application. For more information see [\[9\]](#).

In general, SPI supports four operation modes. The modes are different in clock phase and clock polarity. The module's SPI mode can be configured via embedded processing option. Make sure the module and the connected slave device works with the same SPI mode.

[Figure 21](#) shows the characteristics of the four SPI modes. The SPI modes 0 and 3 are the most common used modes. For electrical characteristics please refer to [Table 4](#).

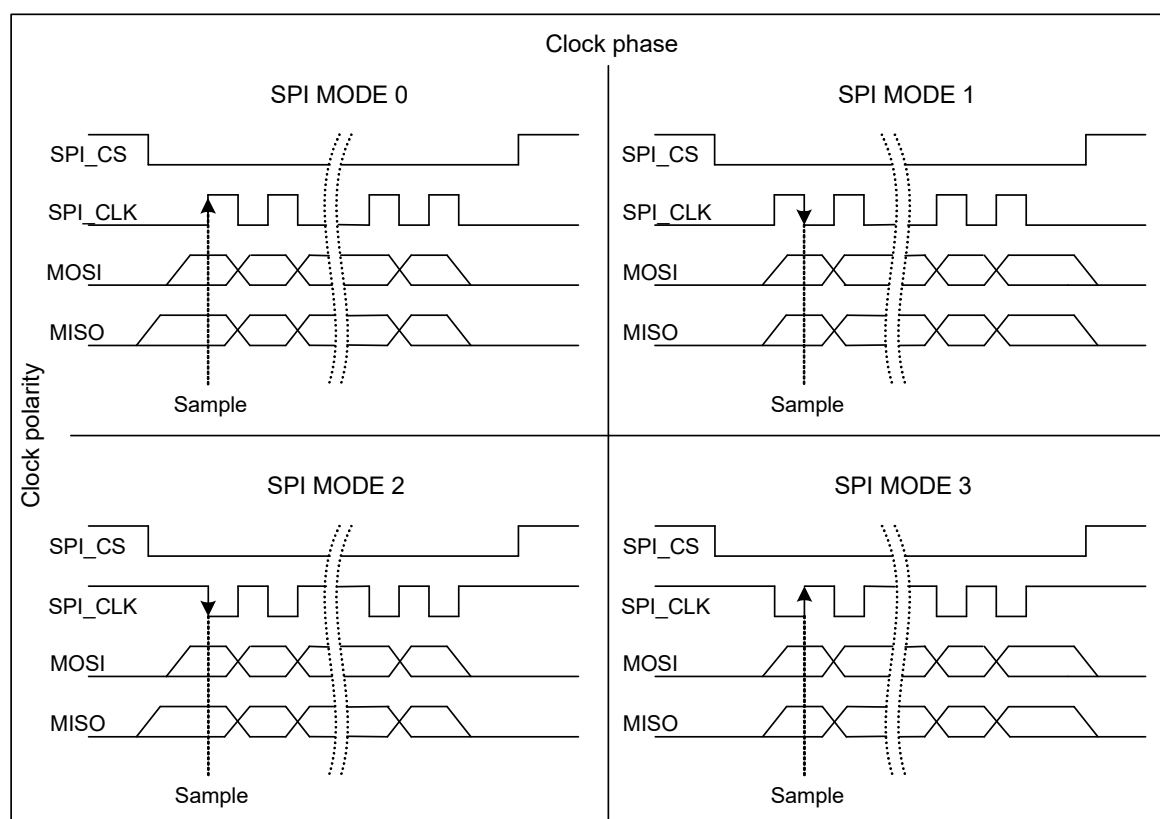


Figure 21: Characteristics of SPI modes

2.1.11 Control Signals

2.1.11.1 Status LED

The STATUS line can be configured to drive a status LED that indicates different operating modes of the module. For details on how to configure status signaling please refer to [1].

To take advantage of this function connect an LED to the STATUS line as shown in Figure 22. The sample circuit is not optimized for low current consumption.

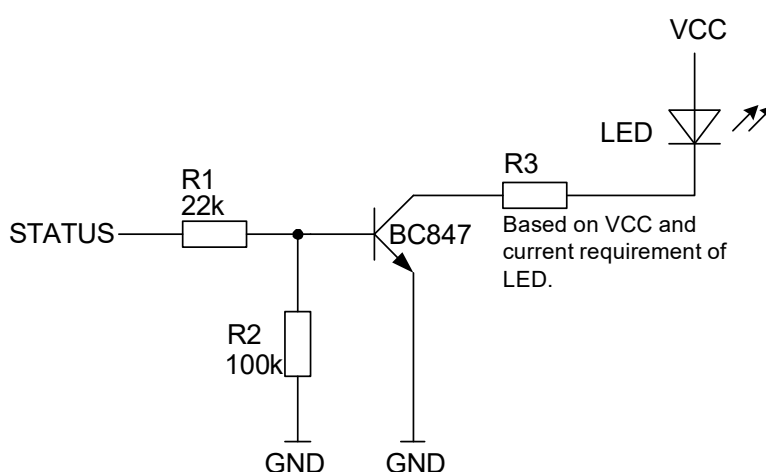


Figure 22: Status signaling with LED driver

2.1.11.2 Power Indication Circuit

In Power Down mode the maximum voltage at any digital or analog interface line must not exceed +0.3V (see also Section 2.1.2.1). Exceeding this limit for any length of time might cause permanent damage to the module.

It is therefore recommended to implement a power indication signal that reports the module's power state and shows whether it is active or in Power Down mode. While the module is in Power Down mode all signals with a high level from an external application need to be set to low state or high impedance state. The sample power indication circuit illustrated in Figure 23 denotes the module's active state with a low signal and the module's Power Down mode with a high signal or high impedance state. The sample circuit is not optimized for low current consumption.

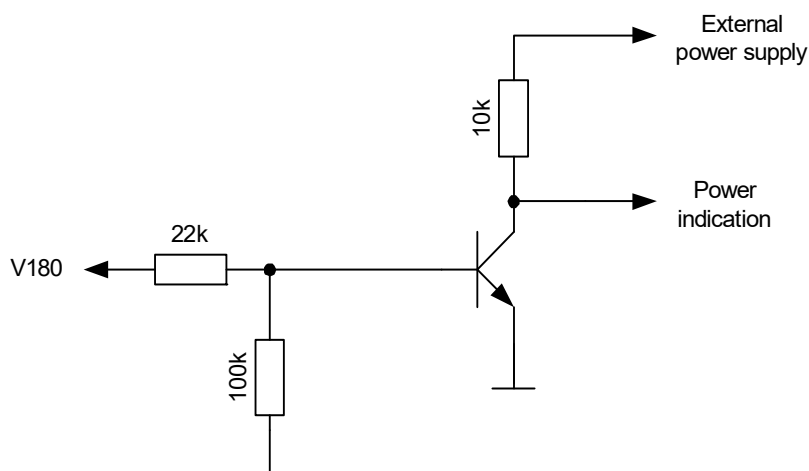


Figure 23: Power indication circuit

2.1.11.3 Fast Shutdown

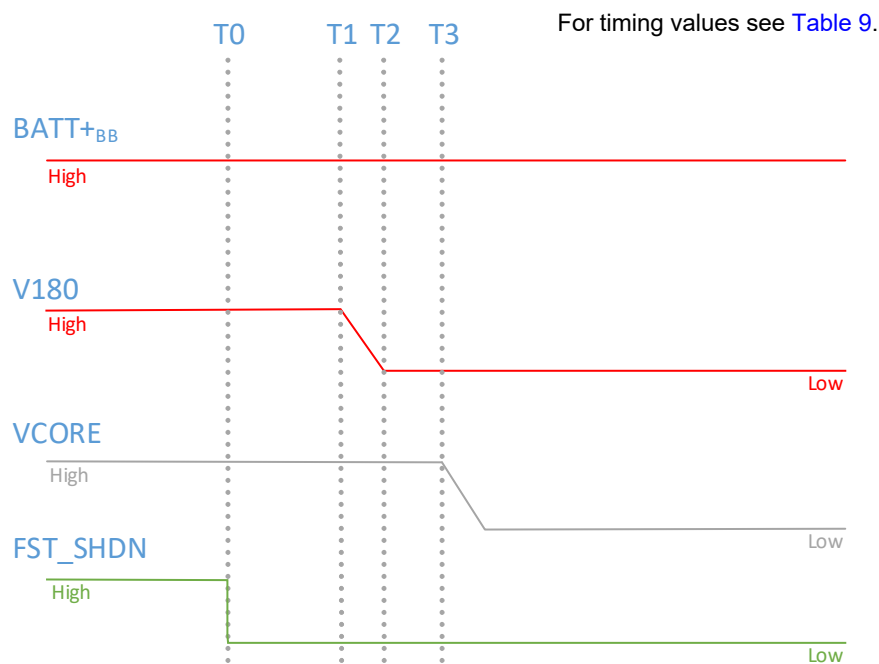
The FST_SHDN line triggers the module's fast shutdown procedure. The fast shutdown procedure ensures data integrity during shutdown, but will no longer deregister gracefully from the network thus saving the time normally required for network deregistration. For fast shutdown behavior and timings see [Figure 24](#) as well as [Table 9](#).

The FST_SHDN line is an active low control signal and must be applied via an open drain or open collector circuit (see [Table 4](#) for electrical characteristics). It is recommended to verify the behavior of the external application especially during the boot and initialization phase against back powering and unintentional fast shutdown.

It is recommended to keep the FST_SHDN line low until the module has shut down. A low level of the V180 signal indicates that the module has entered the Power Down mode. No shutdown URCs will be issued with a fast shutdown. Thus, it is recommended to monitor the V180 line by the external application. Other reference voltage lines may still show a high level.

Once V180 is low, the external application can cut the module's power supply.

In order not to trigger a restart loop of the module, the ON line shall be released by the external application, and not be actively driven continuously.

**Figure 24:** Fast shutdown timing**Table 9:** Fast shutdown timing values

| Timing | Description | Typical value | Unit |
|----------|--------------------|---------------|------|
| TX62-W | | | |
| T0 – T1 | FST_SHDN - V180 | 7.38 | ms |
| T1 – T2 | V180 - V180 (low) | 1.09 | |
| T2 – T3 | V180 (low) - VCORE | 2.06 | |
| TX62-W-B | | | |
| T0 – T1 | FST_SHDN - V180 | 6.99 | ms |
| T1 – T2 | V180 - V180 (low) | 0.71 | |
| T2 – T3 | V180 (low) - VCORE | 2.48 | |
| TX62-W-C | | | |
| T0 – T1 | FST_SHDN - V180 | 15.47 | ms |
| T1 – T2 | V180 - V180 (low) | 0.61 | |
| T2 – T3 | V180 (low) - VCORE | 2.58 | |
| TX82-W | | | |
| T0 – T1 | FST_SHDN - V180 | 7.38 | ms |
| T1 – T2 | V180 - V180 (low) | 1.09 | |
| T2 – T3 | V180 (low) - VCORE | 2.06 | |
| TX82-W-B | | | |
| T0 – T1 | FST_SHDN - V180 | TBD. | ms |
| T1 – T2 | V180 - V180 (low) | TBD. | |
| T2 – T3 | V180 (low) - VCORE | TBD. | |

If the FST_SHDN functionality is not used, the FST_SHDN line can be left open because of a configured internal pull-up resistor.

If there is a reasonable probability for sudden power losses, Thales recommends to implement a circuit using the FST_SHDN line with a capacitor to buffer sufficient energy to complete the fast shutdown - see below for sample capacity calculation.

Please note that the normal software controlled shutdown via AT^SMSO can also be configured as a fast shutdown, i.e., without network deregistration. For details see [\[1\]](#).

Sample Capacity Calculation:

The following formula is a guideline for a capacitor required in a fast shutdown circuit to buffer enough energy to complete the fast shutdown process.

Depending on the application design and use case the factors may vary.

Capacitor energy:

$$E[J] = 0.5 \times C \times (V^{2max} - V^{2min}) \times \text{Aging factor}$$

Example:

Aging factor e.g = 0.7

$$E[J] = 0.5 \times 2500\mu F \times ((4.5V)^2 - (3.0V)^2) \times 0.7 = 0.0098J$$

Note: Vmax can be limited by the module supply and/or capacitor voltage. Same applies for the Vmin which is mostly limited by VBATT min.

Module energy usage:

$$V_{avg} = V_{max} + V_{min} / 2$$

Aavg = See typical values in [Section 3.4.1](#)

$$E[W] = V_{avg} \times A_{avg} \times \text{Efficiency}$$

Example:

Power Circuit Efficiency factor, e.g = 0.8

$$E[W] = ((4.5V + 3.0V) / 2) \times 0.2A \times 0.8 = 0.6375W \text{ (assuming the Cat NB1/2 worst case)}$$

Discharge time:

$$T[s] = E[J] / E[W]$$

Example:

$$T[s] = 0.0098J / 0.6375W = 0.015s$$

2.1.11.4 SIM Switch

The UICC/USIM/SIM interface lines may be connected to an external SIM card multiplexer controlled by the SIM_SWITCH signal as shown in [Figure 25](#). Thus, it becomes possible to switch between two networks/subscriptions each with their own UICC, and maybe different connection speeds. Please note that hot SIM insert/removal is only possible on the first SIM interface. Also note that the SIM_SWITCH can be used to switch between a SIM and the embedded optional eUICC interface as described in [Section 2.1.7](#).

The SIM SWITCH signal is controlled by AT command (see [1]).

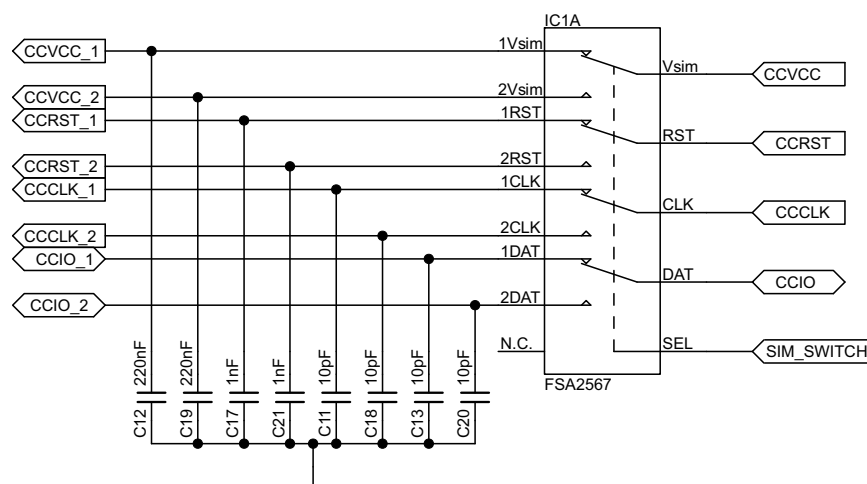


Figure 25: SIM switch circuit

2.1.11.5 SUSPEND Mode Indicator

When all conditions for entering into SUSPEND mode are fulfilled, the SUSPEND_MON signal changes from high to low, indicating that the module has entered its SUSPEND mode.

When leaving the SUSPEND mode, the URC “^SYSRESUME” is triggered, and the SUSPEND MON signal is set to high again.

SUSPEND_MON usage can be enabled/disabled by AT command (see [1]: AT^SCFG “GPIO/Mode/Suspend”).

2.2 RF Antenna Interface

The RF interface has an impedance of 50Ω. TX62/TX82 is capable of sustaining a total mismatch at the antenna line without any damage, even when transmitting at maximum RF power.

The external antenna must be matched properly to achieve best performance regarding radiated power, modulation accuracy and harmonic suppression. Antenna matching networks are not included on the TX62/TX82 module and should be placed in the host application if the antenna does not have an impedance of 50Ω.

Regarding the return loss TX62/TX82 provides the following values in the active band:

Table 10: Return loss in the active band

| State of module | Return loss of module | Recommended return loss of application |
|-----------------|-----------------------|--|
| Receive | ≥ 8dB | ≥ 12dB |
| Transmit | not applicable | ≥ 12dB |
| Idle | ≤5dB | not applicable |

2.2.1 Antenna Interface Specifications

Table 11: RF Antenna interface GSM / LTE¹ of TX82-W, and TX62-W

| Parameter | Conditions | Min. ² | Typical | | Unit |
|--|---|-------------------|---------|--------|------|
| | | | TX62-W | TX82-W | |
| LTE connectivity (Cat M1) | Band 1, 2, 3, 4, 5, 8, 12, 13, 18, 19, 20, 25, 26, 27, 28, 66, 85 | | | | |
| LTE Cat M1: Receiver Input Sensitivity @NTNV BW: 5 MHz, UL: Modulation: QPSK; N _{RB} =6; DL: Modulation: QPSK; N _{RB} =4; | LTE 2100 Band 1 | -103 | -107 | -106 | dBm |
| | LTE 1800 Band 2 | -101 | -107 | -106 | dBm |
| | LTE 1900 Band 3 | -100 | -107 | -105.5 | dBm |
| | LTE AWS-1 Band 4 | -103 | -107 | -106 | dBm |
| | LTE 850 Band 5 | -101.5 | -107.5 | -106 | dBm |
| | LTE 900 Band 8 | -100.5 | -107 | -106.5 | dBm |
| | LTE 700 Band 12 | -100 | -107 | -106.3 | dBm |
| | LTE 700 Band 13 | -100 | -107 | -106.3 | dBm |
| | LTE 800 Band 18 | -103 | -107.5 | -106.2 | dBm |
| | LTE 800 Band 19 | -103 | -107.5 | -106 | dBm |
| | LTE 800 Band 20 | -100.5 | -107 | -106 | dBm |
| | LTE 1900 Band 25 | -101 | -107.5 | -106.2 | dBm |
| | LTE 800 Band 26 | -101 | -107.5 | -106.3 | dBm |
| | LTE 800 Band 27 | -101.5 | -107.5 | -106 | dBm |
| | LTE 700 Band 28 | -101.5 | -107.5 | -106 | dBm |
| | LTE AWS-3 Band 66 | -99 | -107 | -106 | dBm |
| | LTE 700 Band 85 | -99.2 | -107 | -106 | dBm |

Table 11: RF Antenna interface GSM / LTE¹ of TX82-W, and TX62-W

| Parameter | Conditions | Min. ² | Typical | | Unit |
|--|---|-------------------|---------|--------|------|
| | | | TX62-W | TX82-W | |
| LTE Cat M1: Power @ ARP with 50Ω Load, NTNV BW: 5 MHz, UL: Modulation: QPSK; N _{RB} =1; | LTE 2100 Band 1 | +18 | +20 | +20 | dBm |
| | LTE 1800 Band 2 | +18 | +20 | +20 | dBm |
| | LTE 1900 Band 3 | +18 | +20 | +20 | dBm |
| | LTE AWS-1 Band 4 | +18 | +20 | +20 | dBm |
| | LTE 850 Band 5 | +18 | +20 | +20 | dBm |
| | LTE 900 Band 8 | +18 | +20 | +20 | dBm |
| | LTE 700 Band 12 | +18 | +20 | +20 | dBm |
| | LTE 700 Band 13 | +18 | +20 | +20 | dBm |
| | LTE 800 Band 18 | +18 | +20 | +20 | dBm |
| | LTE 800 Band 19 | +18 | +20 | +20 | dBm |
| | LTE 800 Band 20 | +18 | +20 | +20 | dBm |
| | LTE 1900 Band 25 | +18 | +20 | +20 | dBm |
| | LTE 800 Band 26 | +18 | +20 | +20 | dBm |
| | LTE 800 Band 27 | +18 | +20 | +20 | dBm |
| | LTE 700 Band 28 | +18 | +20 | +20 | dBm |
| | LTE AWS-3 Band 66 | +18 | +20 | +20 | dBm |
| | LTE 700 Band 85 | +18 | +20 | +20 | dBm |
| LTE connectivity (Cat NB1/2) | Band 1, 2, 3, 4, 5, 8, 12, 13, 18, 19, 20, 25, 26, 28, 66, 71, 85 | | | | |
| LTE Cat NB1/2: Receiver Input Sensitivity @NTNV DL: Modulation: QPSK; Subcarriers: 12; UL: Modulation: BPSK; Subcarrier spacing: 15KHz; N _{tones} : 1@0 | LTE 2100 Band 1 | -108.2 | -115 | -114 | dBm |
| | LTE 1800 Band 2 | -108.2 | -115.5 | -114 | dBm |
| | LTE 1900 Band 3 | -108.2 | -114.5 | -114 | dBm |
| | LTE AWS-1 Band 4 | -108.2 | -115 | -114 | dBm |
| | LTE 850 Band 5 | -108.2 | -116 | -114.5 | dBm |
| | LTE 900 Band 8 | -108.2 | -115.5 | -115 | dBm |
| | LTE 700 Band 12 | -108.2 | -116 | -115 | dBm |
| | LTE 700 Band 13 | -108.2 | -116 | -115 | dBm |
| | LTE 800 Band 18 | -108.2 | -115.5 | -115 | dBm |
| | LTE 800 Band 19 | -108.2 | -115.5 | -114.5 | dBm |
| | LTE 800 Band 20 | -108.2 | -115.5 | -115 | dBm |
| | LTE 1900 Band 25 | -108.2 | -115.5 | -114.5 | dBm |
| | LTE 800 Band 26 | -108.2 | -116 | -115 | dBm |
| | LTE 700 Band 28 | -108.2 | -116 | -115 | dBm |
| | LTE AWS-3 Band 66 | -108.2 | -115.5 | -114 | dBm |
| | LTE 600 Band 71 | -108.2 | -116 | -115 | dBm |
| | LTE 700 Band 85 | -108.2 | -116 | -115.5 | dBm |

Table 11: RF Antenna interface GSM / LTE¹ of TX82-W, and TX62-W

| Parameter | | Conditions | Min. ² | Typical | | Unit |
|---|---------------|------------------------|-------------------|---------|--------|------|
| | | | | TX62-W | TX82-W | |
| LTE Cat NB1/2: Power @ ARP with 50Ω Load, NTNV Configuration ID: 1, UL: Modulation: BPSK; Subcarrier: 1;Subcarrier space: 3.75 kHz; N _{tones} : 1@0 | | LTE 2100 Band 1 | +18 | +20 | +20 | dBm |
| | | LTE 1800 Band 2 | +18 | +20 | +20 | dBm |
| | | LTE 1900 Band 3 | +18 | +20 | +20 | dBm |
| | | LTE AWS-1 Band 4 | +18 | +20 | +20 | dBm |
| | | LTE 850 Band 5 | +18 | +20 | +20 | dBm |
| | | LTE 900 Band 8 | +18 | +20 | +20 | dBm |
| | | LTE 700 Band 12 | +18 | +20 | +20 | dBm |
| | | LTE 700 Band 13 | +18 | +20 | +20 | dBm |
| | | LTE 800 Band 18 | +18 | +20 | +20 | dBm |
| | | LTE 800 Band 19 | +18 | +20 | +20 | dBm |
| | | LTE 800 Band 20 | +18 | +20 | +20 | dBm |
| | | LTE 1900 Band 25 | +18 | +20 | +20 | dBm |
| | | LTE 800 Band 26 | +18 | +20 | +20 | dBm |
| | | LTE 700 Band 28 | +18 | +20 | +20 | dBm |
| | | LTE AWS-3 Band 66 | +18 | +20 | +20 | dBm |
| | | LTE 600 Band 71 | +18 | +20 | +20 | dBm |
| | | LTE 700 Band 85 | +18 | +20 | +20 | dBm |
| GPRS coding schemes | | Class 10, CS1 to CS4 | | | | |
| EGPRS | | Class 10, MCS1 to MCS9 | | | | |
| GSM Class | | Small MS | | | | |
| GPRS Static Receiver input Sensitivity @ PDTCH/CS-1 | | GSM 850/900 | -104 | | -110 | dBm |
| | | GSM 1800/1900 | -104 | | -109 | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 4, i.e. no reduction) | GSM 850/900 | GPRS, 1 TX | | | 32.5 | dBm |
| | | GPRS, 2 TX | | | 32.5 | dBm |
| | | EDGE, 1 TX | | | 27.0 | dBm |
| | | EDGE, 2TX | | | 27.0 | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | 29.5 | dBm |
| | | GPRS, 2 TX | | | 29.5 | dBm |
| | | EDGE, 1 TX | | | 26.0 | dBm |
| | | EDGE, 2TX | | | 26.0 | dBm |

Table 11: RF Antenna interface GSM / LTE¹ of TX82-W, and TX62-W

| Parameter | | Conditions | Min. ² | Typical | | Unit |
|--|---------------|------------|-------------------|---------|--------|------|
| | | | | TX62-W | TX82-W | |
| RF Power @ ARP with 50Ω Load, (ROPR = 5) | GSM 850/900 | GPRS, 1 TX | | | 32.5 | dBm |
| | | GPRS, 2 TX | | | 23.5 | dBm |
| | | EDGE, 1 TX | | | 27.0 | dBm |
| | | EDGE, 2TX | | | 27.0 | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | 29.5 | dBm |
| | | GPRS, 2 TX | | | 29.5 | dBm |
| | | EDGE, 1 TX | | | 26.0 | dBm |
| | | EDGE, 2TX | | | 26.0 | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 6) | GSM 850/900 | GPRS, 1 TX | | | 32.5 | dBm |
| | | GPRS, 2 TX | | | 31.5 | dBm |
| | | EDGE, 1 TX | | | 27.0 | dBm |
| | | EDGE, 2TX | | | 27.0 | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | 29.5 | dBm |
| | | GPRS, 2 TX | | | 28.5 | dBm |
| | | EDGE, 1 TX | | | 26.0 | dBm |
| | | EDGE, 2TX | | | 26.0 | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 7) | GSM 850/900 | GPRS, 1 TX | | | 32.5 | dBm |
| | | GPRS, 2 TX | | | 29.5 | dBm |
| | | EDGE, 1 TX | | | 27.0 | dBm |
| | | EDGE, 2TX | | | 27.0 | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | 29.5 | dBm |
| | | GPRS, 2 TX | | | 26.5 | dBm |
| | | EDGE, 1 TX | | | 26.0 | dBm |
| | | EDGE, 2TX | | | 26.0 | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 8, i.e. maximum reduction) | GSM 850/900 | GPRS, 1 TX | | | 32.5 | dBm |
| | | GPRS, 2 TX | | | 29.5 | dBm |
| | | EDGE, 1 TX | | | 27.0 | dBm |
| | | EDGE, 2TX | | | 24.0 | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | 29.5 | dBm |
| | | GPRS, 2 TX | | | 26.5 | dBm |
| | | EDGE, 1 TX | | | 26.0 | dBm |
| | | EDGE, 2TX | | | 23.0 | dBm |

1. GSM (2G) only supported by TX82-W.

2. "Min." signifies 3GPP limit in case of Receiver Input Sensitivity.

Table 12: RF Antenna interface GSM / LTE¹ of TX62-W-B and TX82-W-B

| Parameter | Conditions | Min. ² | Typical | | Unit |
|--|---|-------------------|----------|----------|------|
| | | | TX62-W-B | TX82-W-B | |
| LTE connectivity (Cat M1) | Band 1, 2, 3, 4, 5, 8, 12, 13, 18, 19, 20, 25, 26, 27, 28, 66, 85 | | | | |
| LTE Cat M1: Receiver Input Sensitivity @NTNV BW: 5 MHz, UL: Modulation: QPSK; N _{RB} =6; DL: Modulation: QPSK; N _{RB} =4; | LTE 2100 Band 1 | -103 | -106.5 | | dBm |
| | LTE 1800 Band 2 | -101 | -106.3 | | dBm |
| | LTE 1900 Band 3 | -100 | -105.7 | | dBm |
| | LTE AWS-1 Band 4 | -103 | -106.3 | | dBm |
| | LTE 850 Band 5 | -101.5 | -106.5 | | dBm |
| | LTE 900 Band 8 | -100.5 | -106.3 | | dBm |
| | LTE 700 Band 12 | -100 | -105.7 | | dBm |
| | LTE 700 Band 13 | -100 | -106 | | dBm |
| | LTE 800 Band 18 | -103 | -106.5 | | dBm |
| | LTE 800 Band 19 | -103 | -106.5 | | dBm |
| | LTE 800 Band 20 | -100.5 | -105.5 | | dBm |
| | LTE 1900 Band 25 | -101 | -106.2 | | dBm |
| | LTE 800 Band 26 | -101 | -106.5 | | dBm |
| | LTE 800 Band 27 | -101.5 | -106.4 | | dBm |
| | LTE 700 Band 28 | -101.5 | -105.8 | | dBm |
| | LTE AWS-3 Band 66 | -99 | -106.2 | | dBm |
| | LTE 700 Band 85 | -99.2 | -105.6 | | dBm |
| LTE Cat M1: Power @ ARP with 50Ω Load, NTNV BW: 5 MHz, UL: Modulation: QPSK; N _{RB} =1; | LTE 2100 Band 1 | +21 | +23 | | dBm |
| | LTE 1800 Band 2 | +21 | +23 | | dBm |
| | LTE 1900 Band 3 | +21 | +23 | | dBm |
| | LTE AWS-1 Band 4 | +21 | +23 | | dBm |
| | LTE 850 Band 5 | +21 | +23 | | dBm |
| | LTE 900 Band 8 | +21 | +23 | | dBm |
| | LTE 700 Band 12 | +21 | +23 | | dBm |
| | LTE 700 Band 13 | +21 | +23 | | dBm |
| | LTE 800 Band 18 | +21 | +23 | | dBm |
| | LTE 800 Band 19 | +21 | +23 | | dBm |
| | LTE 800 Band 20 | +21 | +23 | | dBm |
| | LTE 1900 Band 25 | +21 | +23 | | dBm |
| | LTE 800 Band 26 | +21 | +23 | | dBm |
| | LTE 800 Band 27 | +21 | +23 | | dBm |
| | LTE 700 Band 28 | +21 | +23 | | dBm |
| | LTE AWS-3 Band 66 | +21 | +23 | | dBm |
| | LTE 700 Band 85 | +21 | +23 | | dBm |

Table 12: RF Antenna interface GSM / LTE¹ of TX62-W-B and TX82-W-B

| Parameter | Conditions | Min. ² | Typical | | Unit |
|--|---|-------------------|----------|----------|------|
| | | | TX62-W-B | TX82-W-B | |
| LTE connectivity (Cat NB1/2) | Band 1, 2, 3, 4, 5, 8, 12, 13, 18, 19, 20, 25, 26, 28, 66, 71 ³ , 85 | | | | |
| LTE Cat NB1/2: Receiver Input Sensitivity @NTNV DL: Modulation: QPSK; Subcarriers: 12; UL: Modulation: BPSK; Subcarrier spacing: 15KHz; N _{tones} : 1@0 | LTE 2100 Band 1 | -108.2 | -114 | | dBm |
| | LTE 1800 Band 2 | -108.2 | -114.3 | | dBm |
| | LTE 1900 Band 3 | -108.2 | -114 | | dBm |
| | LTE AWS-1 Band 4 | -108.2 | -114.5 | | dBm |
| | LTE 850 Band 5 | -108.2 | -115 | | dBm |
| | LTE 900 Band 8 | -108.2 | -115 | | dBm |
| | LTE 700 Band 12 | -108.2 | -115.5 | | dBm |
| | LTE 700 Band 13 | -108.2 | -115.5 | | dBm |
| | LTE 800 Band 18 | -108.2 | -115 | | dBm |
| | LTE 800 Band 19 | -108.2 | -115 | | dBm |
| | LTE 800 Band 20 | -108.2 | -115 | | dBm |
| | LTE 1900 Band 25 | -108.2 | -114 | | dBm |
| | LTE 800 Band 26 | -108.2 | -115 | | dBm |
| | LTE 700 Band 28 | -108.2 | -115.5 | | dBm |
| | LTE AWS-3 Band 66 | -108.2 | -114 | | dBm |
| | LTE 600 Band 71 ³ | -108.2 | -115 | -- | dBm |
| | LTE 700 Band 85 | -108.2 | -115 | | dBm |
| LTE Cat NB1/2: Power @ ARP with 50Ω Load, NTV Configuration ID: 1, UL: Modulation: BPSK; Subcarrier: 1;Subcarrier space: 3.75 kHz; N _{tones} : 1@0 | LTE 2100 Band 1 | +21 | +23 | | dBm |
| | LTE 1800 Band 2 | +21 | +23 | | dBm |
| | LTE 1900 Band 3 | +21 | +23 | | dBm |
| | LTE AWS-1 Band 4 | +21 | +23 | | dBm |
| | LTE 850 Band 5 | +21 | +23 | | dBm |
| | LTE 900 Band 8 | +21 | +23 | | dBm |
| | LTE 700 Band 12 | +21 | +23 | | dBm |
| | LTE 700 Band 13 | +21 | +23 | | dBm |
| | LTE 800 Band 18 | +21 | +23 | | dBm |
| | LTE 800 Band 19 | +21 | +23 | | dBm |
| | LTE 800 Band 20 | +21 | +23 | | dBm |
| | LTE 1900 Band 25 | +21 | +23 | | dBm |
| | LTE 800 Band 26 | +21 | +23 | | dBm |
| | LTE 700 Band 28 | +21 | +23 | | dBm |
| | LTE AWS-3 Band 66 | +21 | +23 | | dBm |
| | LTE 600 Band 71 ³ | +21 | +23 | -- | dBm |
| | LTE 700 Band 85 | +21 | +23 | | dBm |

Table 12: RF Antenna interface GSM / LTE¹ of TX62-W-B and TX82-W-B

| Parameter | | Conditions | Min. ² | Typical | | Unit |
|---|---------------|------------------------|-------------------|----------|----------|------|
| | | | | TX62-W-B | TX82-W-B | |
| GPRS coding schemes | | Class 10, CS1 to CS4 | | | | |
| EGPRS | | Class 10, MCS1 to MCS9 | | | | |
| GSM Class | | Small MS | | | | |
| GPRS Static Receiver input Sensitivity @ PDTCH/CS-1 | | GSM 850/900 | TBD. | | TBD. | dBm |
| | | GSM 1800/1900 | TBD. | | TBD. | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 4, i.e. no reduction) | GSM 850/900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 5) | GSM 850/900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 6) | GSM 850/900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| RF Power @ ARP with 50Ω Load, (ROPR = 7) | GSM 850/900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |

2.2 RF Antenna Interface

Table 12: RF Antenna interface GSM / LTE¹ of TX62-W-B and TX82-W-B

| Parameter | | Conditions | Min. ² | Typical | | Unit |
|--|---------------|------------|-------------------|----------|----------|------|
| | | | | TX62-W-B | TX82-W-B | |
| RF Power @ ARP with 50Ω Load, (ROPR = 8, i.e. maximum reduction) | GSM 850/900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |
| | GSM 1800/1900 | GPRS, 1 TX | | | TBD. | dBm |
| | | GPRS, 2 TX | | | TBD. | dBm |
| | | EDGE, 1 TX | | | TBD. | dBm |
| | | EDGE, 2TX | | | TBD. | dBm |

1. GSM (2G) only supported by TX82-W-B.

2. "Min." signifies 3GPP limit in case of Receiver Input Sensitivity.

3. LTE Band 71 not supported with TX82-W-B.

Table 13: RF Antenna interface LTE of TX62-W-C

| Parameter | Conditions | Min. ¹ | Typical | Unit |
|---|------------------------------|-------------------|---------|------|
| LTE connectivity (Cat M1) | Band 1, 3, 8, 20, 28, 31, 72 | | | |
| LTE Cat M1: Receiver Input Sensitivity @NTNV BW: 5 MHz, UL: Modulation: QPSK; N _{RB} =6; DL: Modulation: QPSK; N _{RB} =4; | LTE 2100 Band 1 | -103 | | dBm |
| | LTE 1900 Band 3 | -100 | | dBm |
| | LTE 900 Band 8 | -100.5 | | dBm |
| | LTE 800 Band 20 | -100.5 | | dBm |
| | LTE 700 Band 28 | -101.5 | | dBm |
| | LTE 450 Band 31 | -97.3 | | dBm |
| | LTE 450 Band 72 | -97.3 | | dBm |
| LTE Cat M1: Power @ ARP with 50Ω Load, NTV BW: 5 MHz, UL: Modulation: QPSK; N _{RB} =1; | LTE 2100 Band 1 | +21 | +23 | dBm |
| | LTE 1900 Band 3 | +21 | +23 | dBm |
| | LTE 900 Band 8 | +21 | +23 | dBm |
| | LTE 800 Band 20 | +21 | +23 | dBm |
| | LTE 700 Band 28 | +20.5 | +23 | dBm |
| | LTE 450 Band 31 | +24 | +26 | dBm |
| | LTE 450 Band 72 | +24 | +26 | dBm |

Table 13: RF Antenna interface LTE of TX62-W-C

| Parameter | Conditions | Min. ¹ | Typical | Unit |
|--|------------------------------|-------------------|---------|------|
| LTE connectivity (Cat NB1/2) ² | Band 1, 3, 8, 20, 28, 31, 72 | | | |
| LTE Cat NB1/2: Receiver Input Sensitivity @NTNV DL: Modulation: QPSK; Subcarriers: 12; UL: Modulation: BPSK; Subcarrier spacing: 15KHz; N _{tones} : 1@0 | LTE 2100 Band 1 | -108.2 | | dBm |
| | LTE 1900 Band 3 | -108.2 | | dBm |
| | LTE 900 Band 8 | -108.2 | | dBm |
| | LTE 800 Band 20 | -108.2 | | dBm |
| | LTE 700 Band 28 | -108.2 | | dBm |
| | LTE 450 Band 31 | -108.2 | | dBm |
| | LTE 450 Band 72 | -108.2 | | dBm |
| LTE Cat NB1/2: Power @ ARP with 50Ω Load, NTNV Configuration ID: 1, UL: Modulation: BPSK; Subcarrier: 1; Subcarrier space: 3.75 kHz; N _{tones} : 1@0 | LTE 2100 Band 1 | +21 | +23 | dBm |
| | LTE 1900 Band 3 | +21 | +23 | dBm |
| | LTE 900 Band 8 | +21 | +23 | dBm |
| | LTE 800 Band 20 | +21 | +23 | dBm |
| | LTE 700 Band 28 | +21 | +23 | dBm |
| | LTE 450 Band 31 | +21 | +23 | dBm |
| | LTE 450 Band 72 | +21 | +23 | dBm |

1. "Min." signifies 3GPP limit in case of Receiver Input Sensitivity.

2. With TX62-W-C support for LTE Cat NB1/2 is by default deactivated, but may be activated on demand.

2.2.2 Antenna Installation

The antennas is connected by soldering the antenna pads (RF_OUT, ANT_GNSS) and its neighboring ground pads directly to the application's PCB.

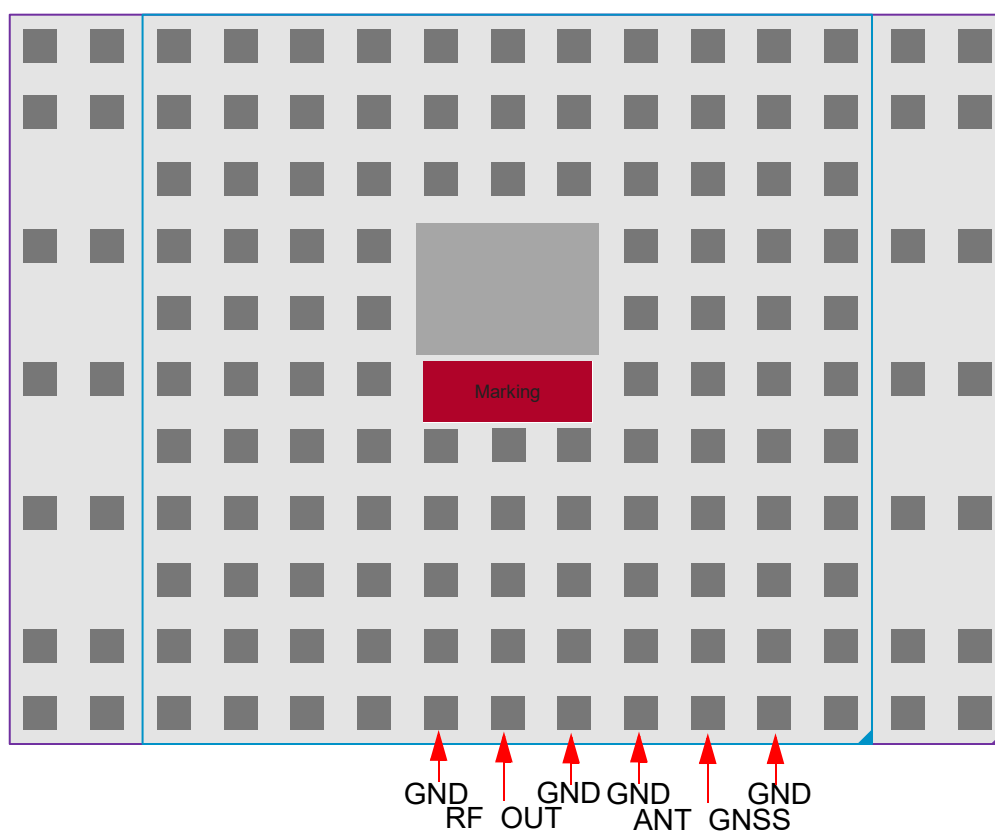


Figure 26: Antenna pads (top view)

The distance between the antenna pads and their neighboring GND pads has been optimized for best possible impedance. On the application PCB, special attention should be paid to these pads, in order to prevent mismatch.

The wiring of the antenna connection line, starting from the antenna pad to the application antenna should result in a 50Ω line impedance. Line width and distance to the GND plane needs to be optimized with regard to the PCB's layer stack. Some examples are given in [Section 2.2.3](#).

To prevent receiver desensitization due to interferences generated by fast transients like high speed clocks on the application PCB, it is recommended to realize the antenna connection line using embedded Stripline rather than Micro-Stripline technology. Please see [Section 2.2.3.1](#) for an example.¹

For type approval purposes, the use of a 50Ω coaxial antenna connector (U.FL-R-SMT) might be necessary. In this case the U.FL-R-SMT connector should be placed as close as possible to TX62/TX82's antenna pad.

1. Please note that because of KDB 447498.GNSS, it is required to get a dedicated FCC ID, if using a PCB printed antenna.

2.2.3 RF Line Routing Design

2.2.3.1 Line Arrangement Examples

Several dedicated tools are available to calculate line arrangements for specific applications and PCB materials - for example from <http://www.polarinstruments.com/> (commercial software) or from <https://www.awr.com/software/options/tx-line> (free software).

Embedded Stripline

This figure below shows a line arrangement example for embedded stripline with 65µm FR4 prepreg (type: 1080) and 710µm FR4 core (4-layer PCB).

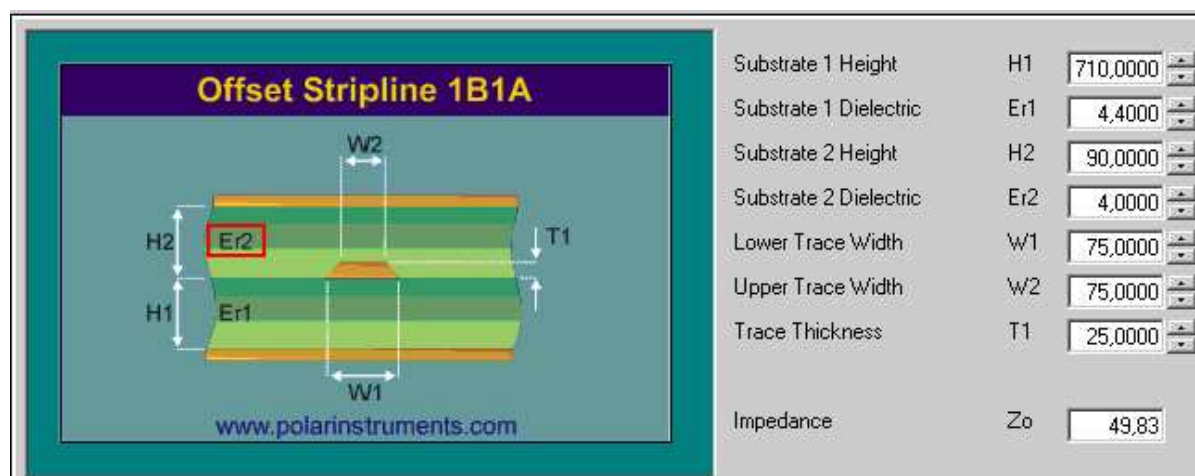


Figure 27: Embedded Stripline with 65µm prepreg (1080) and 710µm core

Micro-Stripline

This section gives two line arrangement examples for micro-stripline.

- Micro-Stripline on 1.0mm Standard FR4 2-Layer PCB
The following two figures show examples with different values for D1 (ground strip separation).

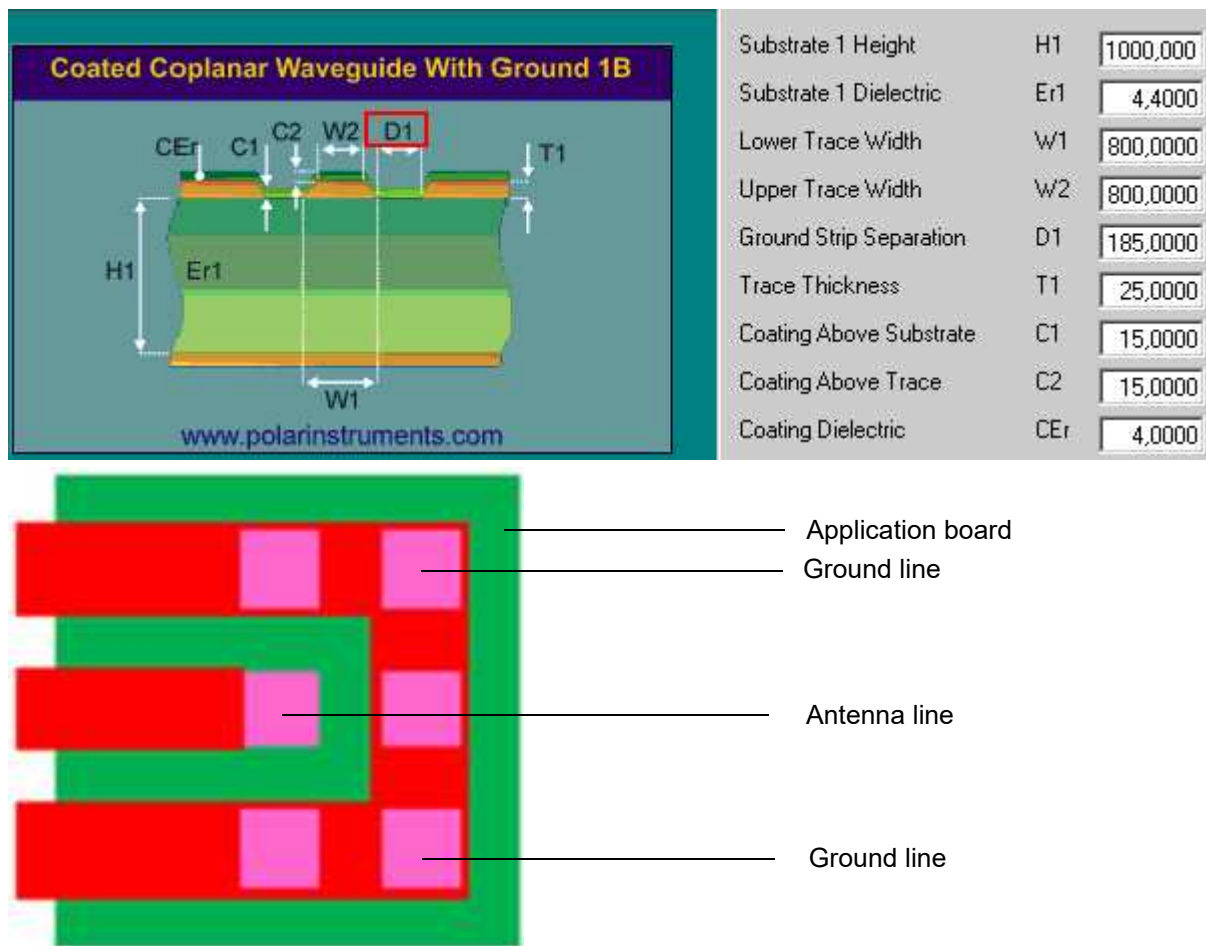


Figure 28: Micro-Stripline on 1.0mm Standard FR4 2-layer PCB - example 1

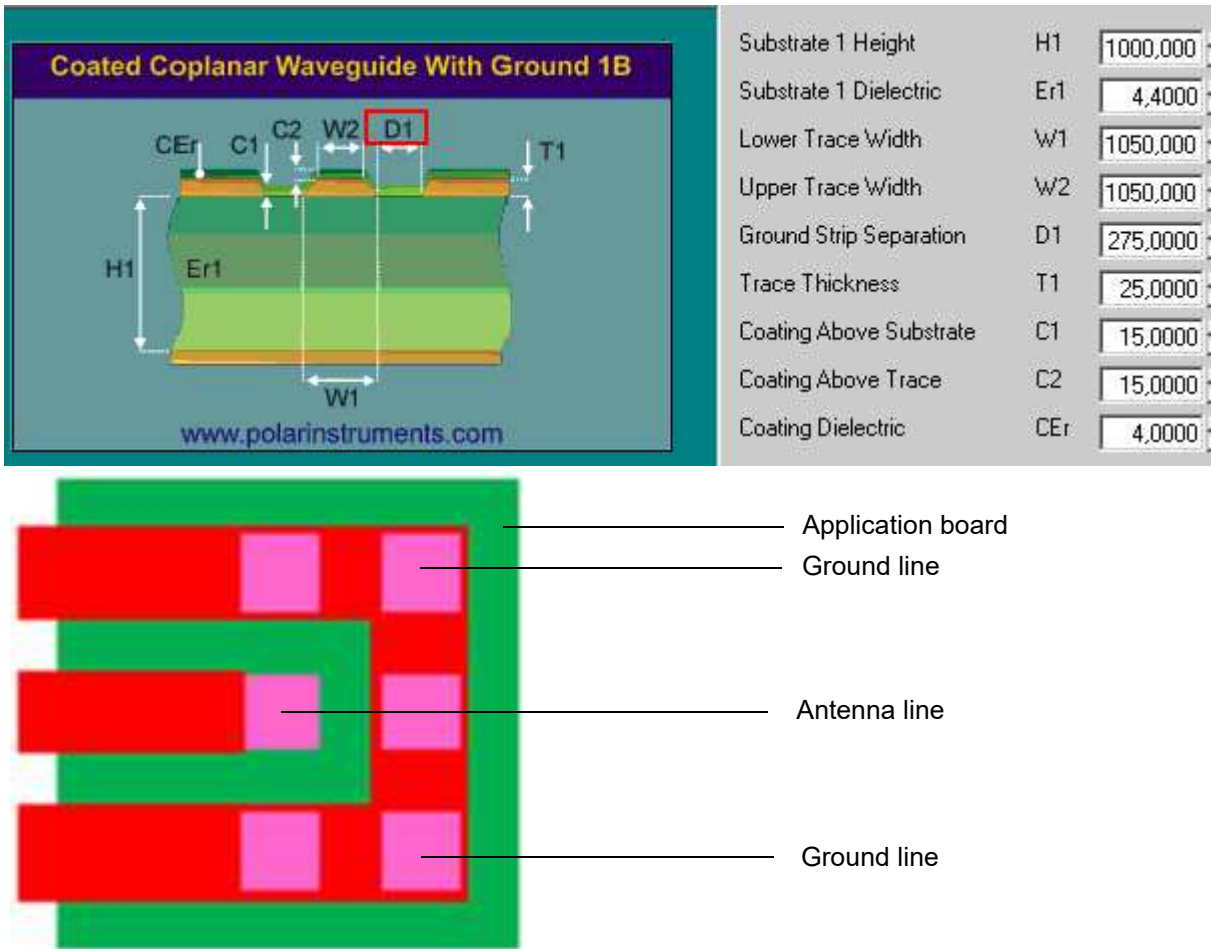


Figure 29: Micro-Stripline on 1.0mm Standard FR4 2-layer PCB - example 2

2.2 RF Antenna Interface

- Micro-Stripline on 1.5mm Standard FR4 2-Layer PCB
The following two figures show examples with different values for D1 (ground strip separation).

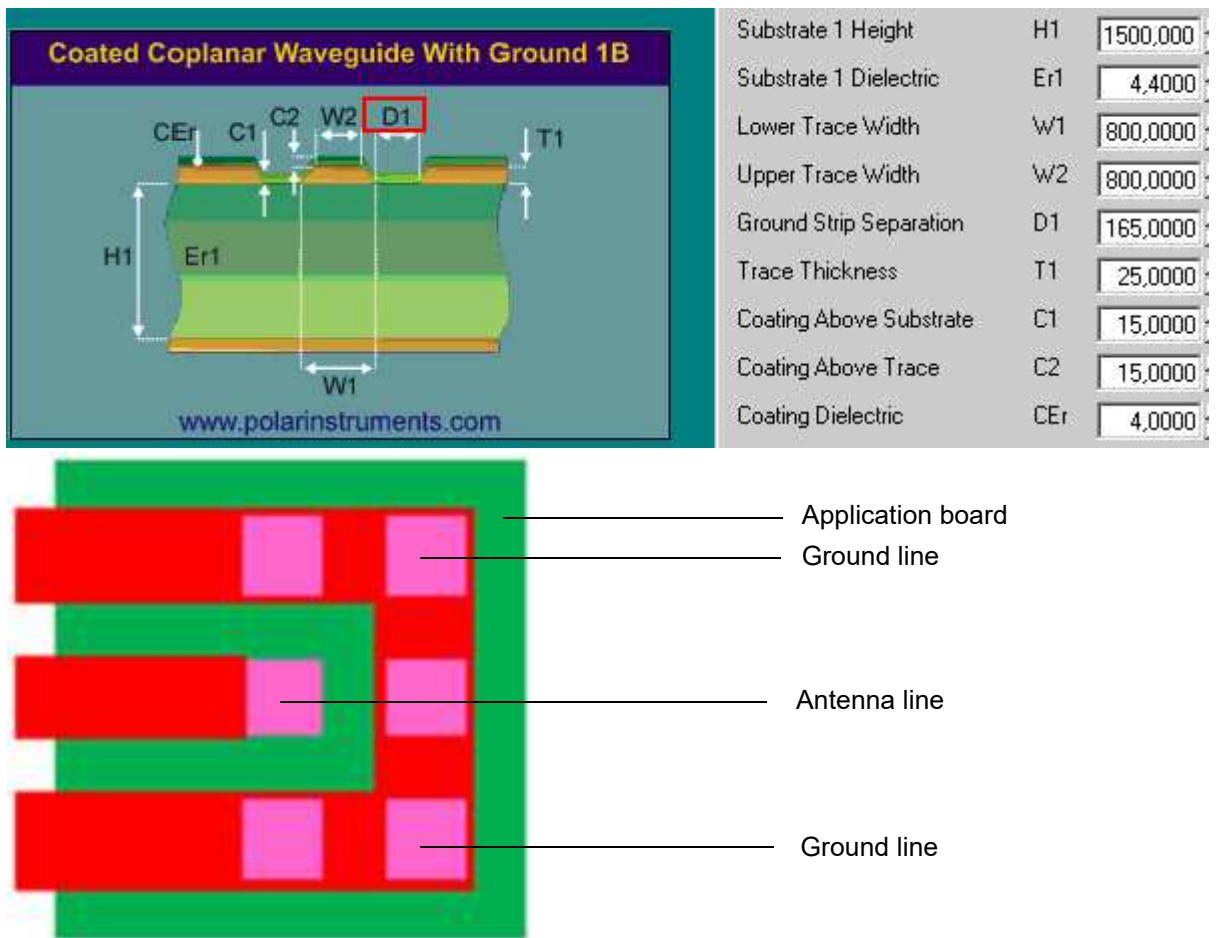


Figure 30: Micro-Stripline on 1.5mm Standard FR4 2-layer PCB - example 1

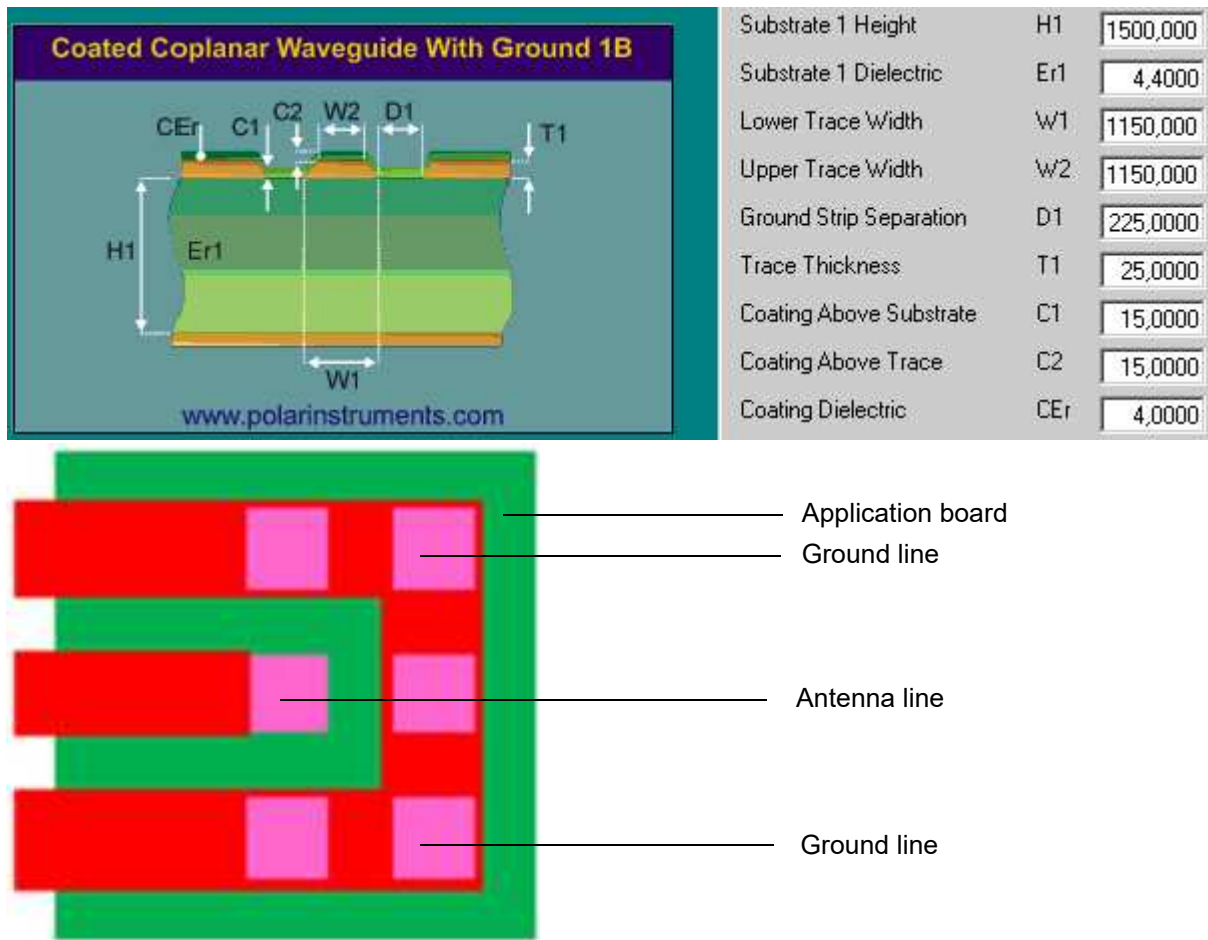


Figure 31: Micro-Stripline on 1.5mm Standard FR4 2-layer PCB - example 2

2.2.3.2 Routing Example

Interface to RF Connector

Figure 32 shows the connection of the module's antenna pad with an application PCB's coaxial antenna connector. Please note that the TX62/TX82 bottom plane appears mirrored, since it is viewed from TX62/TX82 top side. By definition the top of customer's board shall mate with the bottom of the TX62/TX82 module.

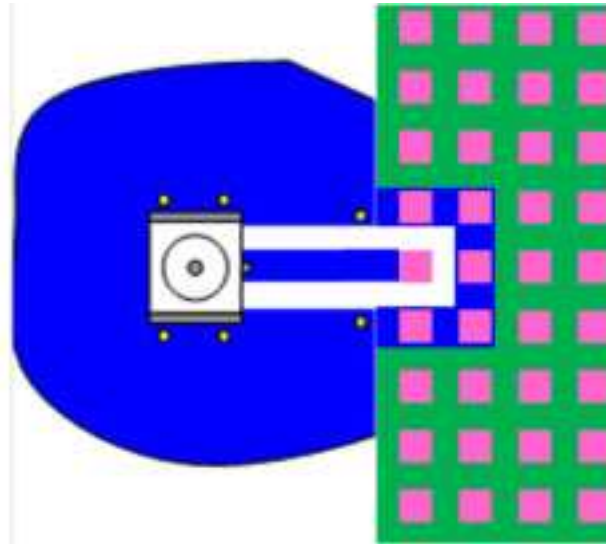


Figure 32: Routing to application's RF connector - top view

2.3 GNSS Interface

2.3.1 GNSS Receiver

TX62/TX82 integrates a GNSS receiver that offers the full performance of GPS/GLONASS/Bei-Dou/Galileo technology. The GNSS receiver is able to continuously track all satellites in view, thus providing accurate satellite position data.

The integrated GNSS receiver supports the NMEA protocol via ASC0 interface. NMEA is a combined electrical and data specification for communication between various (marine) electronic devices including GNSS receivers. It has been defined and controlled by the US based National Marine Electronics Association. For more information on the NMEA Standard please refer to <http://www.nmea.org>.

Depending on the receiver's knowledge of last position, current time and ephemeris data, the receiver's startup time (i.e., TTFF = Time-To-First-Fix) may vary: If the receiver has no knowledge of its last position or time, a startup takes considerably longer than if the receiver still has knowledge of its last position, time and almanac or has still access to valid ephemeris data and the precise time. For more information see [Section 2.3.3](#). Often, 2D measurements will be used over 3D depending on space vehicle (SV) locations as this will be just as accurate and faster.

By default, the GNSS receiver is switched off. It has to be switched on and configured using AT commands (AT^SGPSC; see [\[1\]](#)). Please note that concurrent GNSS and GSM/LTE operations are not supported (AT^SCFG= "MEopMode/RscMgmt/Rrc"; see [\[1\]](#)).

2.3.2 GNSS Antenna

In addition to the RF antenna interface TX62/TX82 also has a GNSS antenna interface. See [Section 2.1.1](#) to find out where the GNSS antenna pad is located. The GNSS installation is the same as for the RF antenna interface - see [Section 2.2.2](#).

It is possible to connect active or passive GNSS antennas. In either case the antennas must have 50Ω impedance. Please note that if an active GNSS antenna is selected, the voltage for it has to be supplied by the external application, and a capacitor must be added to avoid voltage back-feeding (see [Figure 33](#)). If a passive GNSS antenna is selected, this capacitor is optional.

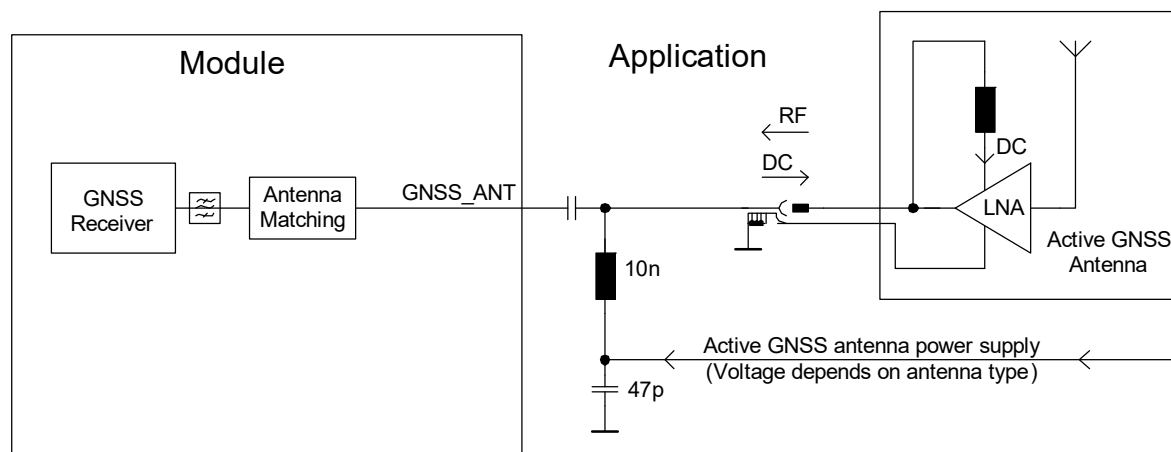


Figure 33: Sample supply voltage circuit for active GNSS antenna

2.3.3 GNSS Antenna Interface Characteristics

Table 14: GNSS properties

| Parameter | Conditions | Min. | Typical | Max. | Unit |
|---------------------------------------|--|----------|----------|----------|------|
| Horizontal accuracy | 50% CEP, open sky | | 2 | | m |
| Maximal update rate | | | 1 | | Hz |
| Frequency | GPS | 1573.397 | 1575.420 | 1576.443 | MHz |
| | GLONASS | 1598.563 | 1602.563 | 1606.563 | |
| | Beidou | 1559.052 | 1561.098 | 1563.144 | |
| | Galileo | 1573.397 | 1575.420 | 1576.443 | |
| Tracking Sensitivity | Open sky Active antenna or LNA Passive antenna: GPS GLONASS Beidou Galileo | | -162 | | dBm |
| Acquisition Sensitivity | Open sky Active antenna or LNA Passive antenna: GPS GLONASS Beidou Galileo | | -159 | | dBm |
| Time-to-First-Fix (TTFF) ¹ | Hot (average at -130dBm) | | 3 | | s |
| | Cold (average at -130dBm) | | 35 | | s |

1. Test conditions: open sky environment

2.4 Sample Application

Figure 34 shows a typical example of how to integrate a TX62/TX82 module with an application. Usage of the various host interfaces depends on the desired features of the application.

Note that the sample application is not optimized for low current consumption.

Because of the very low power consumption design, current flowing from any other source into the module circuit must be avoided, for example reverse current from high state external control lines. Therefore, the controlling application must be designed to prevent reverse current flow. Otherwise there is the risk of undefined states of the module during startup and shutdown or even of damaging the module.

Because of the high RF field density inside the module, it cannot be guaranteed that no self interference might occur, depending on frequency and the applications grounding concept. The potential interferers may be minimized by placing small capacitors (47pF) at suspected lines (e.g. RXD0, TXD0, and ON).

While developing SMT applications it is strongly recommended to provide test points for certain signals, i.e., lines to and from the module - for debug and/or test purposes. The SMT application should allow for an easy access to these signals. For details on how to implement test points see [5] and [6]. Possible test points are mentioned in Section 2.1.2.

The EMC measures are best practice recommendations. In fact, an adequate EMC strategy for an individual application is very much determined by the overall layout and, especially, the position of components. For example, mounting the internal acoustic transducers directly on the PCB eliminates the need to use the ferrite beads shown in the sample schematic.

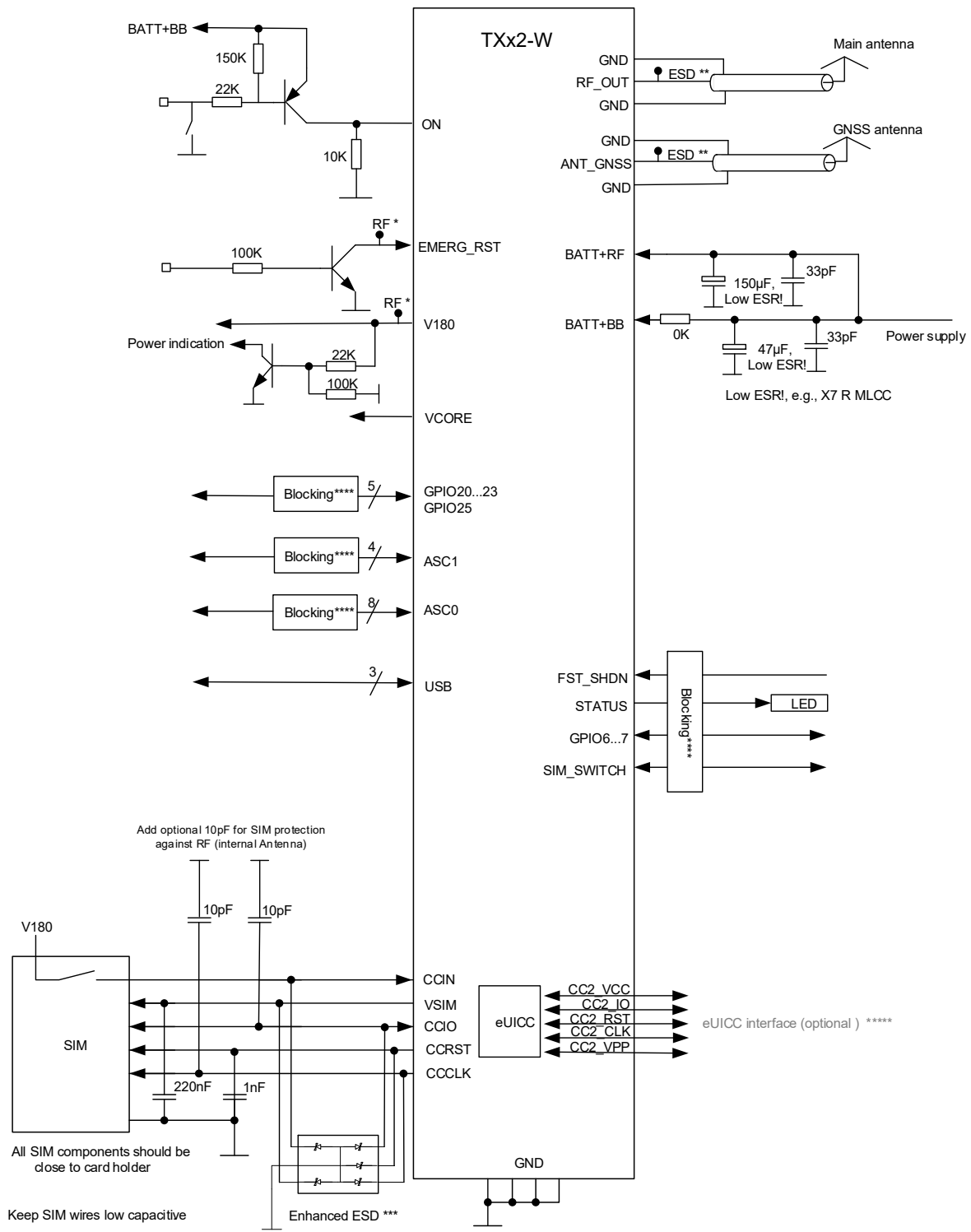
Depending on the micro controller used by an external application TX62/TX82's digital input and output lines may require level conversion. Section 2.4.1 shows a possible sample level conversion circuit.

Disclaimer

No warranty, either stated or implied, is provided on the sample schematic diagram shown in Figure 34 and the information detailed in this section. Functionality and compliance with national regulations depend to a great amount on the used electronic components, and the individual application layout manufacturers are required to ensure adequate design and operating safeguards for their products using TX62/TX82 modules. Because of the number of frequencies used it is recommended to involve antenna vendors already quite early to maximize performance of the external application's layout.

2.4 Sample Application

For switch on circuit see [Section 3.2.1](#)



RF* = Optional 47pF against self-interference. See also [Section 3.6](#) for measures against RF interference

ESD** = ESD protection for RF antenna interface. For more details see [Section 3.6.1](#)

Enhanced ESD*** = Enhanced ESD protection for SIM interface. For more details see [Section 2.1.6.1](#)

Blocking**** = For more details see [Section 3.6](#)

eUICC interface***** = For more details see [Section 2.1.7](#)

Figure 34: Schematic diagram of TX62/TX82 sample application

2.4.1 Sample Level Conversion Circuit

Depending on the micro controller used by an external application TX62/TX82's digital input and output lines (i.e., ASC0, ASC1) may require level conversion. The following [Figure 35](#) shows a sample circuit with recommended level shifters for an external application's micro controller (with VLOGIC between 3.0V...3.6V). The level shifters can be used for digital input and output lines with $V_{OH,max}=1.85V$ or $V_{IH,max}=1.85V$. The sample circuit is not optimized for low current consumption.

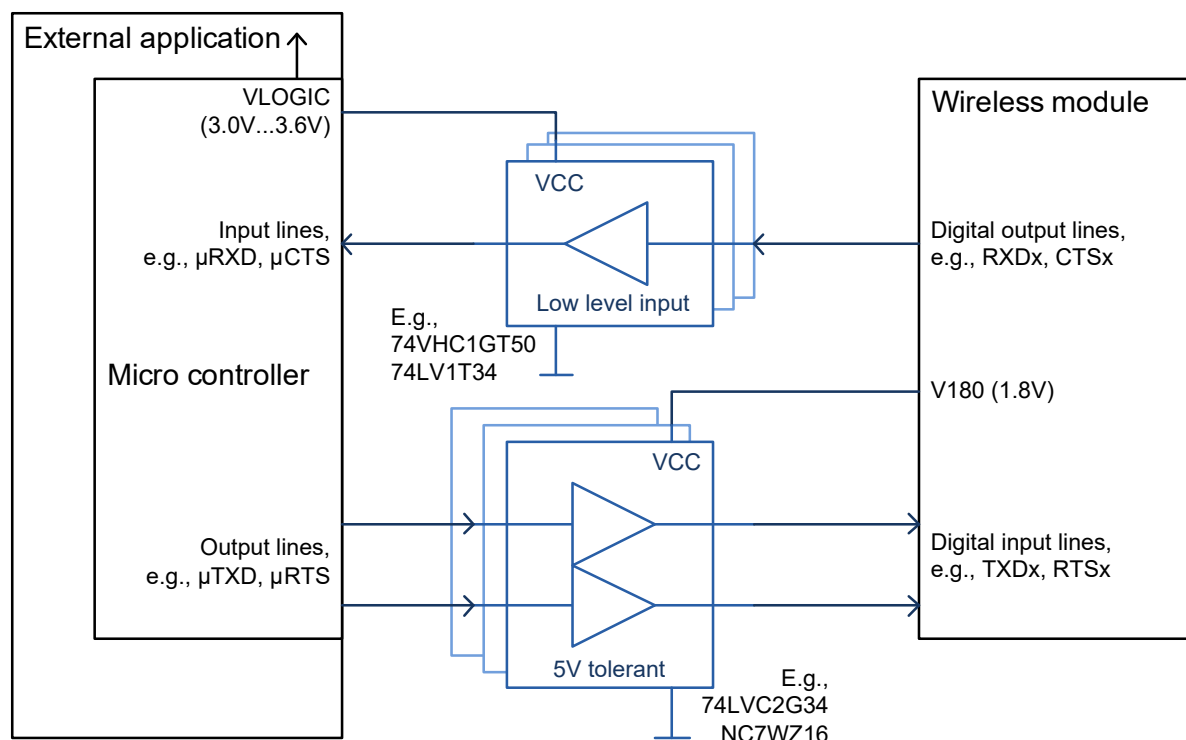


Figure 35: Sample level conversion circuit

3 Operating Characteristics

3.1 Operating Modes

The table below briefly summarizes the various operating modes referred to throughout the document.

Table 15: Overview of operating modes

| Mode | Function | |
|----------------------|---|---|
| Normal operation | Data transfer | GSM/(E)GPRS/LTE M1 NB1/2 data transfer in progress. |
| | Idle | Software and interfaces are active and ready to send and receive, but no GSM/(E)GPRS/LTE M1 NB1/2 data transfer is currently in progress. |
| SLEEP ¹ | <p>Low power mode when no call is in progress and there is no active communication on any serial interface (ASC0, ASC1). During SLEEP mode, the module is in a low power consumption state depending on paging cycles based on network defined DRX values, and optionally network negotiated eDRX (extended DRX) as well as 3GPP PSM values. The firmware is active to a minimum extent, and preserves the state it was in before entering the SLEEP mode. The module stays registered to the network.</p> <p>SLEEP mode option can be enabled/disabled by AT command (see : AT^SCFG parameter "MEopMode/PwrSave").</p> | |
| SUSPEND ¹ | <p>Low power mode when almost all components are switched off - except for the internal RTC and interrupt triggered wake up mechanisms. The module keeps registered to the network. The module is in its lowest power consumption state. The module can only be woken up by the ON or EMERG_RST signal, or it may wake up and be reachable again after expiration of a 3GPP PSM (Power Saving Mode) periodic TAU cycle (i.e., network timer) that may include DRX and/or eDRX paging cycles for a certain inactivity period. The module wakes up with its signal states being the same as for the first startup configuration, and does not preserve the signal states it had in before entering SUSPEND mode.</p> <p>The SUSPEND mode option can be enabled/disabled by AT commands (see MEopMode/PowerMgmt/Suspend").</p> | |
| Airplane | <p>Restricted operating mode where the module's radio part is shut down, causing the module to log off from the GSM/(E)GPRS/LTE M1 NB1/2 network, and to disable all AT commands whose execution requires a radio connection. Airplane mode can be controlled by AT command (see : AT+CFUN).</p> | |
| POWER DOWN | <p>State after normal shutdown by sending the switch off command (see : AT^SMSO). Software is not active. Interfaces are not accessible. Operating voltage remains applied.</p> | |

1. For details on the module's low power modes and their configuration, please refer to [Section 3.3](#).

3.2 Power Up/Power Down Scenarios

Do not turn on TX62/TX82 while it is beyond the safety limits of voltage stated in [Section 2.1.2.1](#). TX62/TX82 immediately switches off after having started and detected these inappropriate conditions. In extreme cases this can cause permanent damage to the module.

3.2.1 Turn on TX62/TX82

TX62/TX82 can be turned on as described in the following sections:

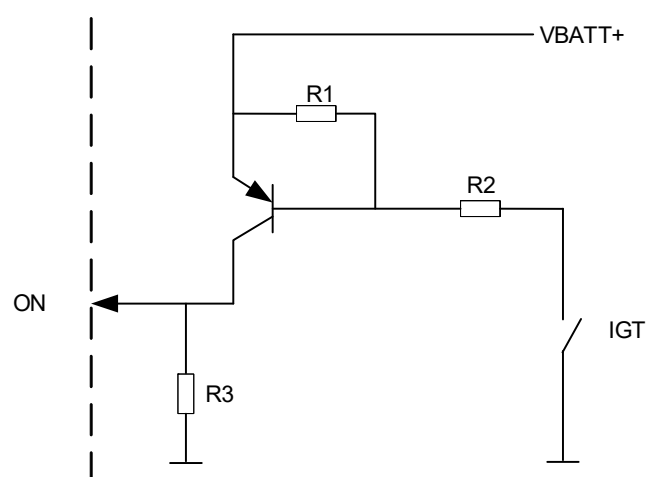
- Hardware driven switch on by ON signal: Starts Normal mode (see [Section 3.2.1.1](#) as well as [Section 3.2.1.2](#) (for automatic power on)).

After startup or restart, a high level of the V180 and VCORE lines, as well as the URC ^SYS-START send by the module indicate that the module has started up (again). The URC notifies the host application that the first AT command can be sent to the module (see also [\[1\]](#)).

3.2.1.1 Switch on TX62/TX82 Using ON Signal

The ON signal switches the module on, if the module is in POWER DOWN mode (or in SUSPEND mode - see [Section 3.3.1](#)). This signal is a rising edge sensitive signal. The maximum input voltage can be BATT+. The module starts in the operating mode with a rising edge signal at the ON signal.

The following [Figure 36](#) illustrates the recommended power on circuit, [Figure 37](#) and [Table 16](#) show the start-up behavior and timings if ON valid. Please note that the power on circuit is not optimized with regard to ultra low power consumption.



Recommended ratings: R1 = 150k, R2 = 22k, and R3 = 10k

Figure 36: Sample ON circuit

3.2 Power Up/Power Down Scenarios

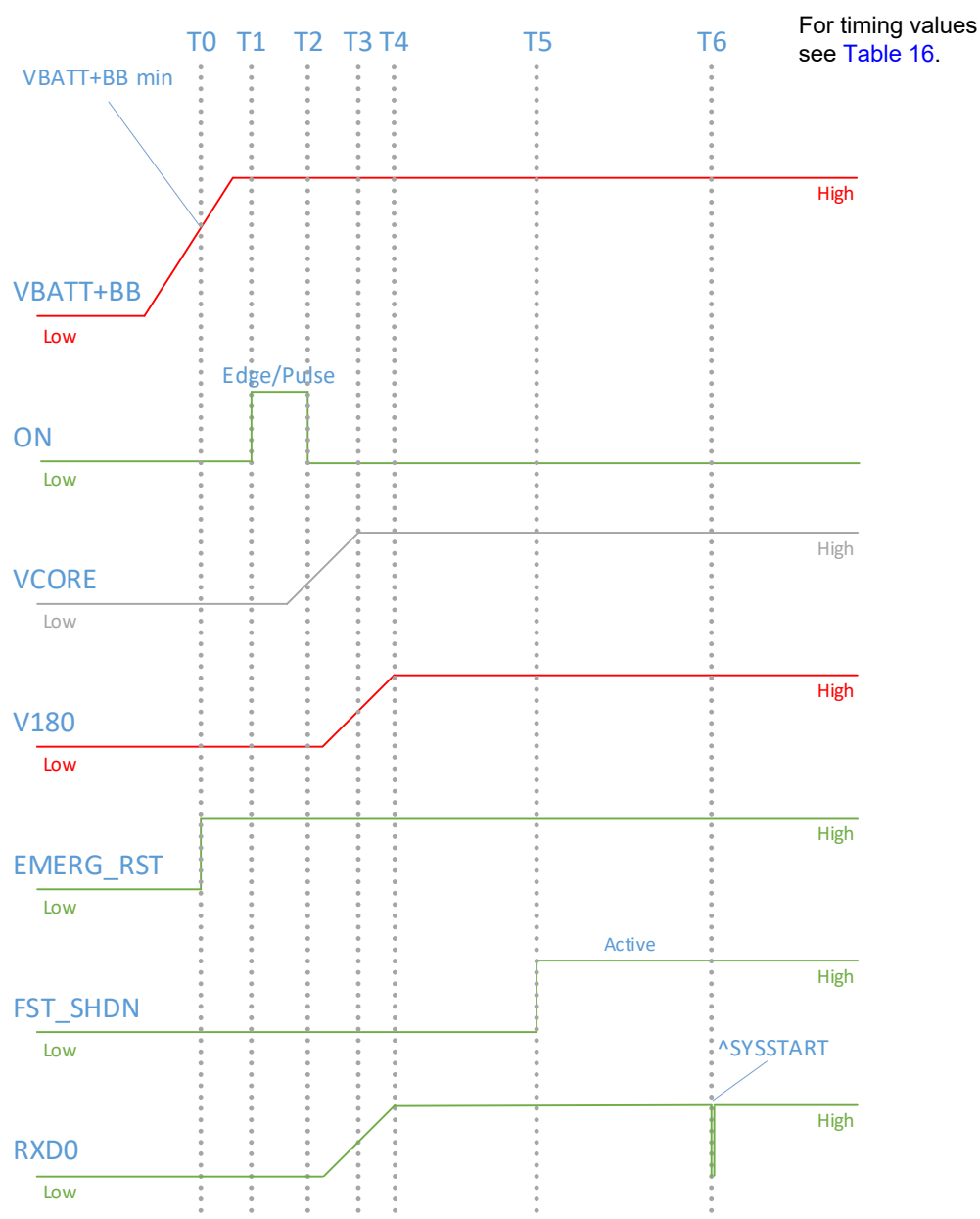


Figure 37: ON startup behavior

Table 16: ON startup timing values

| Timing | Description | Typical value | Unit |
|---------------|----------------------|---------------|------|
| TX62-W | | | |
| T0 - T1 | Minimum startup time | 50 | ms |
| T1 - T2 | Recommended ON pulse | 30 | ms |
| T2 - T3 | ON – VCORE | 23.51 | ms |
| T3 - T4 | VCORE – V180 | 262.15 | μs |
| T4 - T5 | V180 – FST_SHDN | 1.42 | s |
| T5 - T6 | FST_SHDN - ^SYSSTART | 1.81 | s |

3.2 Power Up/Power Down Scenarios

Table 16: ON startup timing values

| Timing | Description | Typical value | Unit |
|-----------------|----------------------|---------------|------|
| TX62-W-B | | | |
| T0 - T1 | Minimum startup time | 50 | ms |
| T1 - T2 | Recommended ON pulse | 30 | ms |
| T2 - T3 | ON – VCORE | 23.85 | ms |
| T3 - T4 | VCORE – V180 | 300.25 | µs |
| T4 - T5 | V180 – FST_SHDN | 2.78 | s |
| T5 - T6 | FST_SHDN - ^SYSSTART | 0.43 | s |
| TX62-W-C | | | |
| T0 - T1 | Minimum startup time | 50 | ms |
| T1 - T2 | Recommended ON pulse | 30 | ms |
| T2 - T3 | ON – VCORE | 23.61 | ms |
| T3 - T4 | VCORE – V180 | 333.34 | µs |
| T4 - T5 | V180 – FST_SHDN | 1.51 | s |
| T5 - T6 | FST_SHDN - ^SYSSTART | 2.05 | s |
| TX82-W | | | |
| T0 - T1 | Minimum startup time | 50 | ms |
| T1 - T2 | Recommended ON pulse | 30 | ms |
| T2 - T3 | ON – VCORE | 23.51 | ms |
| T3 - T4 | VCORE – V180 | 262.15 | µs |
| T4 - T5 | V180 – FST_SHDN | 1.42 | s |
| T5 - T6 | FST_SHDN - ^SYSSTART | 1.81 | s |
| TX82-W-B | | | |
| T0 - T1 | Minimum startup time | TBD. | ms |
| T1 - T2 | Recommended ON pulse | TBD. | ms |
| T2 - T3 | ON – VCORE | TBD. | ms |
| T3 - T4 | VCORE – V180 | TBD. | µs |
| T4 - T5 | V180 – FST_SHDN | TBD. | s |
| T5 - T6 | FST_SHDN - ^SYSSTART | TBD. | s |

Note: During the boot up phase of the module, the fast shutdown functionality, i.e., the use of the FST_SHDN line as described in [Section 2.1.11.3](#), is not available. The FST_SHDN functionality becomes active only at T5 (see [Table 16](#)).

In case of a power loss before the FST_SHDN line is active (T5), the data integrity is ensured even without the FST_SHDN functionality. Once the FST_SHDN line becomes active, the line can be used to ensure data integrity during for example a power loss scenario.

3.2.1.2 Automatic Power On

When an automatic power on circuit is required for the module application, the ON pulse must be generated after BATT+ is applied. To achieve this, it is recommended to add a monoflop circuit.

With the initial switch on after BATT+ was applied, the pulse of the ON signal must be longer than 1ms. Afterwards, and if the module was already turned off at least once by AT^SMSO, the pulse of the ON signal to switch the module on must be longer than 30ms.

Figure 38 shows a suitable sample circuit.

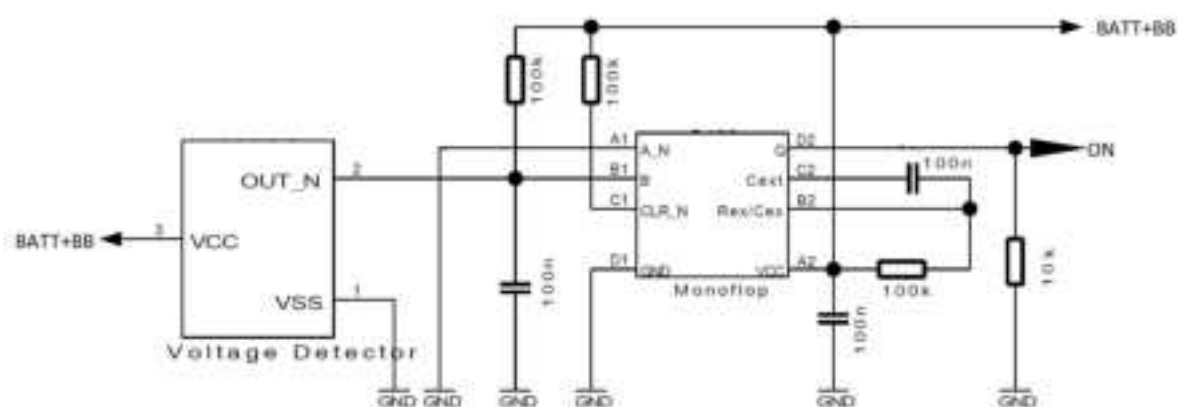


Figure 38: Automatic switch ON circuit sample

For the sample voltage detector circuit it is recommended to use the voltage detector NCP803SN232T1G from ON Semiconductor, and the monoflop 74LVC1G123 from Nexperia.

3.2.2 Restart TX62/TX82

After startup TX62/TX82 can be re-started as described in the following sections:

- Software controlled reset by AT+CFUN command: Starts Normal mode (see [Section 3.2.2.1](#)).
- Hardware controlled reset by EMERG_RST line: Starts Normal mode (see [Section 3.2.2.2](#))

3.2.2.1 Restart TX62/TX82 via AT+CFUN Command

To reset and restart the TX62/TX82 module use the command AT+CFUN. See [\[1\]](#) for details.

3.2.2.2 Restart TX62/TX82 Using EMERG_RST

The EMERG_RST signal is internally connected to the baseband processor. A low level phase until V180 went low triggers the module restart process, and sets the processor and all signals to their respective reset states. With a shorter low level phase, i.e., V180 low state not reached, no module restart is triggered, and the module's state remains unchanged. The reset state is described in [Section 3.2.3](#) as well as in the figures showing the startup behavior of an interface.

Please note that if the EMERG_RST signal is not released again as shown in [Figure 39](#), i.e., changed from low to high after a restart/reset, the module will be repeatedly restarted.

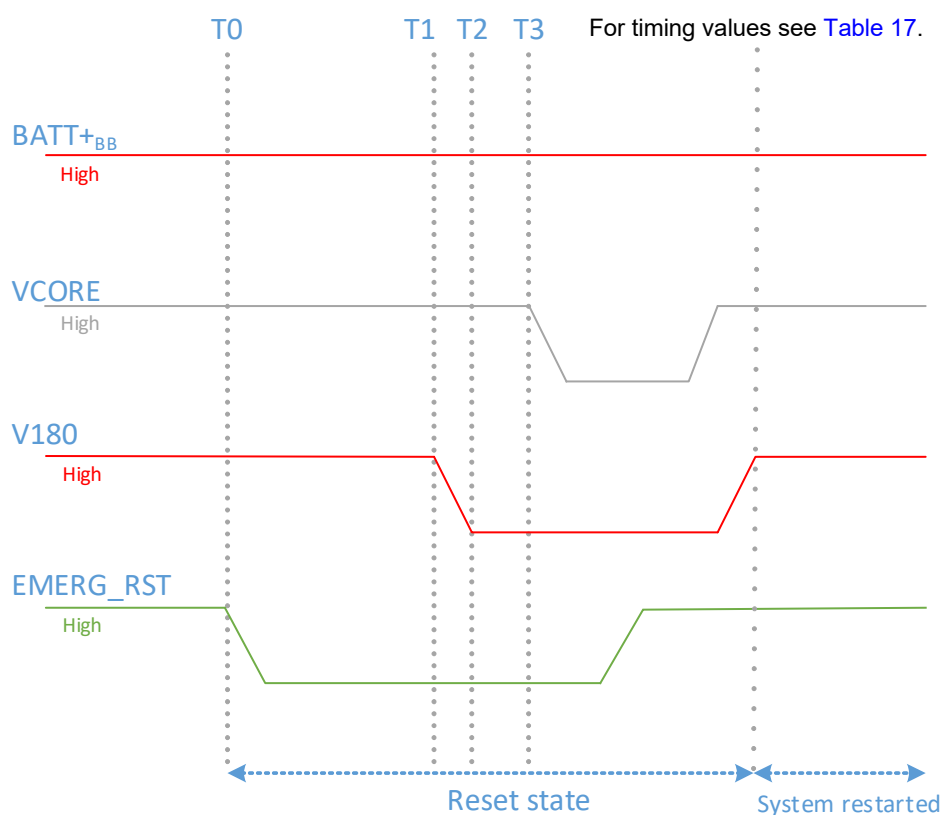


Figure 39: Emergency restart behavior

3.2 Power Up/Power Down Scenarios

Table 17: EMERG_RST restart timing values

| Timing | Description | Typical value | Unit |
|----------|--------------------|---------------|------|
| TX62-W | | | |
| T0 - T1 | EMERG_RST - V180 | 763.42 | ms |
| T1 - T2 | V180 – V180 (low) | 1.05 | |
| T2 - T3 | V180 (low) – VCORE | 3.96 | |
| TX62-W-B | | | |
| T0 - T1 | EMERG_RST - V180 | 771.22 | ms |
| T1 - T2 | V180 – V180 (low) | 0.94 | |
| T2 - T3 | V180 (low) – VCORE | 4.09 | |
| TX62-W-C | | | |
| T0 - T1 | EMERG_RST - V180 | 767.14 | ms |
| T1 - T2 | V180 – V180 (low) | 0.62 | |
| T2 - T3 | V180 (low) – VCORE | 2.55 | |
| TX82-W | | | |
| T0 - T1 | EMERG_RST - V180 | 763.42 | ms |
| T1 - T2 | V180 – V180 (low) | 1.05 | |
| T2 - T3 | V180 (low) – VCORE | 3.96 | |
| TX82-W-B | | | |
| T0 - T1 | EMERG_RST - V180 | TBD. | ms |
| T1 - T2 | V180 – V180 (low) | TBD. | |
| T2 - T3 | V180 (low) – VCORE | TBD. | |

It is strongly recommended to control this EMERG_RST line with an open collector transistor or an open drain field-effect transistor.

Caution: Use the EMERG_RST line only when, due to serious problems, the software is not responding for more than 5 seconds. Pulling the EMERG_RST line causes the loss of all information stored in the volatile memory. Therefore, this procedure is intended only for use in case of emergency, e.g. if TX62/TX82 does not respond, if reset or shutdown via AT command fails.

3.2.3 Signal States after Startup

[Table 18](#) describes various states interface signals pass through after startup until the system is active.

Signals are in an initial state while the module is initializing. Once the startup initialization has completed, i.e. when the software is running, all signals are in a defined state, the module is ready to receive and transmit data. The state of some signals may change again once a respective interface is activated or configured by AT command. For details on certain other signal state changes during startup see also [Section 3.2.1](#) (ON, VCORE, V180), [Section 3.2.2](#) (EMERG_RST), and [Section 2.1.4](#) (ASC0 signals).

Table 18: Signal states

| Signal name | Reset state | First start up configuration |
|---------------------|-------------|------------------------------|
| CCIO | PD | O / L |
| CCRST | PD | O / L |
| CCCLK | PD | O / L |
| CCIN | PD | I / PD |
| RXD0 | PD | O / H |
| TXD0 | PD | I / PD |
| CTS0 | PD | O / H |
| RTS0 | PD | I / PD |
| DTR0 | PD | I / PU |
| DCD0 | PD | O / H |
| DSR0 | PD | O / H |
| RING0 | PD | O / H |
| RXD1 | PD | O / H |
| TXD1 | PD | I / PD |
| CTS1 | PD | O / H |
| RTS1 | PD | I / PD |
| STATUS | PD | I / PD |
| FST_SHDN | PD | I / PU |
| I2CDAT ¹ | PD | OD |
| I2CCLK ¹ | PD | OD |
| SIM_SWITCH | PD | I / PD |
| SUSPEND_MON | PD | I / PD |
| GPIO6,7,20-23,25 | PD | High-Z / PD |

1. Available with embedded processing option only.

Abbreviations used in above [Table 18](#):

| | |
|---|---|
| L = Low level H = High level High-Z = High Impedance I = Input | O = Output OD = Open Drain PD = Pull down, 55kΩ ~390kΩ PU = Pull up, 55kΩ ~390kΩ |
|---|---|

3.2.4 Turn off TX62/TX82

To switch the module off the following procedures may be used:

- *Software controlled shutdown procedure*: Software controlled by sending an AT command over the serial application interface. See [Section 3.2.4.1](#).
- *Hardware controlled shutdown procedure*: Hardware controlled by setting the FST_SHDN line to low. See [Section 2.1.11.3](#).
- *Automatic shutdown (software controlled)*: See [Section 3.2.5](#)
 - Takes effect if TX62/TX82 board temperature exceeds a critical limit, or if
 - Undervoltage or overvoltage is detected.

With any shutdown scenario it is recommended to monitor the V180 line. If V180 is low, it is safe to cut the module power supply. Cutting the power supply too early, i.e., if V180 is not low, might harm the module.

3.2.4.1 Switch off TX62/TX82 Using AT Command

The best and safest approach to powering down the module is to issue the AT^SMSO command. This procedure lets the module log off from the network and allows the software to enter into a secure state and to save data before disconnecting the power supply. Any AT commands after AT^SMSO are ignored, and the shutdown procedure continues undisturbed. The shutdown procedure is an active process (depending on environmental conditions such as network states) until the module switches off - for signal behavior and timings see [Figure 40](#) and [Table 19](#). It cannot be specified how long the shutdown procedure may take at the worst.

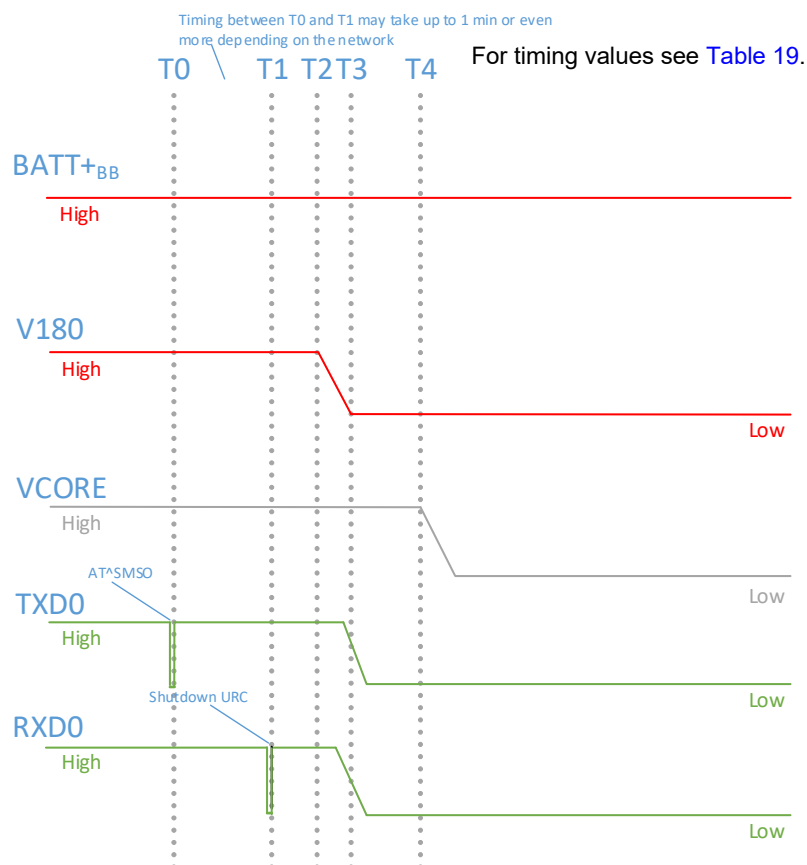


Figure 40: Switch off behavior

3.2 Power Up/Power Down Scenarios

Table 19: Switch off timing values (AT^SMSO)

| Timing | Description | Typical value | Unit |
|----------|--------------------|--|------|
| TX62-W | | | |
| T0 - T1 | AT^SMSO – URC | 294.13 ¹ (depending on network) | ms |
| T1 - T2 | URC – V180 | 13.68 | |
| T2 - T3 | V180 – V180 (low) | 0.83 | |
| T3 - T4 | V180 (low) – VCORE | 2.41 | |
| TX62-W-B | | | |
| T0 - T1 | AT^SMSO – URC | 302.63 ¹ (depending on network) | ms |
| T1 - T2 | URC – V180 | 13.70 | |
| T2 - T3 | V180 – V180 (low) | 0.70 | |
| T3 - T4 | V180 (low) – VCORE | 2.50 | |
| TX62-W-C | | | |
| T0 - T1 | AT^SMSO – URC | 234.92 ¹ (depending on network) | ms |
| T1 - T2 | URC – V180 | 37.17 | |
| T2 - T3 | V180 – V180 (low) | 0.65 | |
| T3 - T4 | V180 (low) – VCORE | 2.53 | |
| TX82-W | | | |
| T0 - T1 | AT^SMSO – URC | 294.13 ¹ (depending on network) | ms |
| T1 - T2 | URC – V180 | 13.68 | |
| T2 - T3 | V180 – V180 (low) | 0.83 | |
| T3 - T4 | V180 (low) – VCORE | 2.41 | |
| TX82-W-B | | | |
| T0 - T1 | AT^SMSO – URC | TBD. | ms |
| T1 - T2 | URC – V180 | TBD. | |
| T2 - T3 | V180 – V180 (low) | TBD. | |
| T3 - T4 | V180 (low) – VCORE | TBD. | |

1. Value is dependent on network, and may take up to 5 seconds for LTE Cat NB1/2 networks.

A low level of the V180 signal - in addition to the regular "^SHUTDOWN" URC issued by the module - indicates that the switch off procedure has completed and the module has entered the Power Down mode.

Note: Using the command AT^SMSO="fast", it is possible to trigger a fast shutdown procedure, i.e., shutting down without gracefully deregistering from the network thus saving time between T0 - T2. Same as with the fast shutdown procedure triggered with the FST_SHDN line (see [Section 2.1.11.3](#)), there will be no ^SHUTDOWN URC in this case. The timings for module switch off using AT^SMSO="fast" are listed below in [Table 20](#).

3.2 Power Up/Power Down Scenarios

Table 20: Switch off timing values (AT^SMSO="fast")

| Timing | Description | Typical value | Unit |
|----------|----------------------|---------------|------|
| TX62-W | | | |
| T0 - T1 | AT^SMSO="fast" – URC | 3.34 | ms |
| T1 - T2 | URC – V180 | 1.51 | |
| T2 - T3 | V180 – V180 (low) | 0.83 | |
| T3 - T4 | V180 (low) – VCORE | 2.39 | |
| TX62-W-B | | | |
| T0 - T1 | AT^SMSO="fast" – URC | 3.48 | ms |
| T1 - T2 | URC – V180 | 8.87 | |
| T2 - T3 | V180 – V180 (low) | 0.67 | |
| T3 - T4 | V180 (low) – VCORE | 2.53 | |
| TX62-W-C | | | |
| T0 - T1 | AT^SMSO="fast" – URC | 4.62 | ms |
| T1 - T2 | URC – V180 | 12.28 | |
| T2 - T3 | V180 – V180 (low) | 0.59 | |
| T3 - T4 | V180 (low) – VCORE | 2.62 | |
| TX82-W | | | |
| T0 - T1 | AT^SMSO="fast" – URC | 3.34 | ms |
| T1 - T2 | URC – V180 | 1.51 | |
| T2 - T3 | V180 – V180 (low) | 0.83 | |
| T3 - T4 | V180 (low) – VCORE | 2.39 | |
| TX82-W-B | | | |
| T0 - T1 | AT^SMSO="fast" – URC | TBD. | ms |
| T1 - T2 | URC – V180 | TBD. | |
| T2 - T3 | V180 – V180 (low) | TBD. | |
| T3 - T4 | V180 (low) – VCORE | TBD. | |

3.2.5 Automatic Shutdown

Automatic shutdown takes effect if the following event occurs:

- The TX62/TX82 board is exceeding the critical limits of overtemperature or undertemperature (see [Section 3.2.5.1](#))
- Undervoltage or overvoltage is detected (see [Section 3.2.5.2](#) and [Section 3.2.5.3](#))

The automatic shutdown procedure is equivalent to the power-down initiated with an AT command, i.e. TX62/TX82 logs off from the network and the software enters a secure state avoiding loss of data.

3.2.5.1 Thermal Shutdown

The board temperature is constantly monitored by an internal NTC resistor located on the PCB. The values detected by the NTC resistor are measured directly on the board and therefore, are not fully identical with the ambient temperature.

Each time the board temperature goes out of range or back to normal, TX62/TX82 instantly displays an alert (if enabled).

- URCs indicating the level "1" or "-1" allow the user to take appropriate precautions, such as protecting the module from exposure to extreme conditions. The presentation of the URCs depends on the settings selected with the AT^SCTM write command (for details see):
AT^SCTM=1: Presentation of URCs is always enabled.
AT^SCTM=0 (default): Presentation of URCs is enabled during the 2 minute guard period after start-up of TX62/TX82. After expiry of the 2 minute guard period, the presentation of URCs will be disabled, i.e. no URCs with alert levels "1" or "-1" will be generated.
- URCs indicating the level "2" or "-2" are followed by an orderly shutdown after 5 seconds unless the temperature returns to a valid operating level ("1", "0", "-1") or the shutdown ability was disabled with AT^SCFG, "MEopMode/ShutdownOnCritTemp", <sdoct>. The presentation of these URCs is always enabled, i.e. they will be output even though the factory setting AT^SCTM=0 was never changed.

The maximum temperature ratings are stated in [Section 3.5](#). Refer to [Table 21](#) for the associated URCs.

Table 21: Temperature dependent behavior

| Sending temperature alert (2min after module start-up, otherwise only if URC presentation enabled) | |
|--|---|
| ^SCTM_B: 1 | Board close to overtemperature limit. |
| ^SCTM_B: -1 | Board close to undertemperature limit. |
| ^SCTM_B: 0 | Board back to non-critical temperature range. |
| Automatic shutdown after 5 seconds (URC appears no matter whether presentation was enabled or not) | |
| ^SCTM_B: 2 | Alert: Board equal or beyond overtemperature limit. TX62/TX82 switches off. |
| ^SCTM_B: -2 | Alert: Board equal or below undertemperature limit. TX62/TX82 switches off. |

3.2.5.2 Undervoltage Shutdown

The undervoltage shutdown threshold is the specified minimum supply voltage V_{BATT+} given in [Table 4](#). When the average supply voltage measured by TX62/TX82 approaches the undervoltage shutdown threshold (i.e., 0.05V offset) the module will send the following URC:

^SBC: Undervoltage

If the undervoltage persists the module will send the URC several times before switching off automatically.

This type of URC does not need to be activated by the user. It will be output automatically when fault conditions occur.

Note: For battery powered applications it is strongly recommended to implement a BATT+ connecting circuit in order to not only be able save power, but also to restart the module after an undervoltage shutdown where the battery is deeply discharged. Also note that the undervoltage threshold is calculated for max. 400mV voltage drops during transmit burst. Power supply sources for external applications should be designed to tolerate 400mV voltage drops without crossing the lower limit of 3.3V. For external applications operating at the limit of the allowed tolerance the default undervoltage threshold may be adapted by subtracting an offset. For details see [\[1\]](#): AT^SCFG= "MESHUTDOWN/sVsup/threshold".

3.2.5.3 Overvoltage Shutdown

The overvoltage shutdown threshold is the specified maximum supply voltage V_{BATT+} given in [Table 4](#). When the average supply voltage measured by TX62/TX82 approaches the overvoltage shutdown threshold (i.e., 0.05V offset) the module will send the following URC:

^SBC: Overvoltage Warning

The overvoltage warning is sent only once - until the next time the module is close to the overvoltage shutdown threshold.

If the voltage continues to rise above the specified overvoltage shutdown threshold, the module will send the following URC:

^SBC: Overvoltage Shutdown

This alert is sent only once before the module shuts down cleanly without sending any further messages.

This type of URC does not need to be activated by the user. It will be output automatically when fault conditions occur.

Keep in mind that several TX62/TX82 components are directly linked to BATT+ and, therefore, the supply voltage remains applied at major parts of TX62/

TX82. Especially the power amplifier linked to BATT+_{RF} is sensitive to high voltage and might even be destroyed.

3.3 Power Saving

TX62/TX82 can control its power consumption through specific features as summarized in [Table 22](#), and further detailed in the following sections. The mentioned operating modes are detailed in [Section 3.1](#). For typical power supply ratings during power saving please refer to [Section 3.4.1](#).

Table 22: Power saving features

| Module operation mode | Network actions | Power Saving Features |
|---|-----------------|--|
| Normal operation (network connected) | | |
| Data transfer | Active transfer | Radio Output Power Reduction (ROPR) for GSM only |
| IDLE | DRX paging | Paging cycles based on DRX values provided by network |
| | eDRX paging | Paging cycles based on eDRX values negotiated with network |
| | 3GPP PSM paging | Paging cycles based on 3GPP PSM values negotiated with network |
| Low power operation (network connected) | | |
| SLEEP | DRX paging | Serial interface (ASC0, ASC1) shut down - except for RTS0/1 available Paging cycles based on DRX values provided by network |
| | eDRX paging | Serial interface (ASC0, ASC1) shut down - except for RTS0/1 available Paging cycles based on provided DRX and negotiated eDRX values |
| | 3GPP PSM paging | Serial interface (ASC0, ASC1) shut down - except for RTS0/1 available Paging cycles based on provided DRX, negotiated optional eDRX, and PSM values |
| SUSPEND | DRX paging | All components shut down - except for RTC and certain signal triggers Paging cycles based on DRX values provided by network |
| | eDRX paging | All components shut down - except for RTC and certain signal triggers Paging cycles based on provided DRX and negotiated eDRX values |
| | 3GPP PSM paging | All components shut down - except for RTC and certain signal triggers Paging cycles based on provided DRX, negotiated optional eDRX, and PSM values |
| No network connection | | |
| Airplane | -- | Module radio part shut down |
| POWER DOWN | -- | Module switched off. Standby state with BATT+ connected |
| Power off | -- | Module switched off. BATT+ not connected |

3.3.1 Low Power Modes

There are two specific low power modes available that can be configured to allow TX62/TX82 to save power - SLEEP mode ([Section 3.3.1.1](#)) and SUSPEND mode ([Section 3.3.1.2](#)).

Figure 41 illustrates how the module transits between its operating modes including SLEEP and SUSPEND modes.

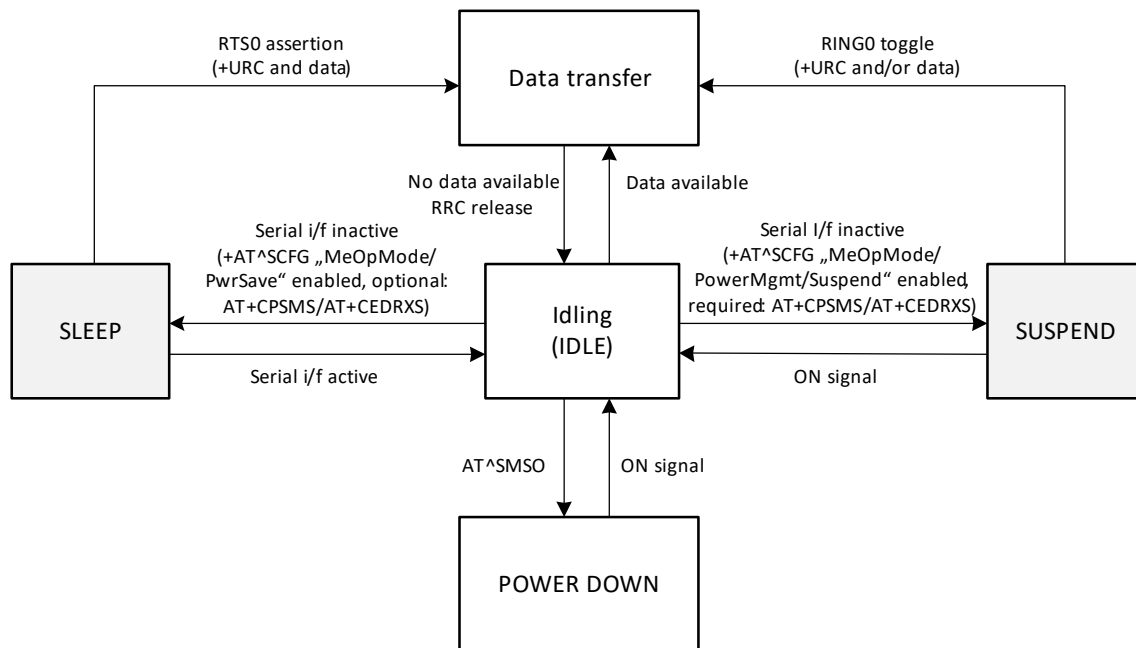


Figure 41: Low power modes with state transitions

Notes:

- When all serial interfaces (i.e. ASC0, and ASC1) are idle, the module can enter SLEEP or SUSPEND mode depending on additional configuration settings.
- The serial interfaces are not idle if there is any response message not read out from any of them.

3.3.1.1 SLEEP Mode

SLEEP mode is a module's low power mode when no call is in progress and there is no active communication on any serial interface (ASC0, ASC1). During SLEEP mode, the serial interfaces are shut down except for RTS0 that may be used to wake up TX62/TX82 from SLEEP mode (see below). The module is in a low power consumption state depending on paging cycles based on network defined DRX values, and possibly network negotiated eDRX (extended DRX) as well as 3GPP PSM values - if configured.

The firmware is active to a minimum extent, and preserves the state it was in before entering the SLEEP mode. The module stays registered to the network.

For details on the network based DRX values see [Section 3.3.2.1](#) (GSM/(E)GPRS) and [Section 3.3.3.1](#) (LTE M1 NB1/2). For details on the network negotiated eDRX values see [Section 3.3.3.2](#), for network negotiated 3GPP PSM values see [Section 3.3.3.3](#).

The SLEEP mode option can be enabled/disabled by AT command (see [\[1\]](#): AT^SCFG parameter "MEopMode/PwrSave").

RTS0 can be used to wake up TX62/TX82 from SLEEP mode between paging cycles. Assertion of RTS0 (i.e., toggle from inactive high to active low) serves as wake up event, thus allowing an external application to almost immediately terminate power saving. After RTS0 assertion, the CTS0 line signals module wake up, i.e., readiness of the AT command interface. It is therefore recommended to enable RTS/CTS flow control (default setting). [Figure 42](#) shows the described RTS0 wake up mechanism.

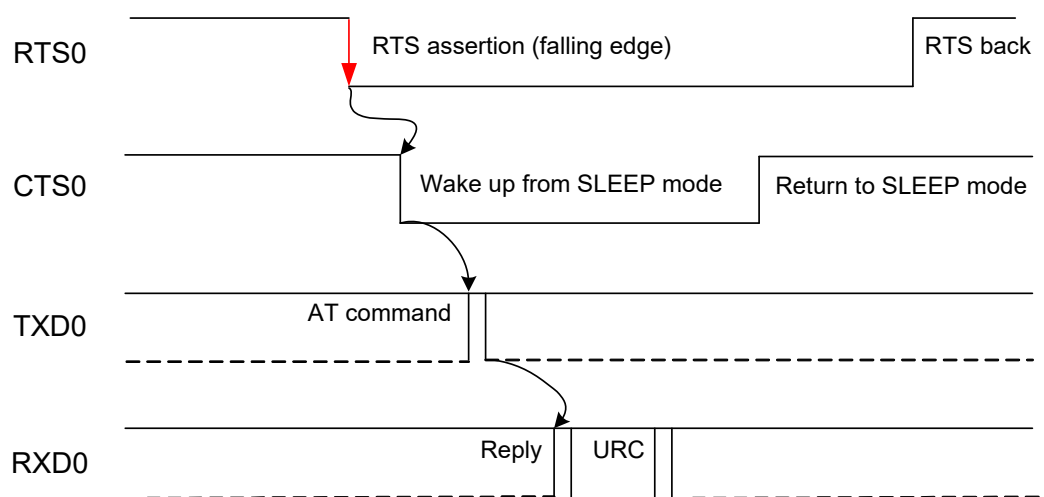


Figure 42: Wake-up via RTS0

3.3.1.2 SUSPEND Mode

In contrast to SLEEP mode, SUSPEND mode is a module's low power mode with almost all components switched off - except for the internal RTC and interrupt triggered wake up mechanisms. The module stays registered to the network, and the RRC connection is released. The module is in its lowest power consumption state.

Once the SUSPEND mode is enabled via AT command (see MEopMode/PowerMgmt/Suspend"), and the appropriate SUSPEND mode indicators are enabled (see PSM and possible eDRX settings need to be negotiated with the network. eDRX and PSM network settings are described in more detail in [Section 3.3.3.2](#) and [Section 3.3.3.3](#).

If the PSM settings are agreed upon with the network, TX62/TX82 is able to enter SUSPEND mode, and the following AT^SIND URC is generated:

+CIEV: "suspendAvailable",1

In addition, if there is no further communication with the network, and the module is ready to enter SUSPEND mode, the following AT^SIND URC is generated:

+CIEV: "suspendReady",1

Also, the SUSPEND_MON signal will turn low as soon as the module enters SUSPEND mode (see [Section 2.1.11.5](#)).

[Figure 43](#) shows the handshake between external application, module and the network for entering SUSPEND mode or possibly SLEEP mode depending on configuration and network response.

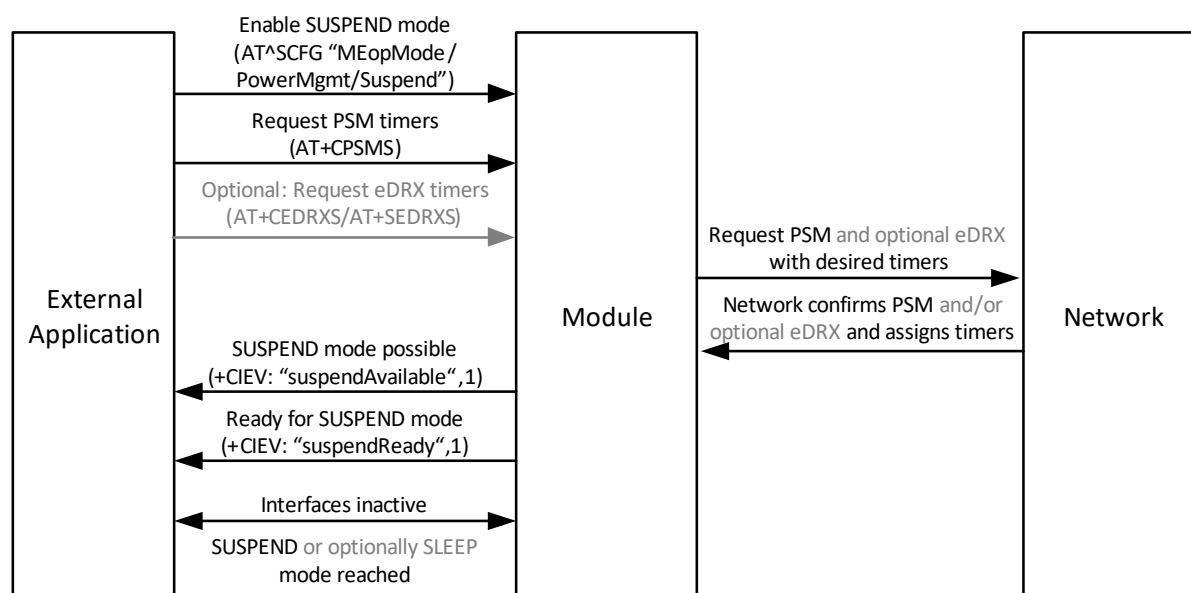


Figure 43: Handshake for entering the module's SUSPEND mode

3.3 Power Saving

From SUSPEND mode the module can only be woken up by the ON or EMERG_RST signals, or it may wake up and be reachable again after expiration of a negotiated 3GPP PSM periodic TAU cycle (i.e., network timer) that may include DRX as well as eDRX paging cycles for an inactivity period (see [Section 3.3.3.3](#) for details).

The module wakes up with its signal states being the same as the first startup configuration (see [Section 3.2.3](#)), and does not preserve the signal states it had in before entering SUSPEND mode.

[Figure 44](#) shows the handshake between external application, module and network for waking up the module via ON/EMERG_RST signal.

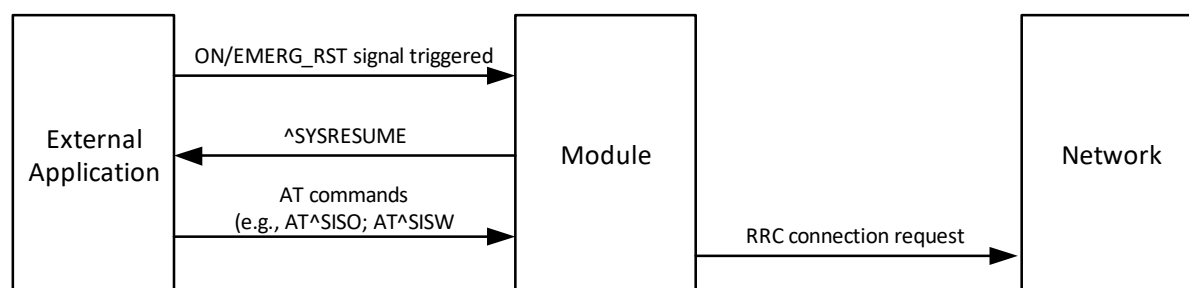


Figure 44: Handshake for module wake up via ON signal

[Figure 45](#) shows the handshake between external application, module and network for waking up the module after expiry of the 3GPP PSM periodic TAU cycle (Tracking Area Update).

In this case the module automatically wakes up, and is reachable by the network to receive data (e.g., an SMS). The module wakeup can be indicated to the external application by toggling the RING0 line. See [\[1\]](#) for the AT^SGPICFG command to control the RING0 logic level. The external application should now activate the appropriate communication interfaces to wake up the module from SUSPEND mode, to receive the ^SYSRESUME URC, and to be able to transfer data.

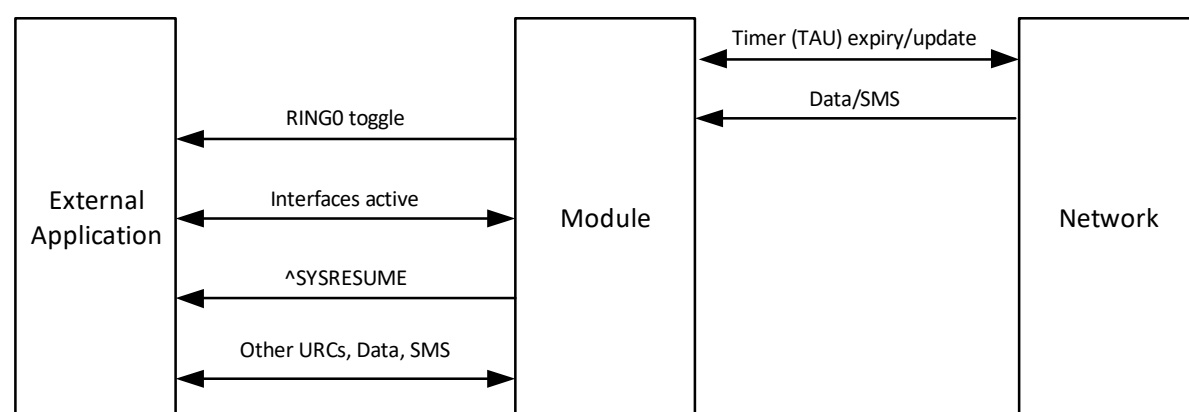


Figure 45: Handshake for module wake up after eDRX/PSM timer expiry

3.3.2 Power Saving while Attached to GSM Networks (TX82-W only)

Power saving while attached to GSM networks is based on standard DRX values defined for the network (see [Section 3.3.2.1](#)).

Apart from network based power saving it is possible to use the AT command `AT+SCFG="Radio/OutputPowerReduction"` for the module in (E)GPRS multislot scenarios to reduce its output power according to 3GPP 45.005. By default a maximum power reduction is enabled. For details on this AT command see [\[1\]](#).

3.3.2.1 DRX (Standard Configuration)

The power saving possibilities while attached to a GSM network depend on the paging timing cycle of the base station. The duration of a power saving interval can be calculated using the following formula:

$$t = 4.615 \text{ ms (TDMA frame duration)} * 51 \text{ (number of frames)} * \text{DRX value.}$$

DRX (Discontinuous Reception) is a value from 2 to 9, resulting in paging intervals between 0.47 and 2.12 seconds. The DRX value of the base station is assigned by the GSM network operator.

In the pauses between listening to paging messages, the module resumes power saving, i.e., SLEEP mode, as shown in [Figure 46](#).

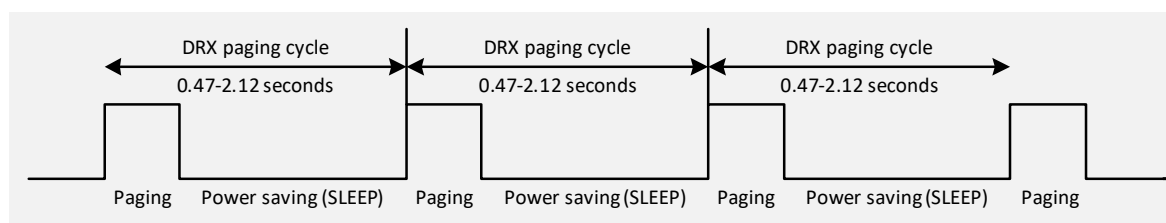


Figure 46: DRX based paging and power saving (SLEEP) in GSM networks

The varying pauses explain the different potential for power saving during SLEEP mode. The longer the pause the less power is consumed.

Generally, power saving depends on the module's application scenario and may differ from the above mentioned normal operation. The power saving interval may be shorter than 0.47 seconds or longer than 2.12 seconds.

3.3.2.2 eDRX (Extended DRX Configuration)

Note: eDRX support for GSM networks is disabled. eDRX support is only available for LTE Cat M1 and Cat NB1/2 networks (see [Section 3.3.3.2](#)).

3.3.3 Power Saving while Attached to LTE M1 NB1/2 Networks

This section describes the power saving possibilities in LTE Cat M1 and LTE Cat NB1/2 networks through DRX (see [Section 3.3.3.1](#)) values, as well as configurable eDRX (see [Section 3.3.3.2](#)), and 3GPP PSM (see [Section 3.3.3.3](#)) timers.

3.3.3.1 DRX (Standard Configuration)

TX62/TX82 can be enabled to use DRX (Discontinuous Reception) in RRC idle mode to reduce power consumption (see also [Section 3.3.1.1](#)). The power saving possibilities while attached to an LTE Cat M1 or LTE Cat NB1/2 network depend on the paging timing cycle of the base station.

During normal operation, i.e., the module is connected to an LTE Cat M1 or LTE Cat NB1/2 network, the duration of power saving period varies. It may be calculated using the following formula:

$$t = \text{DRX Cycle Value} * 10 \text{ ms}$$

DRX cycle value in LTE Cat M1 or LTE Cat NB1/2 networks is any of the four values: 128, 256, 512 and 1024, thus resulting power saving intervals between 1.28 and 10.24 seconds. The DRX cycle value of the base station is assigned by the network operator.

In the pauses between listening to paging messages, the module resumes power saving, as shown in [Figure 47](#).

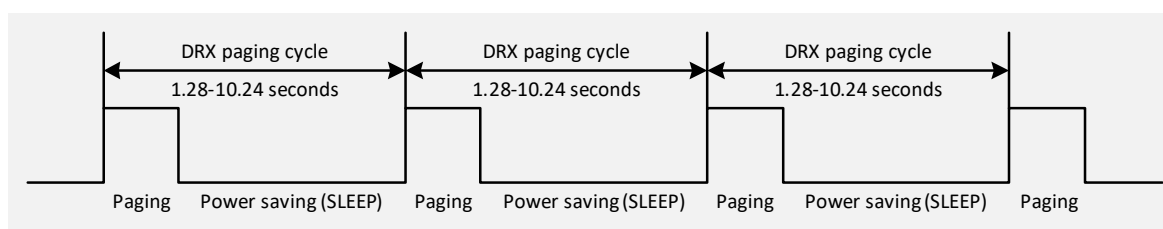


Figure 47: DRX based paging and power saving (SLEEP) in LTE Cat M1 and Cat NB1/2 networks

The varying pauses explain the different potential for power saving (SLEEP mode). The longer the pause the less power is consumed.

3.3.3.2 eDRX (Extended DRX Configuration)

TX62/TX82 and the network may negotiate the use of eDRX (extended DRX) to reduce power consumption, while being available for mobile terminating data and/or network originated procedures within a certain delay dependent on the network negotiated eDRX cycle value (see also [Section 3.3.1.2](#)). If the network supports eDRX, the module monitors the paging messages during a periodic Paging Time Window (PTW) configured for TX62/TX82.

The possible eDRX paging cycle length (PCL) ranges from 5.12s up to a maximum of 10485.76s (almost 3 hours).

The PTW length can be calculated using the following formula:

$$t_{ptw} = (PTW \text{ value} + 1) * 2560 \text{ ms}$$

[Figure 48](#) shows the eDRX timings, with the module listening to paging messages during a paging time window (PTW).

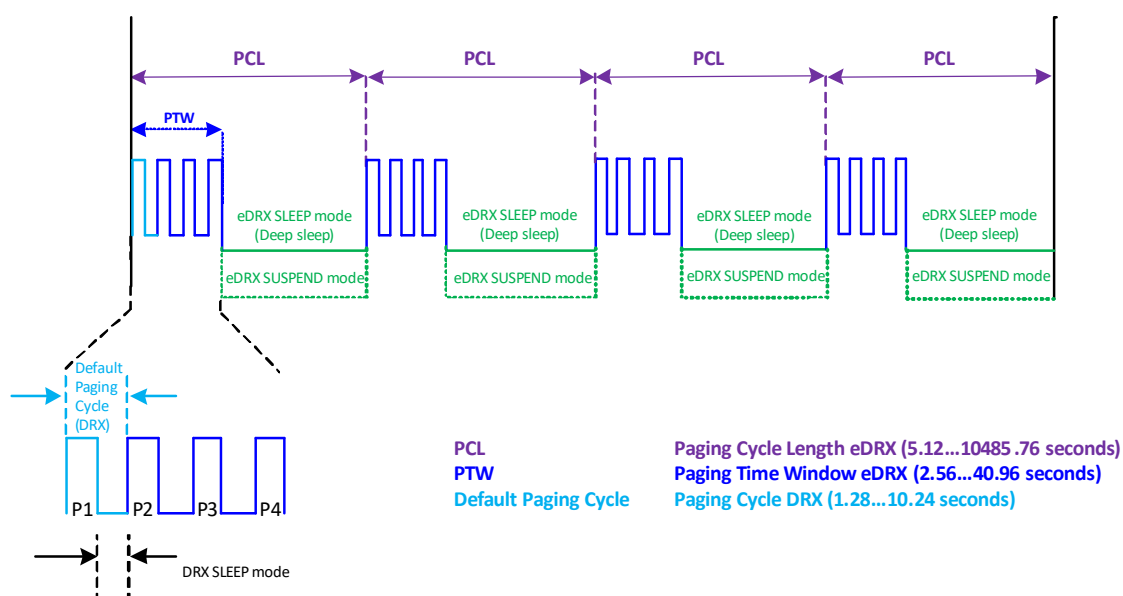


Figure 48: eDRX based paging and power saving in LTE Cat M1 and Cat NB1/2 networks

The eDRX timer can be configured with AT+CEDRXS (or AT^SEDRXS with a PTW timer request) that negotiates the eDRX settings with the network. The dynamic parameters are readable with AT+CEDRXRDP. For more information on these AT commands see [\[1\]](#).

Note 1: If SUSPEND mode is enabled in addition to SLEEP mode and eDRX settings, the module is able to reduce its current consumption even further during the eDRX paging cycle (see [Figure 48](#)). This optional so-called eDRX SUSPEND mode can be enabled with the AT^SCFG command "Radio/Suspend,<suspendmode>". However, the module will in this case not longer be able to change into the regular 3GPP PSM SUSPEND mode.

Note 2: eDRX can be configured together with 3GPP PSM (AT+CPSMS) as it will not only affect SLEEP mode (deep sleep) and eDRX SUSPEND mode, but also the 3GPP PSM SUSPEND mode - see [Section 3.3.3.3](#).

3.3.3.3 3GPP PSM Configuration

TX62/TX82 can be configured to use 3GPP PSM to reduce power consumption. PSM is similar to power off, while TX62/TX82 remains registered with the network. There is no need to re-attach or re-establish PDN connections. TX62/TX82 in PSM is not immediately reachable for mobile terminating services (see also SUSPEND mode in [Section 3.3.1.2](#))

The network accepts and negotiates the use of PSM by providing specific values for periodic TAU cycles (T3412) as well as an active timer (T3324). Upon expiry of the active timer, or if the value provided by the network is zero, TX62/TX82 may activate PSM.

Note: If TX62/TX82 negotiates to enable both PSM (requesting an active timer and possibly a periodic TAU cycle value) as well as eDRX (requesting a specific extended idle mode DRX cycle value and possibly a paging time window), it is up to the network to decide whether to:

1. Enable only PSM, i.e. not accept the request for eDRX.
2. Enable only eDRX, i.e. not accept the request for an active timer.
3. Enable both PSM (i.e. negotiate and provide requested PSM timers) and eDRX (i.e. negotiate and provide extended DRX parameters).

[Figure 49](#) shows the module's eDRX and PSM timings for the third case where module and network negotiate PSM and eDRX simultaneously (for eDRX see also [Section 3.3.3.2](#)). For the second case the module will not reach SUSPEND mode and will continue with the eDRX paging cycles. For the first case the module will not extend the DRX paging cycles, but will continue with the DRX paging cycles until the active timer (T3324) expires.

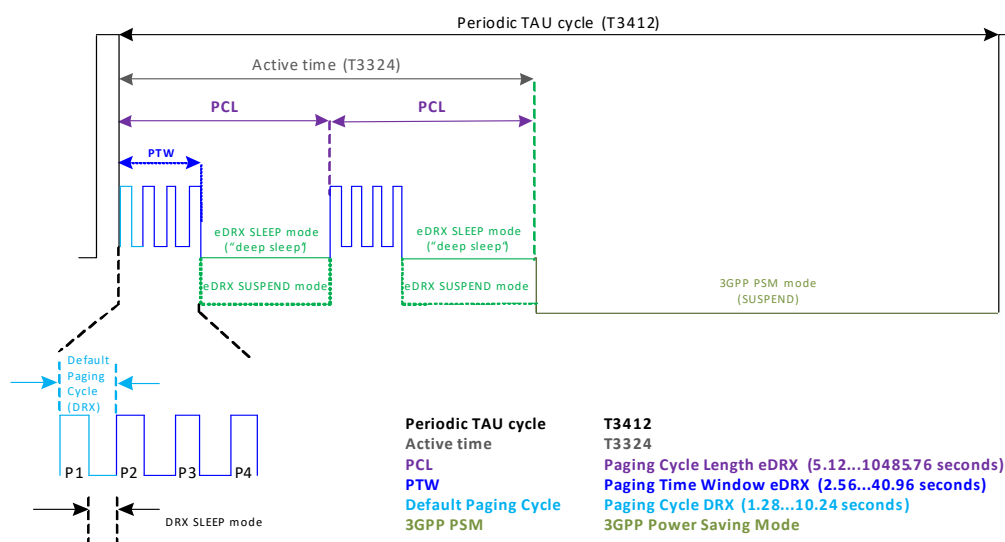


Figure 49: eDRX/PSM based paging and power saving in LTE Cat M1 or Cat NB1/2 networks

TX62/TX82 monitors paging message only while the active timer (T3324) has not expired. If the module has uplink data or signal, it will not change to PSM.

The active timer (T3324) and periodic tracking area update (TAU) timer (T3412) can be negotiated/requested with AT+CPSMS. For more information on this AT command see [\[1\]](#).

3.4 Power Supply

TX62/TX82 needs to be connected to a power supply at the SMT application interface - 2 lines BATT+, and GND. There are two separate voltage domains for BATT+:

- BATT+_{BB} with a line mainly for the baseband power supply.
- BATT+_{RF} with a line for the GSM/LTE power amplifier supply. Please note that this line does not have to be connected with TX62-W.

Please note that BATT+ in this document refers to both voltage domains and power supply lines - BATT+_{BB} and BATT+_{RF}.

The power supply of TX62/TX82 has to be a single voltage source at BATT+_{BB} and BATT+_{RF}. It should be of type PS1, according to IEC 62368-1, and must be able to provide the peak current during the uplink transmission.

Suitable low ESR capacitors should be placed as close as possible to the BATT+ pads, e.g., X7R MLCC (see also [Section 2.1.2](#)).

All key functions for supplying power to the device are handled by the power management IC. It provides the following features:

- Stabilizes the supply voltages for the baseband using low drop linear voltage regulators and a DC-DC step down switching regulator.
- Switches the module's power voltages for the power-up and -down procedures.
- SIM switch to provide SIM power supply.

3.4.1 Power Supply Ratings

[Table 23](#), [Table 24](#), [Table 25](#), [Table 26](#), and [Table 27](#) assemble various voltage supply and current consumption ratings (GSM, Cat M1 and Cat NB1/2) of the module.

Table 23: Voltage supply ratings

| | Description | Conditions | Min | Typ | Max | Unit |
|-------|--|--|------|-----|----------|--------------------------------------|
| BATT+ | TX82-W Supply voltage (LTE and GSM) | Directly measured at Module. | 3.1 | | 4.6 | V |
| | TX82-W Supply voltage (GSM deactivated) | Voltage must stay within the min/max values, including voltage drop, ripple, spikes | 2.8 | | 4.6 | V |
| | TX82-W-B Supply voltage (LTE and GSM) | | 3.1 | | 4.5 | V |
| | TX82-W-B Supply voltage (GSM deactivated) | For every BATT+ transition/reinsertion from 0V, BATT+ should be at least 2.65V to power on the module. | 2.9 | | 4.5 | V |
| | TX62-W Supply voltage | | 2.55 | | 4.8 | V |
| | TX62-W-B Supply voltage | | 2.5 | | 4.5 | V |
| | TX62-W-C Supply voltage | | 3.2 | | 4.2 | V |
| | Maximum allowed voltage drop during transmit burst | Normal condition, power control level for Pout max | | | 400 | mV |
| | Voltage ripple | Normal condition, power control level for Pout max @ f ≤ 250 kHz @ f > 250 kHz | | | 70 20 | mV _{pp} mV _{pp} |

3.4 Power Supply

Table 24: General current consumption ratings (TX62/TX82)

| Description | | Conditions | Typical rating | | | | | Unit |
|--|----------------------------------|---|----------------|----------|----------|--------|----------|------|
| | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., sum of BATT _{BB} ⁺ and BATT _{RF} ⁺ ²) | OFF state supply cur- rent | State after initially connecting V _{BATT+} and/or after a fast shutdown triggered via FST_SHDN | 14 | 14 | 32.5 | 14 | TBD. | μA |
| | | State after switching a running module off via AT^SMSO | 4.5 | 4.5 | 22.7 | 4.5 | TBD. | |
| | Airplane mode (CFUN = 4) | UART (RTS) active | 12 | 12 | 9.59 | 12 | TBD. | mA |
| | | UART (RTS) inactive | 0.55 | 0.54 | 0.49 | 0.49 | TBD. | mA |

1. With an impedance of Z_{LOAD}=50Ω at the antenna connector, Measured at 25°C at 3.8V.2. BATT_{RF}⁺ is available with TX82-W only.**Table 25:** Current consumption ratings Cat M1 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit | |
|---|---|---|------------------|---------------------------------------|----------|----------|--------|----------|------|----|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | | |
| I _{BATT+} ¹ (i.e., only BATT _{BB} ⁺) | Average LTE CAT- M1 supply current | SUSPEND ² | Power save mode | | 3.8 | 4.5 | 21.5 | 4.5 | TBD. | μA |
| | | RRC idle (SLEEP) ² | DRX=256 | | 0.90 | 0.93 | 0.87 | 0.97 | TBD. | mA |
| | | | DRX=128 | | 1.34 | 1.40 | 1.24 | 1.44 | TBD. | mA |
| | | | DRX=64 | | 2.21 | 2.28 | 1.96 | 2.30 | TBD. | mA |
| | | | 20,48s eDRX | 3,84s paging win- dow (DRX=1.28s) | 0.65 | 0.69 | 0.66 | 0.70 | TBD. | mA |
| | | | 81,92s eDRX | 2,56s paging win- dow (DRX=1.28s) | 0.44 | 0.48 | 0.48 | 0.49 | TBD. | mA |
| | | | 163,84 s eDRX | 3,84s paging win- dow (DRX=1.28s) | 0.43 | 0.46 | 0.47 | 0.47 | TBD. | mA |
| | | | 163,84 s eDRX | 10,24s paging win- dow (DRX=1.28s) | 0.46 | 0.50 | 0.50 | 0.51 | TBD. | mA |
| | | RRC idle (SUS- PEND) ² | 81,92s eDRX | 2,56s paging win- dow (DRX=1.28s) | 0.62 | 0.64 | 0.64 | 0.66 | TBD. | mA |
| | | | 163,84 s eDRX | 3,84s paging win- dow (DRX=1.28s) | 0.33 | 0.34 | 0.34 | 0.35 | TBD. | mA |
| | | | 163,84 s eDRX | 10,24s paging win- dow (DRX=1.28s) | 0.39 | 0.41 | TBD. | 0.42 | TBD. | mA |
| | | Connected DRX ³ | Short C-DRX | | 40 | 44 | 42 | 45 | TBD. | mA |
| | | | Long C-DRX | | 10 | 13 | 12 | 14 | TBD. | mA |

3.4 Power Supply

Table 25: Current consumption ratings Cat M1 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|--|-----------------------------------|--|--------------------------|----------------|----------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., only BATT ₊ _{BB}) | Average LTE CAT-M1 supply current | RRC connected Active Transmission ³ TX62-W-B, TX82-W-B, and TX62-W-C⁴ only | Band1, 23dBm | - | 226 | 242 | - | TBD. | mA |
| | | | Band2, 23dBm | - | 224 | - | - | TBD. | mA |
| | | | Band3, 23dBm | - | 230 | 198 | - | TBD. | mA |
| | | | Band4, 23dBm | - | 235 | - | - | TBD. | mA |
| | | | Band5, 23dBm | - | 228 | - | - | TBD. | mA |
| | | | Band8, 23dBm | - | 235 | 193 | - | TBD. | mA |
| | | | Band12, 23dBm | - | 208 | - | - | TBD. | mA |
| | | | Band13, 23dBm | - | 220 | - | - | TBD. | mA |
| | | | Band18, 23dBm | - | 216 | - | - | TBD. | mA |
| | | | Band19, 23dBm | - | 224 | - | - | TBD. | mA |
| | | | Band20, 23dBm | - | 225 | 187 | - | TBD. | mA |
| | | | Band25, 23dBm | - | 226 | - | - | TBD. | mA |
| | | | Band26, 23dBm | - | 226 | - | - | TBD. | mA |
| | | | Band27, 23dBm | - | 213 | - | - | TBD. | mA |
| | | | Band28, 23dBm | - | 214 | 199 | - | TBD. | mA |
| | | | Band31, 26dBm (TX62-W-C) | - | - | 235 | - | - | mA |
| | | | Band66, 23dBm | - | 231 | - | - | TBD. | mA |
| | | | Band72, 26dBm (TX62-W-C) | - | - | 229 | - | - | mA |
| | | | Band85, 23dBm | - | 201 | - | - | TBD. | mA |
| | | RRC connected Active Transmission ³ | Band1, 20dBm | 168 | - | - | 177 | - | mA |
| | | | Band2, 20dBm | 177 | - | - | 171 | - | mA |
| | | | Band3, 20dBm | 167 | - | - | 172 | - | mA |
| | | | Band4, 20dBm | 167 | - | - | 169 | - | mA |
| | | | Band5, 20dBm | 175 | - | - | 187 | - | mA |
| | | | Band8, 20dBm | 180 | - | - | 180 | - | mA |
| | | | Band12, 20dBm | 173 | - | - | 164 | - | mA |
| | | | Band13, 20dBm | 183 | - | - | 185 | - | mA |
| | | | Band18, 20dBm | 179 | - | - | 184 | - | mA |
| | | | Band19, 20dBm | 180 | - | - | 186 | - | mA |
| | | | Band20, 20dBm | 179 | - | - | 185 | - | mA |
| | | | Band25, 20dBm | 176 | - | - | 173 | - | mA |
| | | | Band26, 20dBm | 183 | - | - | 180 | - | mA |
| | | | Band27, 20dBm | 181 | - | - | 183 | - | mA |
| | | | Band28, 20dBm | 170 | - | - | 185 | - | mA |
| | | | Band66, 20dBm | 166 | - | - | 169 | - | mA |
| | | | Band85, 20dBm | 168 | - | - | 164 | - | mA |

3.4 Power Supply

Table 25: Current consumption ratings Cat M1 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|---|-----------------------------------|--|---|----------------|----------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., only BATT _{BB}) | Average LTE CAT-M1 supply current | RRC connected Active Transmission ³ | Band1, 0dBm | 103 | 131 | 112 | 105 | TBD. | mA |
| | | | Band2, 0dBm | 102 | 123 | - | 105 | TBD. | mA |
| | | | Band3, 0dBm | 103 | 120 | 110 | 105 | TBD. | mA |
| | | | Band4, 0dBm | 103 | 121 | - | 105 | TBD. | mA |
| | | | Band5, 0dBm | 102 | 129 | - | 105 | TBD. | mA |
| | | | Band8, 0dBm | 103 | 135 | 111 | 105 | TBD. | mA |
| | | | Band12, 0dBm | 102 | 126 | - | 104 | TBD. | mA |
| | | | Band13, 0dBm | 102 | 135 | - | 105 | TBD. | mA |
| | | | Band18, 0dBm | 103 | 130 | - | 105 | TBD. | mA |
| | | | Band19, 0dBm | 102 | 130 | - | 106 | TBD. | mA |
| | | | Band20, 0dBm | 103 | 130 | 110 | 106 | TBD. | mA |
| | | | Band25, 0dBm | 103 | 124 | - | 105 | TBD. | mA |
| | | | Band26, 0dBm | 103 | 130 | - | 105 | TBD. | mA |
| | | | Band27, 0dBm | 103 | 130 | - | 105 | TBD. | mA |
| | | | Band28, 0dBm | 103 | 127 | 110 | 105 | TBD. | mA |
| | | | Band31, 0dBm (TX62-W-C) | - | - | 102 | - | - | mA |
| | | | Band66, 0dBm | 103 | 121 | - | 106 | TBD. | mA |
| | | | Band72, 0dBm (TX62-W-C) | - | - | 102 | - | - | mA |
| | | | Band85, 0dBm | 103 | 117 | - | 105 | TBD. | mA |
| | | | Peak Current @ RRC connected Active Transmission ³ VBATT = 3.8V TX62-W-B, TX82-W-B, and TX62-W-C ⁴ only | Band1, 23dBm | - | 576 | 644 | - | TBD. |
| Band2, 23dBm | - | 564 | | - | - | TBD. | mA | | |
| Band3, 23dBm | - | 576 | | 520 | - | TBD. | mA | | |
| Band4, 23dBm | - | 576 | | - | - | TBD. | mA | | |
| Band5, 23dBm | - | 552 | | - | - | TBD. | mA | | |
| Band8, 23dBm | - | 588 | | 480 | - | TBD. | mA | | |
| Band12, 23dBm | - | 516 | | - | - | TBD. | mA | | |
| Band13, 23dBm | - | 552 | | - | - | TBD. | mA | | |
| Band18, 23dBm | - | 528 | | - | - | TBD. | mA | | |
| Band19, 23dBm | - | 552 | | - | - | TBD. | mA | | |
| Band20, 23dBm | - | 552 | | 488 | - | TBD. | mA | | |
| Band25, 23dBm | - | 564 | | - | - | TBD. | mA | | |
| Band26, 23dBm | - | 552 | | - | - | TBD. | mA | | |
| Band27, 23dBm | - | 516 | | - | - | TBD. | mA | | |
| Band28, 23dBm | - | 516 | | 482 | - | TBD. | mA | | |
| Band31, 26dBm (TX62-W-C) | - | - | | 596 | - | - | mA | | |
| Band66, 23dBm | - | 564 | | - | - | TBD. | mA | | |
| Band72, 26dBm (TX62-W-C) | - | - | | 600 | - | - | mA | | |
| Band85, 23dBm | - | 504 | | - | - | TBD. | mA | | |

Table 25: Current consumption ratings Cat M1 (TX62/TX82)

| Description | Conditions | | Typical rating | | | | | Unit |
|---|--|--------------------------|----------------|----------|----------|--------|----------|------|
| | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., only BATT ₊ _{BB}) | Peak Current @ RRC connected Active Trans- mission ³ VBATT = 3.8V | Band1, 20dBm | 412 | - | - | 408 | - | mA |
| | | Band2, 20dBm | 396 | - | - | 388 | - | mA |
| | | Band3, 20dBm | 388 | - | - | 376 | - | mA |
| | | Band4, 20dBm | 376 | - | - | 396 | - | mA |
| | | Band5, 20dBm | 396 | - | - | 456 | - | mA |
| | | Band8, 20dBm | 452 | - | - | 428 | - | mA |
| | | Band12, 20dBm | 388 | - | - | 372 | - | mA |
| | | Band13, 20dBm | 420 | - | - | 452 | - | mA |
| | | Band18, 20dBm | 432 | - | - | 452 | - | mA |
| | | Band19, 20dBm | 440 | - | - | 456 | - | mA |
| | | Band20, 20dBm | 448 | - | - | 452 | - | mA |
| | | Band25, 20dBm | 388 | - | - | 400 | - | mA |
| | | Band26, 20dBm | 420 | - | - | 436 | - | mA |
| | | Band27, 20dBm | 440 | - | - | 444 | - | mA |
| | | Band28, 20dBm | 404 | - | - | 404 | - | mA |
| | | Band66, 20dBm | 368 | - | - | 384 | - | mA |
| | | Band85, 20dBm | 384 | - | - | 372 | - | mA |
| | Peak Current @ RRC connected Active Trans- mission ³ VBATT= 2.5V (TX62-W-B) VBATT= 3.2V (TX62-W-C) VBATT= TBD.V (TX82-W- B) TX62-W-B, TX82-W-B, and TX62-W-C⁴ only | Band1, 23dBm | - | 624 | 672 | - | TBD. | mA |
| | | Band2, 23dBm | - | 648 | - | - | TBD. | mA |
| | | Band3, 23dBm | - | 636 | 592 | - | TBD. | mA |
| | | Band4, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band5, 23dBm | - | 660 | - | - | TBD. | mA |
| | | Band8, 23dBm | - | 612 | 528 | - | TBD. | mA |
| | | Band12, 23dBm | - | 564 | - | - | TBD. | mA |
| | | Band13, 23dBm | - | 648 | - | - | TBD. | mA |
| | | Band18, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band19, 23dBm | - | 612 | - | - | TBD. | mA |
| | | Band20, 23dBm | - | 648 | 552 | - | TBD. | mA |
| | | Band25, 23dBm | - | 612 | - | - | TBD. | mA |
| | | Band26, 23dBm | - | 612 | - | - | TBD. | mA |
| | | Band27, 23dBm | - | 588 | - | - | TBD. | mA |
| | | Band28, 23dBm | - | 624 | 544 | - | TBD. | mA |
| | | Band31, 26dBm (TX62-W-C) | - | - | 608 | - | - | mA |
| | | Band66, 23dBm | - | 648 | - | - | TBD. | mA |
| | | Band72, 26dBm (TX62-W-C) | - | - | 616 | - | - | mA |
| | | Band85, 23dBm | - | 588 | - | - | TBD. | mA |

3.4 Power Supply

Table 25: Current consumption ratings Cat M1 (TX62/TX82)

| Description | | Conditions | Typical rating | | | | | Unit |
|---|--|---|----------------|----------|----------|--------|----------|------|
| | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., only $BATT+_{BB}$) | Peak Current @ RRC connected Active Transmission ³ VBATT = 2.55V (TX62-W) VBATT = 2.8V (TX82-W) | Band1, 20dBm | 572 | - | - | 528 | - | mA |
| | | Band2, 20dBm | 556 | - | - | 516 | - | mA |
| | | Band3, 20dBm | 564 | - | - | 492 | - | mA |
| | | Band4, 20dBm | 528 | - | - | 500 | - | mA |
| | | Band5, 20dBm | 576 | - | - | 608 | - | mA |
| | | Band8, 20dBm | 656 | - | - | 556 | - | mA |
| | | Band12, 20dBm | 548 | - | - | 476 | - | mA |
| | | Band13, 20dBm | 604 | - | - | 592 | - | mA |
| | | Band18, 20dBm | 624 | - | - | 596 | - | mA |
| | | Band19, 20dBm | 632 | - | - | 588 | - | mA |
| | | Band20, 20dBm | 636 | - | - | 580 | - | mA |
| | | Band25, 20dBm | 556 | - | - | 516 | - | mA |
| | | Band26, 20dBm | 604 | - | - | 560 | - | mA |
| | | Band27, 20dBm | 640 | - | - | 596 | - | mA |
| | | Band28, 20dBm | 588 | - | - | 508 | - | mA |
| | | Band66, 20dBm | 520 | - | - | 496 | - | mA |
| | | Band85, 20dBm | 556 | - | - | 496 | - | mA |
| | Average idle supply current (GNSS on) | CAT-M1 active (UART active) @ DRX=128 GNSS NMEA output off | 65 | 66 | 65 | 64 | TBD. | mA |
| | | GPRS active (UART active) @ DRX=128 GNSS NMEA output on | 64 | 66 | 65 | 64 | TBD. | mA |

1. With an impedance of $Z_{LOAD}=50\Omega$ at the antenna connector, Measured at 25°C at 3.8V.

2. Measurements start 6 minutes after switching ON the module,

Averaging times:

SUSPEND mode: 3 minutes (T3324 = 3s, T3412 = 14400s)

SLEEP mode: 10 minutes, (PSM disabled, eDRX disabled)

Idle eDRX mode: 30 minutes, (PSM disabled, eDRX enabled)

Connected DRX mode: 10 minutes,

RRC connected modes: 3 minutes,

Communication tester settings: no neighbor cells, no cell re-selection etc, RMC (reference measurement channel), SUSPEND/

SLEEP (with PSM/eDRX) is enabled via AT command

3. Communication tester settings:

RMC mode, Half Duplex,

Cat M1 Channel Bandwidth: 10MHz

Modulation: QPSK.

RB setting: 1 UL RBs, 4 DL RBs

4. TX62-W-C supports the following LTE Cat M1 bands only: Band 1, 3, 8, 20, 28, 31, 72

3.4 Power Supply

Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit | |
|---|---|--|--------------------------|---------------------------------------|----------|----------|--------|----------|------|----|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | | |
| I _{BATT+} ¹ (i.e., only BATT ₊ _{BB}) | Average LTE NB1/2 supply current | SUSPEND ² | Power save mode | | 3.8 | 4.5 | 21.5 | 4.5 | TBD. | µA |
| | | RRC idle (SLEEP) ² | DRX=1024 | | 0.77 | 0.79 | 0.79 | 0.88 | TBD. | mA |
| | | | DRX=512 | | 1.08 | 1.09 | 1.17 | 1.17 | TBD. | mA |
| | | | DRX=256 | | 0.85 | 0.86 | 0.85 | 0.94 | TBD. | mA |
| | | | DRX=128 | | 1.23 | 1.26 | 1.20 | 1.35 | TBD. | mA |
| | | | 20,48s eDRX | 2,56s paging win- dow (DRX=1.28s) | 1.15 | 1.14 | 1.20 | 1.19 | TBD. | mA |
| | | | 81,92s eDRX | 2,56s paging win- dow (DRX=1.28s) | 0.49 | 0.49 | 0.58 | 0.55 | TBD. | mA |
| | | | 163,84 s eDRX | 2,56s paging win- dow (DRX=1.28s) | 0.45 | 0.44 | 0.53 | 0.50 | TBD. | mA |
| | | | 163,84 s eDRX | 10,24s paging win- dow (DRX=1.28s) | 0.51 | 0.50 | 0.56 | 0.59 | TBD. | mA |
| | | RRC idle (SUS- PEND) ² | 81,92s eDRX | 2,56s paging win- dow (DRX=1.28s) | 0.62 | 0.66 | 0.67 | 0.66 | TBD. | mA |
| | | | 163,84 s eDRX | 2,56s paging win- dow (DRX=1.28s) | 0.31 | 0.33 | 0.34 | 0.34 | TBD. | mA |
| | | | 163,84 s eDRX | 10,24s paging win- dow (DRX=1.28s) | 0.38 | 0.40 | 0.41 | 0.40 | TBD. | mA |
| | | RRC con- nected Active Transmis- sion DL RMC ³ TX62-W-B, TX82-W-B, and TX62- W-C ⁴ only | Band1, 23dBm | | - | 77 | 79 | - | TBD. | mA |
| | | | Band2, 23dBm | | - | 78 | - | - | TBD. | mA |
| | | | Band3, 23dBm | | - | 77 | 75 | - | TBD. | mA |
| | | | Band4, 23dBm | | - | 76 | - | - | TBD. | mA |
| | | | Band5, 23dBm | | - | 76 | - | - | TBD. | mA |
| | | | Band8, 23dBm | | - | 79 | 68 | - | TBD. | mA |
| | | | Band12, 23dBm | | - | 74 | - | - | TBD. | mA |
| | | | Band13, 23dBm | | - | 76 | - | - | TBD. | mA |
| | | | Band18, 23dBm | | - | 75 | - | - | TBD. | mA |
| | | | Band19, 23dBm | | - | 76 | - | - | TBD. | mA |
| | | | Band20, 23dBm | | - | 77 | 70 | - | TBD. | mA |
| | | | Band25, 23dBm | | - | 77 | - | - | TBD. | mA |
| | | | Band26, 23dBm | | - | 75 | - | - | TBD. | mA |
| | | | Band28, 23dBm | | - | 74 | 74 | - | TBD. | mA |
| | | | Band31, 23dBm (TX62-W-C) | | - | - | 68 | - | - | mA |
| | | | Band66, 23dBm | | - | 78 | - | - | TBD. | mA |
| | | | Band71, 23dBm (TX62-W-B) | | - | 73 | - | - | - | mA |
| | | | Band72, 23dBm (TX62-W-C) | | - | - | 68 | - | - | mA |
| | | | Band85, 23dBm | | - | 74 | - | - | TBD. | mA |

Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|---|----------------------------------|---|-------------------------|----------------|----------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., only $BATT+_{BB}$) | Average LTE NB1/2 supply current | RRC connected Active Transmission DL RMC ³ | Band1, 20dBm | 63 | - | - | 65 | - | mA |
| | | | Band2, 20dBm | 62 | - | - | 64 | - | mA |
| | | | Band3, 20dBm | 62 | - | - | 63 | - | mA |
| | | | Band4, 20dBm | 61 | - | - | 63 | - | mA |
| | | | Band5, 20dBm | 65 | - | - | 70 | - | mA |
| | | | Band8, 20dBm | 66 | - | - | 68 | - | mA |
| | | | Band12, 20dBm | 63 | - | - | 64 | - | mA |
| | | | Band13, 20dBm | 66 | - | - | 69 | - | mA |
| | | | Band18, 20dBm | 66 | - | - | 69 | - | mA |
| | | | Band19, 20dBm | 66 | - | - | 69 | - | mA |
| | | | Band20, 20dBm | 66 | - | - | 70 | - | mA |
| | | | Band25, 20dBm | 63 | - | - | 65 | - | mA |
| | | | Band26, 20dBm | 66 | - | - | 69 | - | mA |
| | | | Band28, 20dBm | 64 | - | - | 68 | - | mA |
| | | | Band66, 20dBm | 62 | - | - | 63 | - | mA |
| | | | Band71, 20dBm | 61 | - | - | 62 | - | mA |
| | | | Band85, 20dBm | 63 | - | - | 64 | - | mA |
| | | | Band1, 0dBm | 44 | 57 | 50 | 45 | TBD. | mA |
| | | | Band2, 0dBm | 43 | 55 | - | 45 | TBD. | mA |
| | | | Band3, 0dBm | 44 | 54 | 50 | 45 | TBD. | mA |
| | | | Band4, 0dBm | 44 | 54 | - | 44 | TBD. | mA |
| | | | Band5, 0dBm | 44 | 57 | - | 45 | TBD. | mA |
| | | | Band8, 0dBm | 44 | 58 | 50 | 45 | TBD. | mA |
| | | | Band12, 0dBm | 44 | 56 | - | 44 | TBD. | mA |
| | | | Band13, 0dBm | 44 | 58 | - | 45 | TBD. | mA |
| | | | Band18, 0dBm | 44 | 57 | - | 45 | TBD. | mA |
| | | | Band19, 0dBm | 44 | 57 | - | 45 | TBD. | mA |
| | | | Band20, 0dBm | 44 | 56 | 50 | 45 | TBD. | mA |
| | | | Band25, 0dBm | 44 | 55 | - | 44 | TBD. | mA |
| | | | Band26, 0dBm | 44 | 57 | - | 45 | TBD. | mA |
| | | | Band28, 0dBm | 44 | 56 | 50 | 45 | TBD. | mA |
| | | | Band31, 0dBm (TX62-W-C) | - | - | 50 | - | - | mA |
| | | | Band66, 0dBm | 44 | 54 | - | 45 | TBD. | mA |
| | | | Band71, 0dBm (TX62-W-B) | 43 | 55 | - | 43 | - | mA |
| | | | Band72, 0dBm (TX62-W-C) | - | - | 49 | - | - | mA |
| | | | Band85, 0dBm | 44 | 56 | - | 44 | TBD. | mA |

3.4 Power Supply

Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|---|----------------------------------|--|--------------------------|----------------|----------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., only $BATT+_{BB}$) | Average LTE NB1/2 supply current | RRC connected Active Transmission UL RMC, single tone mode (1subcarrier), 15KHz spacing ³ TX62-W-B, TX82-W-B, and TX62-W-C⁴ only | Band1, 23dBm | - | 232 | 259 | - | TBD. | mA |
| | | | Band2, 23dBm | - | 237 | - | - | TBD. | mA |
| | | | Band3, 23dBm | - | 228 | 213 | - | TBD. | mA |
| | | | Band4, 23dBm | - | 221 | - | - | TBD. | mA |
| | | | Band5, 23dBm | - | 219 | - | - | TBD. | mA |
| | | | Band8, 23dBm | - | 240 | 187 | - | TBD. | mA |
| | | | Band12, 23dBm | - | 207 | - | - | TBD. | mA |
| | | | Band13, 23dBm | - | 218 | - | - | TBD. | mA |
| | | | Band18, 23dBm | - | 217 | - | - | TBD. | mA |
| | | | Band19, 23dBm | - | 223 | - | - | TBD. | mA |
| | | | Band20, 23dBm | - | 224 | 187 | - | TBD. | mA |
| | | | Band25, 23dBm | - | 235 | - | - | TBD. | mA |
| | | | Band26, 23dBm | - | 219 | - | - | TBD. | mA |
| | | | Band28, 23dBm | - | 207 | 207 | - | TBD. | mA |
| | | | Band31, 23dBm (TX62-W-C) | - | - | 177 | - | - | mA |
| | | | Band66, 23dBm | - | 258 | - | - | TBD. | mA |
| | | | Band71, 23dBm (TX62-W-B) | - | 203 | - | - | - | mA |
| | | | Band72, 23dBm (TX62-W-C) | - | - | 178 | - | - | mA |
| | | | Band85, 23dBm | - | 208 | - | - | TBD. | mA |
| | | RRC connected Active Transmission UL RMC, single tone mode (1subcarrier), 15KHz spacing ³ | Band1, 20dBm | 178 | - | - | 186 | - | mA |
| | | | Band2, 20dBm | 172 | - | - | 180 | - | mA |
| | | | Band3, 20dBm | 166 | - | - | 170 | - | mA |
| | | | Band4, 20dBm | 164 | - | - | 168 | - | mA |
| | | | Band5, 20dBm | 183 | - | - | 203 | - | mA |
| | | | Band8, 20dBm | 191 | - | - | 196 | - | mA |
| | | | Band12, 20dBm | 168 | - | - | 171 | - | mA |
| | | | Band13, 20dBm | 191 | - | - | 202 | - | mA |
| | | | Band18, 20dBm | 186 | - | - | 200 | - | mA |
| | | | Band19, 20dBm | 187 | - | - | 203 | - | mA |
| | | | Band20, 20dBm | 189 | - | - | 203 | - | mA |
| | | | Band25, 20dBm | 180 | - | - | 182 | - | mA |
| | | | Band26, 20dBm | 192 | - | - | 200 | - | mA |
| | | | Band28, 20dBm | 175 | - | - | 190 | - | mA |
| | | | Band66, 20dBm | 167 | - | - | 166 | - | mA |
| | | | Band71, 20dBm | 164 | - | - | 169 | - | mA |
| | | | Band85, 20dBm | 173 | - | - | 169 | - | mA |

Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|---|----------------------------------|--|-------------------------|----------------|----------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., only $BATT+_{BB}$) | Average LTE NB1/2 supply current | RRC connected Active Transmission UL RMC, single tone mode (1subcarrier), 15KHz spacing ³ | Band1, 0dBm | 61 | 111 | 80 | 62 | TBD. | mA |
| | | | Band2, 0dBm | 61 | 98 | - | 61 | TBD. | mA |
| | | | Band3, 0dBm | 61 | 93 | 77 | 61 | TBD. | mA |
| | | | Band4, 0dBm | 61 | 92 | - | 61 | TBD. | mA |
| | | | Band5, 0dBm | 60 | 107 | - | 60 | TBD. | mA |
| | | | Band8, 0dBm | 60 | 116 | 78 | 61 | TBD. | mA |
| | | | Band12, 0dBm | 58 | 102 | - | 59 | TBD. | mA |
| | | | Band13, 0dBm | 60 | 116 | - | 60 | TBD. | mA |
| | | | Band18, 0dBm | 60 | 107 | - | 60 | TBD. | mA |
| | | | Band19, 0dBm | 60 | 107 | - | 61 | TBD. | mA |
| | | | Band20, 0dBm | 60 | 107 | 77 | 61 | TBD. | mA |
| | | | Band25, 0dBm | 61 | 98 | - | 61 | TBD. | mA |
| | | | Band26, 0dBm | 60 | 107 | - | 60 | TBD. | mA |
| | | | Band28, 0dBm | 60 | 103 | 77 | 60 | TBD. | mA |
| | | | Band31, 0dBm (TX62-W-C) | - | - | 63 | - | TBD. | mA |
| | | | Band66, 0dBm | 61 | 92 | - | 62 | TBD. | mA |
| | | | Band71, 0dBm | 58 | 101 | - | 58 | - | mA |
| | | | Band72, 0dBm (TX62-W-C) | - | - | 63 | - | TBD. | mA |
| | | | Band85, 0dBm | 58 | 102 | - | 59 | TBD. | mA |

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Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|--|----------------------------------|--|--------------------------|----------------|----------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., only BATT ₊ _{BB}) | Average LTE NB1/2 supply current | RRC connected Active Transmission UL RMC, multi-tone mode (12 subcarrier), 15kHz spacing ³ TX62-W-B and TX62-W-C⁴ only | Band1, 23dBm | - | 71 | 73 | - | TBD. | mA |
| | | | Band2, 23dBm | - | 72 | - | - | TBD. | mA |
| | | | Band3, 23dBm | - | 72 | 69 | - | TBD. | mA |
| | | | Band4, 23dBm | - | 71 | - | - | TBD. | mA |
| | | | Band5, 23dBm | - | 70 | - | - | TBD. | mA |
| | | | Band8, 23dBm | - | 73 | 66 | - | TBD. | mA |
| | | | Band12, 23dBm | - | 69 | - | - | TBD. | mA |
| | | | Band13, 23dBm | - | 71 | - | - | TBD. | mA |
| | | | Band18, 23dBm | - | 70 | - | - | TBD. | mA |
| | | | Band19, 23dBm | - | 71 | - | - | TBD. | mA |
| | | | Band20, 23dBm | - | 72 | 66 | - | TBD. | mA |
| | | | Band25, 23dBm | - | 72 | - | - | TBD. | mA |
| | | | Band26, 23dBm | - | 70 | - | - | TBD. | mA |
| | | | Band28, 23dBm | - | 70 | 67 | - | TBD. | mA |
| | | | Band31, 23dBm (TX62-W-C) | - | - | 68 | - | TBD. | mA |
| | | | Band66, 23dBm | - | 72 | - | - | TBD. | mA |
| | | | Band71, 23dBm (TX62-W-B) | - | 68 | - | - | - | mA |
| | | | Band72, 23dbm (TX62-W-C) | - | - | 68 | - | TBD. | mA |
| | | | Band85, 23dBm | - | 70 | - | - | TBD. | mA |
| | | RRC connected Active Transmission UL RMC, multi-tone mode (12 subcarrier), 15kHz spacing ³ | Band1, 20dBm | 57 | - | - | 59 | - | mA |
| | | | Band2, 20dBm | 56 | - | - | 58 | - | mA |
| | | | Band3, 20dBm | 57 | - | - | 58 | - | mA |
| | | | Band4, 20dBm | 56 | - | - | 57 | - | mA |
| | | | Band5, 20dBm | 58 | - | - | 62 | - | mA |
| | | | Band8, 20dBm | 60 | - | - | 61 | - | mA |
| | | | Band12, 20dBm | 56 | - | - | 58 | - | mA |
| | | | Band13, 20dBm | 58 | - | - | 62 | - | mA |
| | | | Band18, 20dBm | 59 | - | - | 61 | - | mA |
| | | | Band19, 20dBm | 59 | - | - | 62 | - | mA |
| | | | Band20, 20dBm | 59 | - | - | 62 | - | mA |
| | | | Band25, 20dBm | 56 | - | - | 59 | - | mA |
| | | | Band26, 20dBm | 58 | - | - | 62 | - | mA |
| | | | Band28, 20dBm | 58 | - | - | 61 | - | mA |
| | | | Band66, 20dBm | 55 | - | - | 59 | - | mA |
| | | | Band71, 20dBm | 54 | - | - | 57 | - | mA |
| | | | Band85, 20dBm | 58 | - | - | 59 | - | mA |

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Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | | Typical rating | | | | | Unit |
|--|---|---|-------------------------|--|--------------|----------|--------|----------|------|
| | | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., only BATT _{BB}) | Average LTE NB1/2 supply current | RRC con- nected Active Transmis- sion UL RMC, multi- tone mode (12 subcar- rier), 15kHz spacing ³ | Band1, 0dBm | 45 | 57 | 51 | 46 | TBD. | mA |
| | | | Band2, 0dBm | 45 | 55 | - | 46 | TBD. | mA |
| | | | Band3, 0dBm | 46 | 55 | 52 | 46 | TBD. | mA |
| | | | Band4, 0dBm | 45 | 55 | - | 46 | TBD. | mA |
| | | | Band5, 0dBm | 46 | 57 | - | 46 | TBD. | mA |
| | | | Band8, 0dBm | 46 | 58 | 52 | 46 | TBD. | mA |
| | | | Band12, 0dBm | 45 | 56 | - | 46 | TBD. | mA |
| | | | Band13, 0dBm | 46 | 58 | - | 46 | TBD. | mA |
| | | | Band18, 0dBm | 45 | 57 | - | 46 | TBD. | mA |
| | | | Band19, 0dBm | 45 | 57 | - | 46 | TBD. | mA |
| | | | Band20, 0dBm | 46 | 57 | 52 | 47 | TBD. | mA |
| | | | Band25, 0dBm | 45 | 56 | - | 46 | TBD. | mA |
| | | | Band26, 0dBm | 46 | 57 | - | 46 | TBD. | mA |
| | | | Band28, 0dBm | 46 | 57 | 52 | 47 | TBD. | mA |
| | | | Band31, 0dBm (TX62-W-C) | - | - | 51 | - | - | mA |
| | | | Band66, 0dBm | 46 | 55 | - | 48 | TBD. | mA |
| | | | Band71, 0dBm | 44 | 55 | - | 45 | - | mA |
| | | | Band72, 0dBm (TX62-W-C) | - | - | 51 | - | - | mA |
| | | | Band85, 0dBm | 46 | 57 | - | 47 | TBD. | mA |
| | | | | Peak Current @ RRC connected Active Transmission UL RMC, single tone mode (1subcarrier), 15KHz spacing ³ VBATT=3.8V TX62-W-B, TX82-W-B, and TX62-W-C⁴ only | Band1, 23dBm | - | 576 | 696 | - |
| Band2, 23dBm | - | 588 | | | - | - | TBD. | mA | |
| Band3, 23dBm | - | 588 | | | 544 | - | TBD. | mA | |
| Band4, 23dBm | - | 588 | | | - | - | TBD. | mA | |
| Band5, 23dBm | - | 588 | | | - | - | TBD. | mA | |
| Band8, 23dBm | - | 600 | | | 432 | - | TBD. | mA | |
| Band12, 23dBm | - | 540 | | | - | - | TBD. | mA | |
| Band13, 23dBm | - | 576 | | | - | - | TBD. | mA | |
| Band18, 23dBm | - | 576 | | | - | - | TBD. | mA | |
| Band19, 23dBm | - | 588 | | | - | - | TBD. | mA | |
| Band20, 23dBm | - | 588 | | | 496 | - | TBD. | mA | |
| Band25, 23dBm | - | 576 | | | - | - | TBD. | mA | |
| Band26, 23dBm | - | 588 | | | - | - | TBD. | mA | |
| Band28, 23dBm | - | 552 | | | 496 | - | TBD. | mA | |
| Band31, 23dBm (TX62-W-C) | - | - | | | 456 | - | - | mA | |
| Band66, 23dBm | - | 588 | | | - | - | TBD. | mA | |
| Band71, 23dBm (TX62-W-B) | - | 540 | | | - | - | - | mA | |
| Band72, 23dBm (TX62-W-C) | - | - | | | 464 | - | - | mA | |
| Band85, 23dBm | - | 552 | | | - | - | TBD. | mA | |

Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | Typical rating | | | | | Unit |
|---|--|--------------------------|----------------|----------|----------|--------|----------|------|
| | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., only $BATT+_{BB}$) | Peak Current @ RRC connected Active Transmission UL RMC, single tone mode (1subcarrier), 15KHz spacing ³ VBATT=3.8V | Band1, 20dBm | 388 | - | - | 380 | - | mA |
| | | Band2, 20dBm | 396 | - | - | 372 | - | mA |
| | | Band3, 20dBm | 380 | - | - | 364 | - | mA |
| | | Band4, 20dBm | 352 | - | - | 368 | - | mA |
| | | Band5, 20dBm | 416 | - | - | 448 | - | mA |
| | | Band8, 20dBm | 436 | - | - | 432 | - | mA |
| | | Band12, 20dBm | 388 | - | - | 376 | - | mA |
| | | Band13, 20dBm | 444 | - | - | 436 | - | mA |
| | | Band18, 20dBm | 420 | - | - | 436 | - | mA |
| | | Band19, 20dBm | 420 | - | - | 440 | - | mA |
| | | Band20, 20dBm | 428 | - | - | 440 | - | mA |
| | | Band25, 20dBm | 396 | - | - | 376 | - | mA |
| | | Band26, 20dBm | 436 | - | - | 428 | - | mA |
| | | Band28, 20dBm | 396 | - | - | 408 | - | mA |
| | | Band66, 20dBm | 376 | - | - | 368 | - | mA |
| | | Band71, 20dBm | 372 | - | - | 368 | - | mA |
| | | Band85, 20dBm | 388 | - | - | 368 | - | mA |
| | Peak Current @ RRC connected Active Transmission UL RMC, single tone mode (1subcarrier), 15KHz spacing ³ VBATT=2.5V (TX62-W-B) VBATT=3.2V (TX62-W-C) VBATT=TBD.V (TX82-W-B) TX62-W-B, TX82-W-B, and TX62-W-C⁴ only | Band1, 23dBm | - | 624 | 696 | - | TBD. | mA |
| | | Band2, 23dBm | - | 612 | - | - | TBD. | mA |
| | | Band3, 23dBm | - | 612 | 560 | - | TBD. | mA |
| | | Band4, 23dBm | - | 612 | - | - | TBD. | mA |
| | | Band5, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band8, 23dBm | - | 648 | 464 | - | TBD. | mA |
| | | Band12, 23dBm | - | 576 | - | - | TBD. | mA |
| | | Band13, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band18, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band19, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band20, 23dBm | - | 648 | 512 | - | TBD. | mA |
| | | Band25, 23dBm | - | 612 | - | - | TBD. | mA |
| | | Band26, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band28, 23dBm | - | 588 | 536 | - | TBD. | mA |
| | | Band31, 23dBm (TX62-W-C) | - | - | 464 | - | - | mA |
| | | Band66, 23dBm | - | 624 | - | - | TBD. | mA |
| | | Band71, 23dBm (TX62-W-B) | - | 576 | - | - | - | mA |
| | | Band72, 23dBm (TX62-W-C) | - | - | 480 | - | - | mA |
| | | Band85, 23dBm | - | 588 | - | - | TBD. | mA |

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Table 26: Current consumption ratings Cat NB1/2 (TX62/TX82)

| Description | | Conditions | Typical rating | | | | | Unit |
|--|--|--|----------------|----------|----------|--------|----------|------|
| | | | TX62-W | TX62-W-B | TX62-W-C | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., only BATT ₊ _{BB}) | Peak Current @ RRC connected Active Transmission UL RMC, single tone mode (1 subcarrier), 15KHz spacing ³ VBATT = 2.55V (TX62-W) VBATT = 2.8V (TX82-W) | Band1, 20dBm | 560 | - | - | 512 | - | mA |
| | | Band2, 20dBm | 564 | - | - | 496 | - | mA |
| | | Band3, 20dBm | 544 | - | - | 480 | - | mA |
| | | Band4, 20dBm | 504 | - | - | 484 | - | mA |
| | | Band5, 20dBm | 608 | - | - | 604 | - | mA |
| | | Band8, 20dBm | 620 | - | - | 572 | - | mA |
| | | Band12, 20dBm | 548 | - | - | 488 | - | mA |
| | | Band13, 20dBm | 628 | - | - | 588 | - | mA |
| | | Band18, 20dBm | 600 | - | - | 584 | - | mA |
| | | Band19, 20dBm | 600 | - | - | 588 | - | mA |
| | | Band20, 20dBm | 612 | - | - | 584 | - | mA |
| | | Band25, 20dBm | 572 | - | - | 504 | - | mA |
| | | Band26, 20dBm | 628 | - | - | 576 | - | mA |
| | | Band28, 20dBm | 560 | - | - | 548 | - | mA |
| | | Band66, 20dBm | 536 | - | - | 488 | - | mA |
| | | Band71, 20dBm | 532 | - | - | 488 | - | mA |
| | | Band85, 20dBm | 560 | - | - | 488 | - | mA |
| | Average idle supply current (GNSS on) | LTE NB1/2 active (UART active) @ DRX=128 GNSS NMEA output off | 57 | 65 | 65 | 64 | TBD. | mA |
| | | LTE NB1/2 active (UART active) @ DRX=128 GNSS NMEA output on | 57 | 66 | 66 | 64 | TBD. | mA |

1. With an impedance of Z_{LOAD}=50Ω at the antenna connector, Measured at 25°C at 3.8V.

2. Measurements start 6 minutes after switching ON the module,

Averaging times:

SUSPEND mode: 3 minutes (T3324 = 3s, T3412 = 14400s)

SLEEP mode: 10 minutes, (PSM disabled, eDRX disabled)

Idle eDRX mode: 30 minutes, (PSM disabled, eDRX enabled)

Connected DRX mode: 10 minutes,

RRC connected modes: 3 minutes,

Communication tester settings: no neighbor cells, no cell re-selection etc, RMC (reference measurement channel), SUSPEND/

SLEEP (with PSM/eDRX) is enabled via AT command

3. Communication tester settings:

Cat NB1/2 Channel Bandwidth: 10MHz

Modulation: BPSK for 1 UL subcarrier mode, QPSK for multi-subcarrier mode

4. TX62-W-C supports the following LTE Cat NB1/2 bands only: Band 1, 3, 8, 20, 28, 31, 72. Note also that with TX62-W-C support for LTE Cat NB1/2 is by default deactivated, but may be activated on demand.

Table 27: Current consumption ratings General and GSM (TX82-W and TX82-W-B)

| Description | | Conditions | | Typical rating | | Unit |
|--|---|--|----------------------------|----------------|----------|------|
| | | | | TX82-W | TX82-W-B | |
| I _{BATT+} ¹ (i.e., sum of BATT _{BB} and BATT _{RF}) | Average GSM supply current (GNSS off) | SLEEP ² @DRX=9 (no communication via UART) | | 0.78 | TBD. | mA |
| | | SLEEP ² @DRX=5 (no communication via UART) | | 0.95 | TBD. | mA |
| | | SLEEP ² @DRX=2 (no communication via UART) | | 1.58 | TBD. | mA |
| | | SLEEP ³ @DRX=2 (no communication via UART) | | 13 | TBD. | mA |
| | | GPRS Data transfer GSM850; PCL=5, 1Tx/4Rx | ROPR=8 (max. reduction) | 230 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 232 | TBD. | mA |
| | | GPRS Data transfer GSM850; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 323 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 407 | TBD. | mA |
| | | EDGE Data transfer GSM850; PCL=5; 1Tx/4Rx | ROPR=8 (max. reduction) | 155 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 156 | TBD. | mA |
| | | EDGE Data transfer GSM850; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 231 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 259 | TBD. | mA |
| | | GPRS Data transfer GSM900; PCL=5, 1Tx/4Rx | ROPR=8 (max. reduction) | 260 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 259 | TBD. | mA |
| | | GPRS Data transfer GSM900; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 328 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 464 | TBD. | mA |
| | | EDGE Data transfer GSM900; PCL=5; 1Tx/4Rx | ROPR=8 (max. reduction) | 153 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 152 | TBD. | mA |

Table 27: Current consumption ratings General and GSM (TX82-W and TX82-W-B)

| Description | | Conditions | | Typical rating | | Unit |
|--|---|--|-------------------------|----------------|----------|------|
| | | | | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., sum of $BATT+_{BB}$ and $BATT+_{RF}$) | Average GSM supply current (GNSS off) | EDGE Data transfer GSM900; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 229 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 256 | TBD. | mA |
| | | GPRS Data transfer GSM1800; PCL=5; 1Tx/4RX | ROPR=8 (max. reduction) | 182 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 183 | TBD. | mA |
| | | GPRS Data transfer GSM1800; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 248 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 310 | TBD. | mA |
| | | EDGE Data transfer GSM1800; PCL=5; 1Tx/4Rx | ROPR=8 (max. reduction) | 147 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 145 | TBD. | mA |
| | | EDGE Data transfer GSM1800; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 226 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 244 | TBD. | mA |
| | | GPRS Data transfer GSM1900; PCL=5; 1Tx/4RX | ROPR=8 (max. reduction) | 185 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 184 | TBD. | mA |
| | | GPRS Data transfer GSM1900; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 250 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 315 | TBD. | mA |
| | | EDGE Data transfer GSM1900; PCL=5; 1Tx/4Rx | ROPR=8 (max. reduction) | 149 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 147 | TBD. | mA |
| | | EDGE Data transfer GSM1900; PCL=5; 2Tx/3Rx | ROPR=8 (max. reduction) | 229 | TBD. | mA |
| | | | ROPR=4 (no reduction) | 247 | TBD. | mA |
| | Peak current during GSM transmit burst @ 3.8V | GPRS Data transfer GSM850; PCL=5; 2Tx/3Rx | | 1.79 | TBD. | A |
| | | GPRS Data transfer GSM900; PCL=5; 2Tx/3Rx | | 1.99 | TBD. | A |
| | | GPRS Data transfer GSM1800; PCL=0; 2Tx/3Rx | | 1.26 | TBD. | A |
| | | GPRS Data transfer GSM1900; PCL=0; 2Tx/3Rx | | 1.29 | TBD. | A |

3.4 Power Supply

Table 27: Current consumption ratings General and GSM (TX82-W and TX82-W-B)

| Description | | Conditions | Typical rating | | Unit |
|--|---|---|----------------|----------|------|
| | | | TX82-W | TX82-W-B | |
| I_{BATT+}^1 (i.e., sum of $BATT+_{BB}$ and $BATT+_{RF}$) | Peak current during GSM transmit burst @ 3.0V | GPRS Data transfer GSM850; PCL=5; 2Tx/3Rx | 1.76 | TBD. | A |
| | | GPRS Data transfer GSM900; PCL=5; 2Tx/3Rx | 1.76 | TBD. | A |
| | | GPRS Data transfer GSM1800; PCL=0; 2Tx/3Rx | 1.23 | TBD. | A |
| | | GPRS Data transfer GSM1900; PCL=0; 2Tx/3Rx | 1.26 | TBD. | A |
| | Average GSM IDLE supply current (GNSS on) | GPRS active (UART active) @ DRX=2 GNSS NMEA output off | 68 | TBD. | mA |
| | | GPRS active (UART active) @ DRX=2 GNSS NMEA output on | 68 | TBD. | mA |

1. With an impedance of $Z_{LOAD}=50\Omega$ at the antenna connector, Measured at 25°C at 3.8V.

2. Measurements start 6 minutes after switching ON the module,

Averaging times:

OFF mode: 3 minutes

SLEEP and IDLE mode - 10 minutes

Transfer modes - 3 minutes

Communication tester settings: no neighbor cells, no cell re-selection etc., RMC (reference measurement channel), SLEEP mode is enabled via AT command

3. The power save mode (PSM) is disabled via AT command

3.4.2 Minimizing Power Losses

For TX82-W only: When designing the power supply for your application (and with GSM enabled) please pay specific attention to power losses. Ensure that the input voltage V_{BATT+} never drops below 3.1V on the TX82-W board, not even in a GSM transmit burst where current consumption can rise (for peak values see the power supply ratings listed in [Section 3.4.1](#)).

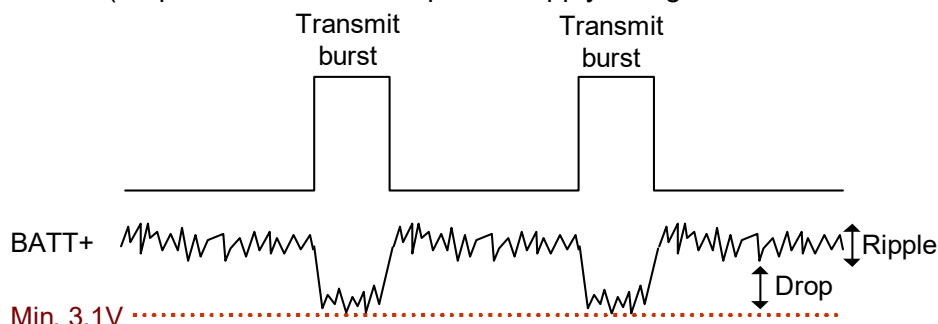


Figure 50: Power supply limits during transmit burst

3.4.3 Measuring the Supply Voltage (V_{BATT+})

To measure the supply voltage V_{BATT+} , it is possible to define two reference points GND and BATT+. GND and BATT+ should be a test pad on the external application the module is mounted on. The external GND reference point has to be connected to and positioned close to the SMT application interface's GND pad F17 and the external BATT+ reference point has to be connected to and positioned close to the SMT application interface's BATT+ pads G15 and G16 ($BATT+_{RF}$) or H15 and H16 ($BATT+_{BB}$) as shown in [Figure 51](#).

Reference point BATT+:

External test pad connected to and positioned closely to BATT+ pad G15, H15, H16 or G16.

Reference point GND:

External test pad connected to and positioned closely to GND pad F17



Figure 51: Position of reference points BATT+ and GND

3.4.4 Monitoring Power Supply by AT Command

To monitor the supply voltage you can also use the AT[^]SBV command which returns the value related to the reference points BATT+ and GND.

The module continuously measures the voltage at intervals depending on the operating mode of the RF interface. The duration of measuring ranges from 0.5 seconds in TALK/DATA mode to 50 seconds when TX62/TX82 is in IDLE mode or Limited Service (deregistered). The displayed voltage (in mV) is averaged over the last measuring period before the AT[^]SBV command was executed.

If the measured voltage drops below or rises above the voltage shutdown thresholds, the module will send an "SBC" URC and shut down (for details see [Section 3.2.5](#)).

3.5 Operating Temperatures

Please note that the module's lifetime, i.e., the MTTF (mean time to failure) may be reduced, if operated outside the extended temperature range.

Table 28: Board temperature

| Parameter | Min | Typ | Max | Unit |
|--|------|-----|------|------|
| Normal operation | -30 | | +85 | °C |
| Extended operation ¹ | -40 | | +90 | °C |
| Automatic shutdown ² Temperature measured on TX62/TX82 board | <-40 | --- | >+90 | °C |

1. Extended operation allows normal mode speech calls or data transmission for limited time. Within the extended temperature range (outside the normal operating temperature range) the specified electrical characteristics may be in- or decreased.

2. Due to temperature measurement uncertainty, a tolerance of $\pm 3^{\circ}\text{C}$ on the thresholds may occur.

See also [Section 3.2.5](#) for information about the NTC for on-board temperature measurement, automatic thermal shutdown and alert messages.

Note: Within the specified operating temperature ranges the board temperature may vary to a great extent depending on operating mode, used frequency band, radio output power and current supply voltage.

The below [Table 29](#) lists the ambient temperature ranges the TX62/TX82 is able to operate in.

Table 29: Ambient temperature

| Parameter | Min | Typ | Max | Unit |
|------------------------|-----|-----|-----|------|
| Normal operation (GSM) | -40 | | +60 | °C |
| Normal operation (LTE) | -40 | | +70 | °C |

3.6 Electrostatic Discharge

The module is not protected against Electrostatic Discharge (ESD) in general. Consequently, it is subject to ESD handling precautions that typically apply to ESD sensitive components. Proper ESD handling and packaging procedures must be applied throughout the processing, handling and operation of any application that incorporates a TX62/TX82 module.

Special ESD protection provided on TX62/TX82:

Main antenna interface: Inductor/capacitor

BATT+: Inductor/capacitor

An example for an enhanced ESD protection for the SIM interface is given in [Section 2.1.6.1](#).

TX62/TX82 has been tested according to group standard ETSI EN 301 489-1 (see [Table 38](#)). Electrostatic values can be gathered from the following table.

Table 30: Electrostatic values

| Specification/Requirements | Contact discharge | Air discharge |
|--|-------------------|------------------|
| ETSI EN 301 489-1 | | |
| Main antenna interface | $\pm 4\text{kV}$ | $\pm 8\text{kV}$ |
| BATT+ | $\pm 4\text{kV}$ | $\pm 8\text{kV}$ |
| JEDEC JESD22-A114D (Human Body Model, Test conditions: $1.5\text{ k}\Omega$, 100 pF) | | |
| All other interfaces | $\pm 1\text{kV}$ | n.a. |

Note: The values may vary with the individual application design. For example, it matters whether or not the application platform is grounded over external devices like a computer or other equipment, such as the Thales reference application described in [Chapter 5](#).

3.6.1 ESD Protection for RF Antenna Interface

The following [Figure 52](#) shows how to implement an external ESD protection for the RF antenna interface with either a T pad or PI pad attenuator circuit (for RF line routing design see also [Section 2.2.3](#)).

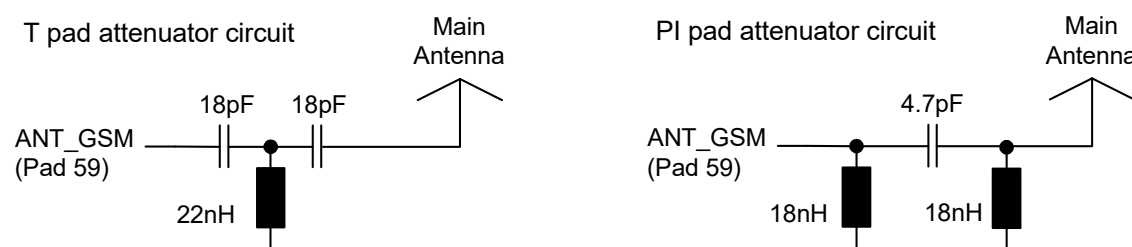


Figure 52: ESD protection for RF antenna interface

Recommended inductor types for the above sample circuits: Size 0402 SMD from Panasonic ELJRF series (22nH and 18nH inductors) or Murata LQW15AN18NJ00 (18nH inductors only).

3.7 Blocking against RF on Interface Lines

To reduce EMI issues there are serial resistors, or capacitors to GND, implemented on the module for the ignition, emergency restart, and SIM interface lines (cp. [Section 2.4](#)). However, all other signal lines have no EMI measures on the module and there are no blocking measures at the module's interface to an external application.

Dependent on the specific application design, it might be useful to implement further EMI measures on some signal lines at the interface between module and application. These measures are described below.

There are five possible variants of EMI measures (A-E) that may be implemented between module and external application depending on the signal line (see [Figure 53](#) and [Table 31](#)). Pay attention not to exceed the maximum input voltages and prevent voltage overshots if using inductive EMC measures.

The maximum value of the serial resistor should be lower than $1\text{k}\Omega$ on the signal line. The maximum value of the capacitor should be lower than 50pF on the signal line. Please observe the electrical specification of the module's SMT application interface and the external application's interface.

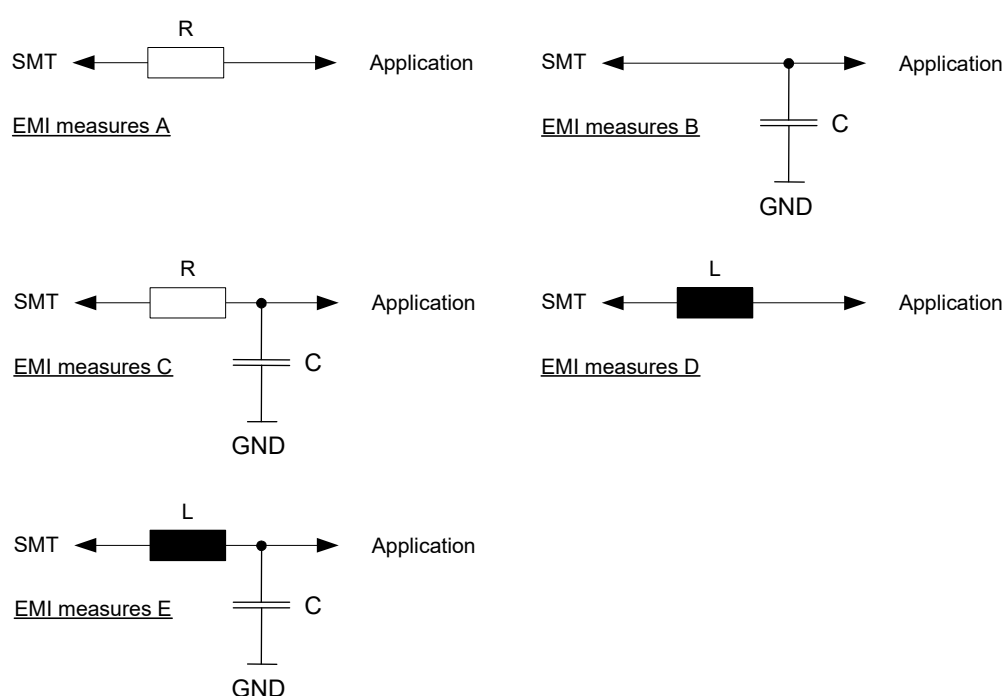


Figure 53: EMI circuits

Note: In case the application uses an internal GSM/LTE antenna that is implemented close to the TX62/TX82 module, Thales strongly recommends sufficient EMI measures, e.g. of type B or C, for each digital input or output.

3.7 Blocking against RF on Interface Lines

The following table lists for each signal line at the module's SMT application interface the EMI measures that may be implemented.

Table 31: EMI measures on the application interface

| Signal name | EMI measures | | | | | Remark |
|--|--------------|---|---|---|---|--|
| | A | B | C | D | E | |
| CCIN | | | | x | | |
| CCRST | | x | | | | The external capacitor should be not higher than 1nF. The value of the capacitor depends on the external application and should be placed close to SIM connector/eUICC. |
| CCIO | | x | | | | The external capacitor should be not higher than 10pF. The value of the capacitor depends on the external application and should be placed close to SIM connector/eUICC. |
| CCCLK | | x | | | | |
| VUSB | | x | | x | x | |
| RXD0 | x | x | x | x | x | |
| TXD0 | x | x | x | x | x | |
| CTS0 | x | x | x | x | x | |
| RTS0 | x | x | x | x | x | |
| DTR0 | x | x | x | x | x | |
| DCD0 | x | x | x | x | x | |
| DSR0 | x | x | x | x | x | |
| RXD1 | x | x | x | x | x | |
| TXD1 | x | x | x | x | x | |
| RTS1 | x | x | x | x | x | |
| CTS1 | x | x | x | x | x | |
| RING0 | x | x | x | x | x | |
| FST_SHDN | x | x | x | x | x | |
| STATUS | x | x | x | x | x | |
| SIM_SWITCH | x | x | x | x | x | |
| SUSPEND_MON | x | x | x | x | x | |
| GPIO6,7,20-23,25 | x | x | x | x | x | |
| I2CDAT ¹ | | x | | x | | The rising signal edge is reduced with an additional capacitor. |
| I2CCLK ¹ | | x | | x | | |
| V180 | | x | | x | x | |
| BATT ⁺ _{RF} (pad G15, G16) | | x | x | | | Measures required if BATT ⁺ _{RF} is close to internal GSM antenna - e.g., 39pF blocking capacitor to ground |
| BATT ⁺ _{BB} (pad H15, H16) | | x | x | | | |

1. Available with embedded processing option only.

3.8 Reliability Characteristics

The test conditions stated below are an extract of the complete test specifications.

Table 32: Summary of reliability test conditions

| Type of test | Conditions | Standard |
|----------------------------|--|--|
| Vibration | Frequency range: 10-20Hz; acceleration: 5g Frequency range: 20-500Hz; acceleration: 20g Duration: 20h per axis; 3 axes | DIN IEC 60068-2-6 ¹ |
| Shock half-sinus | Acceleration: 500g Shock duration: 1ms 1 shock per axis 6 positions (\pm x, y and z) | DIN IEC 60068-2-27 |
| Dry heat | Temperature: $+70 \pm 2^{\circ}\text{C}$ Test duration: 16h Humidity in the test chamber: < 50% | EN 60068-2-2 Bb ETS 300 019-2-7 |
| Temperature change (shock) | Low temperature: $-40^{\circ}\text{C} \pm 2^{\circ}\text{C}$ High temperature: $+85^{\circ}\text{C} \pm 2^{\circ}\text{C}$ Changeover time: < 30s (dual chamber system) Test duration: 1h Number of repetitions: 100 | DIN IEC 60068-2-14 Na ETS 300 019-2-7 |
| Damp heat cyclic | High temperature: $+55^{\circ}\text{C} \pm 2^{\circ}\text{C}$ Low temperature: $+25^{\circ}\text{C} \pm 2^{\circ}\text{C}$ Humidity: 93% \pm 3% Number of repetitions: 6 Test duration: 12h + 12h | DIN IEC 60068-2-30 Db ETS 300 019-2-5 |
| Cold (constant exposure) | Temperature: $-40 \pm 2^{\circ}\text{C}$ Test duration: 16h | DIN IEC 60068-2-1 |

1. For reliability tests in the frequency range 20-500Hz the Standard's acceleration reference value was increased to 20g.

4 Mechanical Dimensions, Mounting and Packaging

4.1 Mechanical Dimensions of TX62-W

Figure 54 shows the top and bottom view of TX62-W and provides an overview of the board's mechanical dimensions. For further details see Figure 55. Figure 56 shows the area at the module's bottom side where possible markings might be printed.

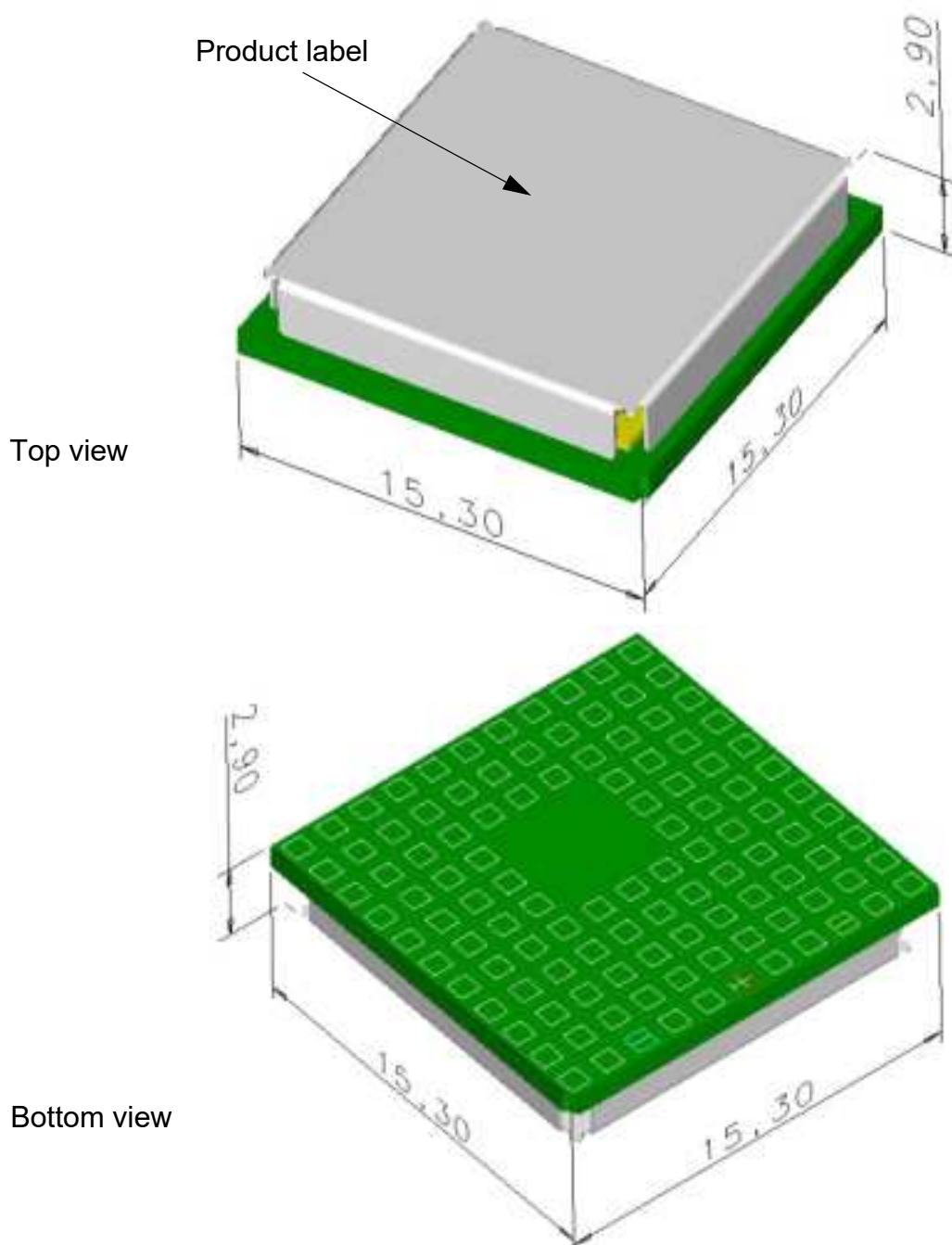


Figure 54: TX62-W– top and bottom view

4.1 Mechanical Dimensions of TX62-W

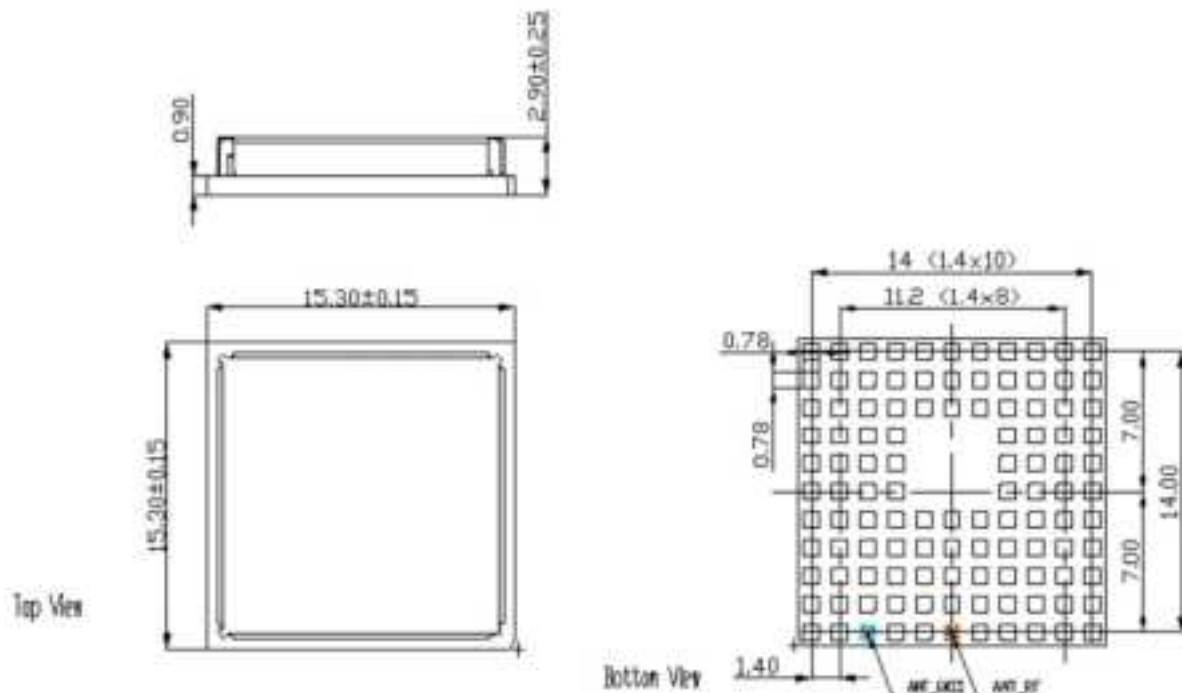


Figure 55: Dimensions of TX62-W (all dimensions in mm)

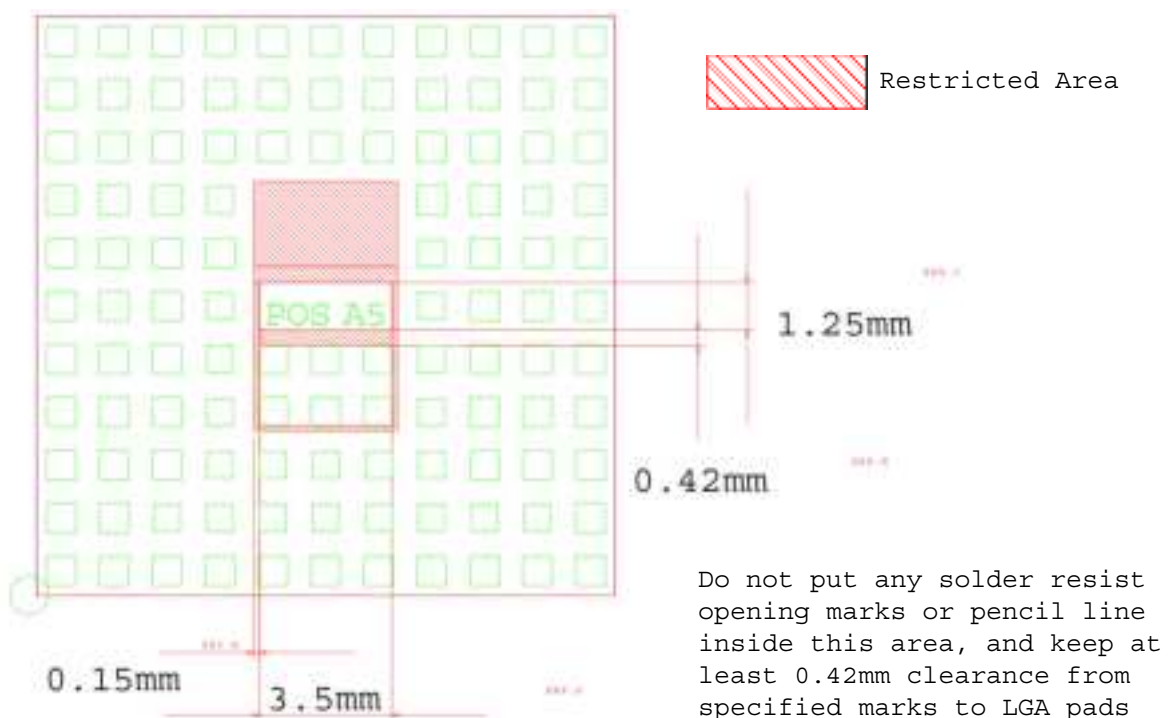


Figure 56: Dimensions of area for possible markings TX62-W (bottom view)

4.2 Mechanical Dimensions of TX82-W, TX82-W-B, TX62-W-B and TX62-W-C

Figure 57 shows the top and bottom view of TX82-W, TX82-W-B, TX62-W-B, and TX62-W-C, and provides an overview of the board's mechanical dimensions. For further details see Figure 59. Figure 60 shows the area at the module's bottom side where possible markings might be printed.

Note: Other than shown in the below 3D view (Figure 57) the module height for TX82-W and TX62-W-B is 2.30mm, and for TX82-W-B and TX62-W-C is 2.92mm.

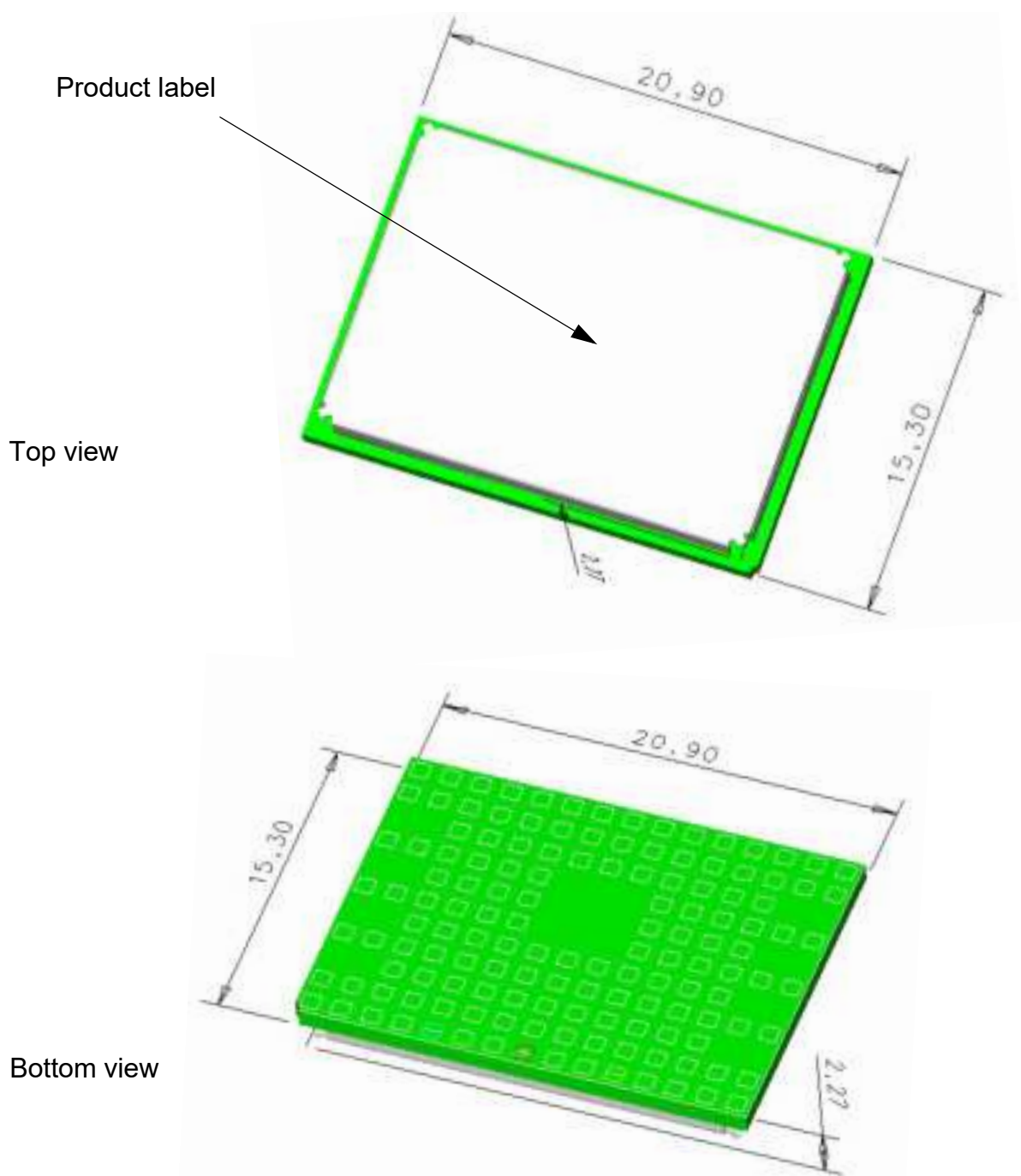


Figure 57: TX82– top and bottom view

4.2 Mechanical Dimensions of TX82-W, TX82-W-B, TX62-W-B and TX62-W-C

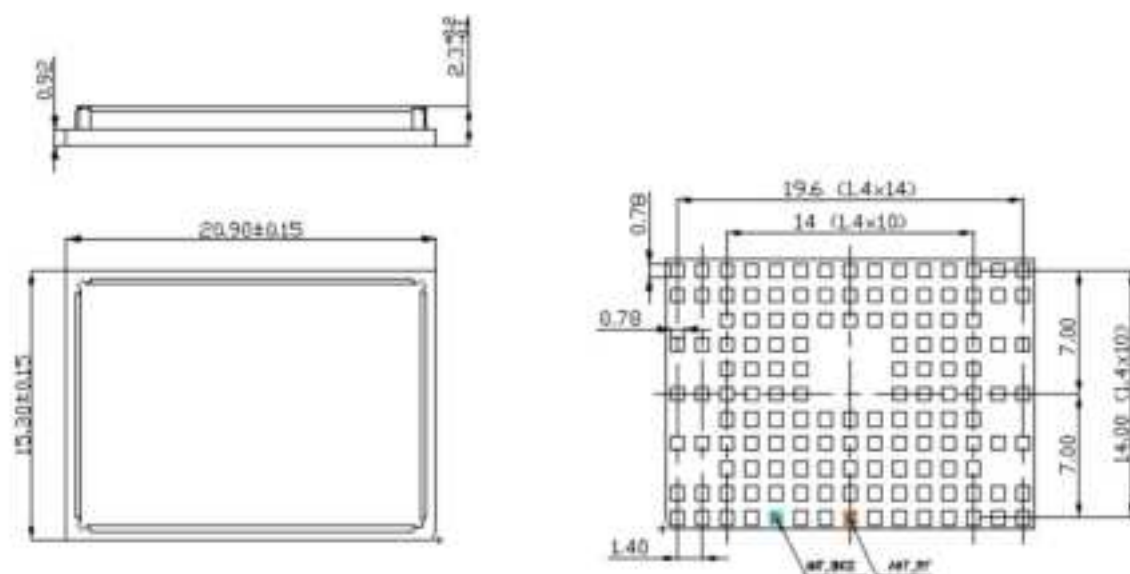


Figure 58: Dimensions of TX82-W and TX62-W-B (all dimensions in mm)

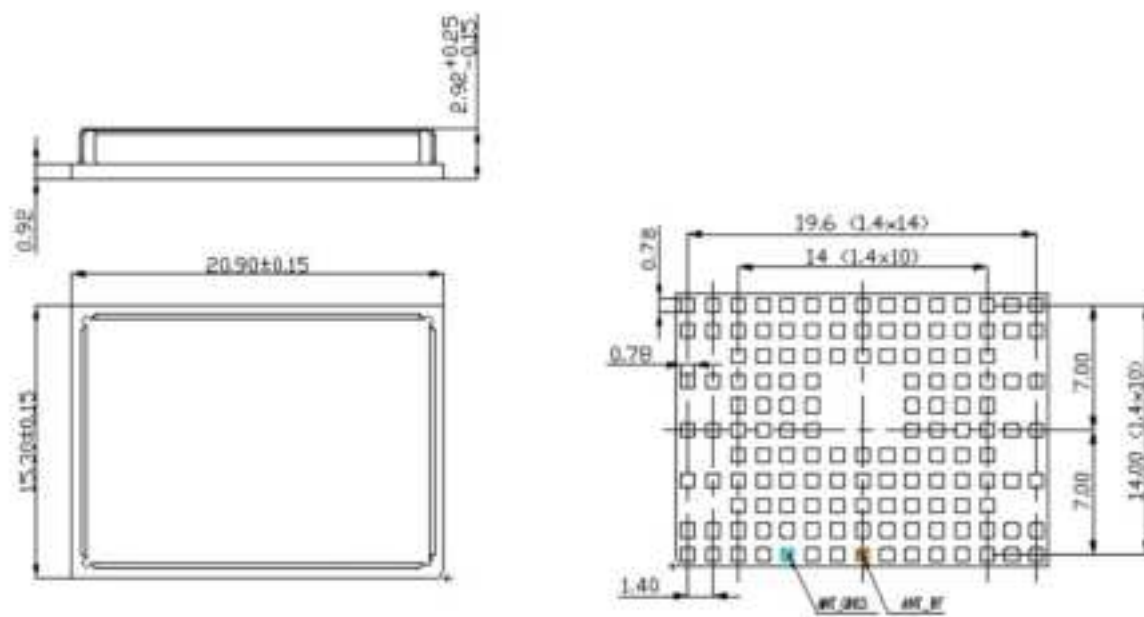


Figure 59: Dimensions of TX82-W-B and TX62-W-C (all dimensions in mm)

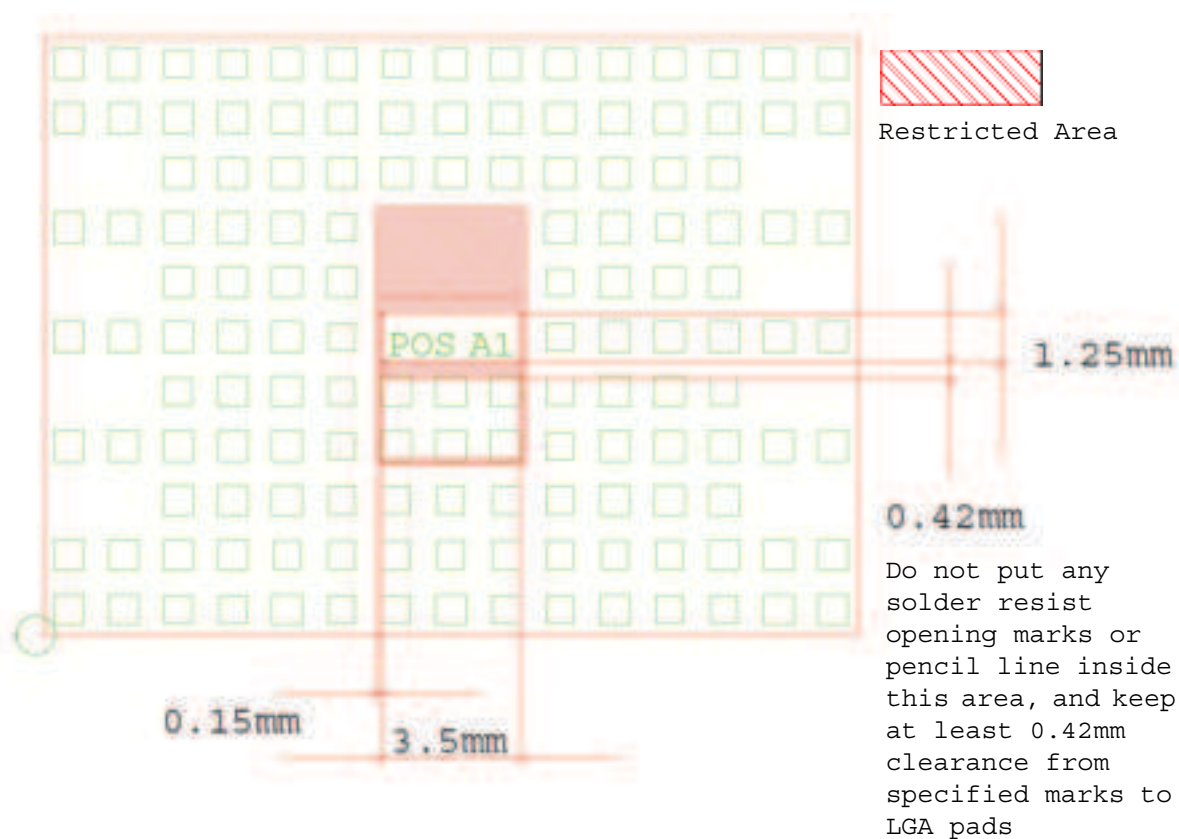


Figure 60: Dimensions of area for possible markings TX82-W, TX82-W-B, TX62-W-B and TX62-W-C (bottom view)

4.3 Mounting TX62/TX82 onto the Application Platform

This section describes how to mount TX62/TX82 onto the PCBs, including land pattern and stencil design, board-level characterization, soldering conditions, durability and mechanical handling. For more information on issues related to SMT module integration see also [5].

Note: To avoid short circuits between signal tracks on an external application's PCB and various markings at the bottom side of the module (see [Figure 56](#) and [Figure 60](#)), it is recommended not to route the signal tracks on the top layer of an external PCB directly under the module, or at least to ensure that signal track routes are sufficiently covered with solder resist.

Note: Do not place external components or devices that might cause any pressure on the module's shielding. See [4] and [5] for further details of thermal and integration guidance.

4.3.1 SMT PCB Assembly

4.3.1.1 Land Pattern and Stencil

The land pattern and stencil design as shown below is based on Thales characterizations for lead-free solder paste on a four-layer test PCB and a 110 micron thick stencil.

The land pattern given in [Figure 61](#) and [Figure 62](#) reflects the module's pad layout, including signal pads and ground pads (for pad assignment see [Section 2.1.1](#)).

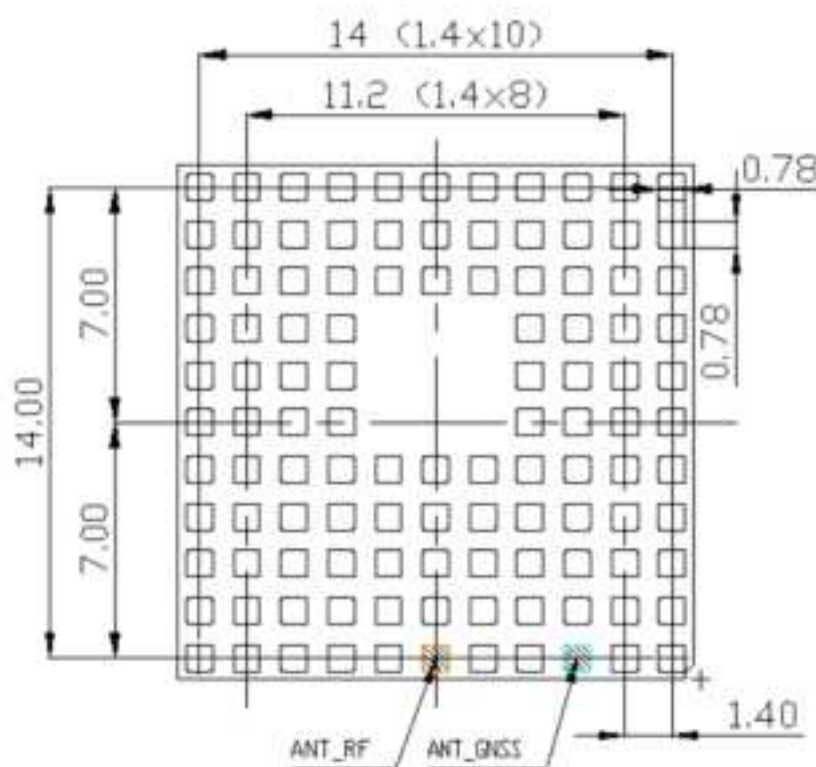


Figure 61: Land pattern TX62-W (top view)

4.3 Mounting TX62/TX82 onto the Application Platform

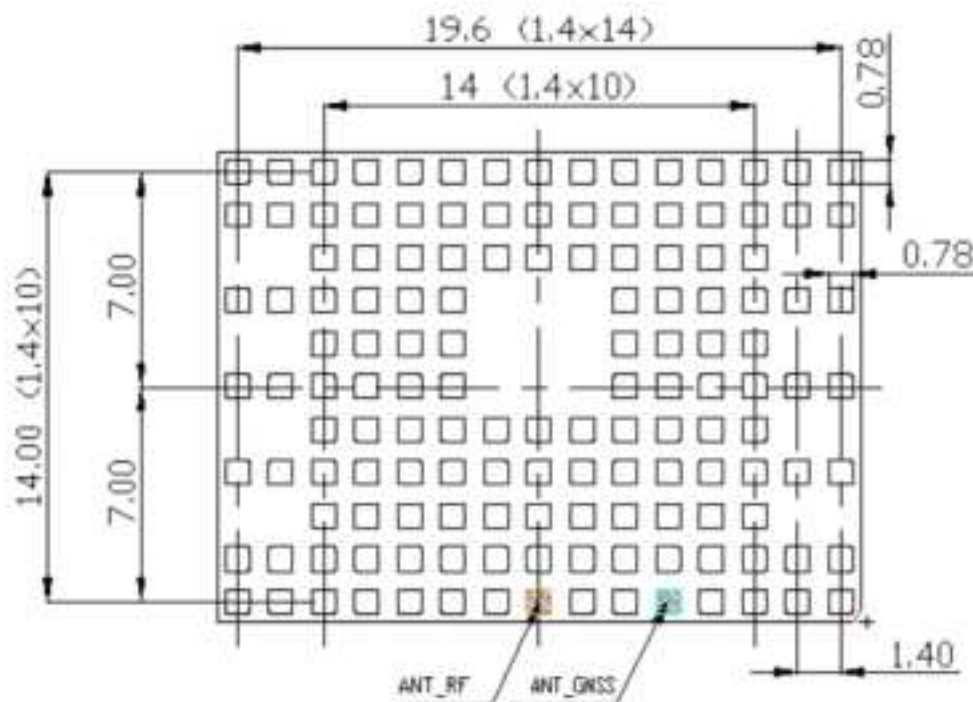


Figure 62: Land pattern TX82-W, TX82-W-B, TX62-W-B and TX62-W-C (top view)

The stencil design illustrated in [Figure 63](#) and [Figure 64](#) is recommended by Thales as a result of extensive tests with Thales Daisy Chain modules.

The central ground pads are primarily intended for stabilizing purposes, and may show some more voids than the application interface pads at the module's rim. This is acceptable, since they are electrically irrelevant.

4.3 Mounting TX62/TX82 onto the Application Platform

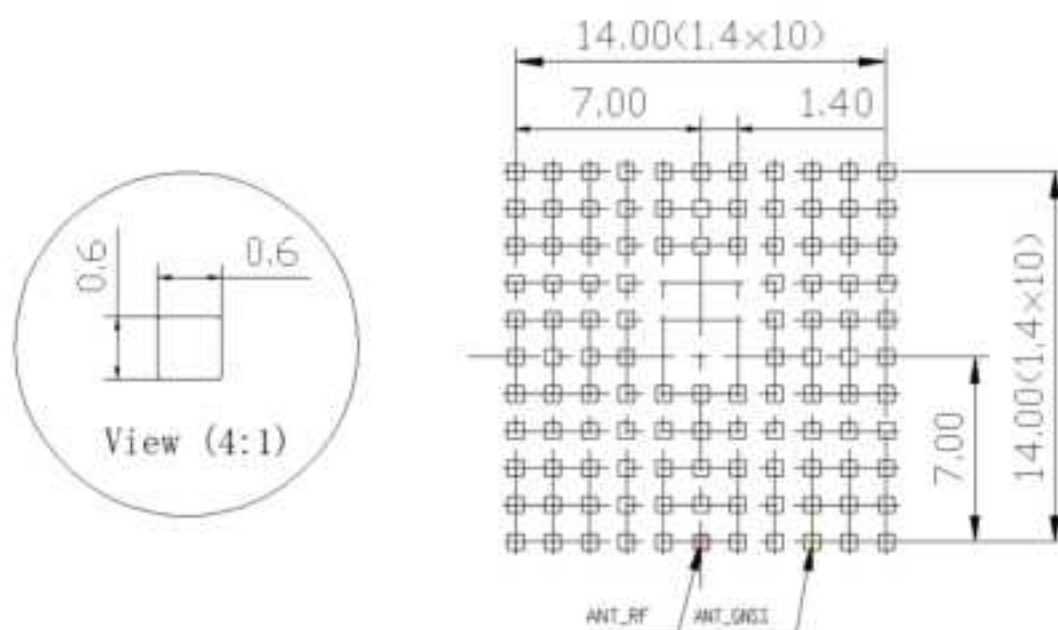


Figure 63: Recommended design for 110µm thick stencil for TX62-W (top view)

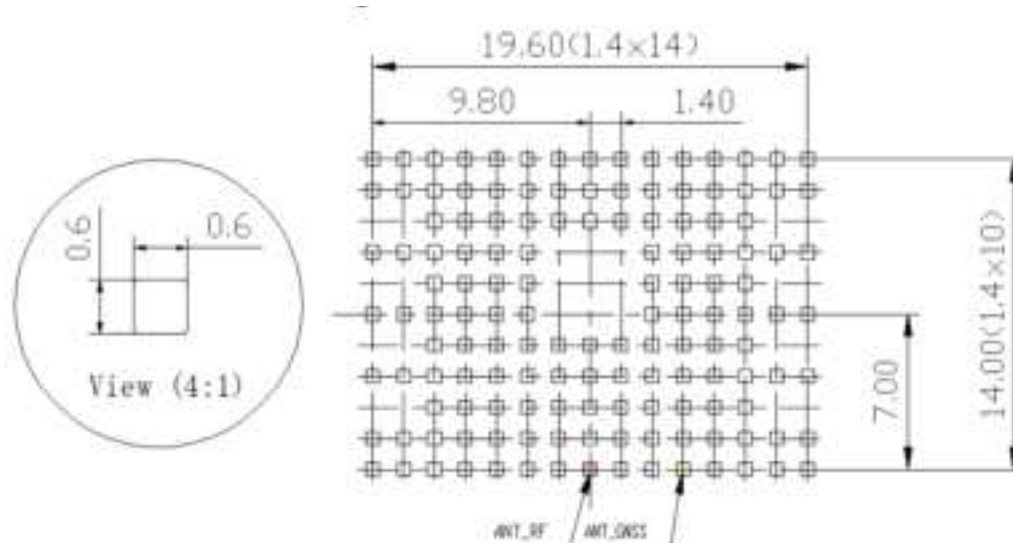


Figure 64: Recommended design for 110µm thick stencil for TX82-W, TX82-W-B, TX62-W-B and TX62-W-C (top view)

4.3.1.2 Board Level Characterization

Board level characterization issues should also be taken into account if devising an SMT process.

Characterization tests should attempt to optimize the SMT process with regard to board level reliability. This can be done by performing the following physical tests on sample boards: Peel test, bend test, tensile pull test, drop shock test and temperature cycling. Sample surface mount checks are described in [\[5\]](#).

4.3 Mounting TX62/TX82 onto the Application Platform

It is recommended to characterize land patterns before an actual PCB production, taking individual processes, materials, equipment, stencil design, and reflow profile into account. For land and stencil pattern design recommendations see also [Section 4.3.1.1](#). Optimizing the solder stencil pattern design and print process is necessary to ensure print uniformity, to decrease solder voids, and to increase board level reliability.

Generally, solder paste manufacturer recommendations for screen printing process parameters and reflow profile conditions should be followed. Maximum ratings are described in [Section 4.3.3](#).

4.3.2 Moisture Sensitivity Level

TX62/TX82 comprises components that are susceptible to damage induced by absorbed moisture.

Thales's TX62/TX82 module complies with the latest revision of the IPC/JEDEC J-STD-020 Standard for moisture sensitive surface mount devices and is classified as MSL 4.

For additional moisture sensitivity level (MSL) related information see [Section 4.3.4](#) and [Section 4.4.2](#).

4.3.3 Soldering Conditions and Temperature

4.3.3.1 Reflow Profile

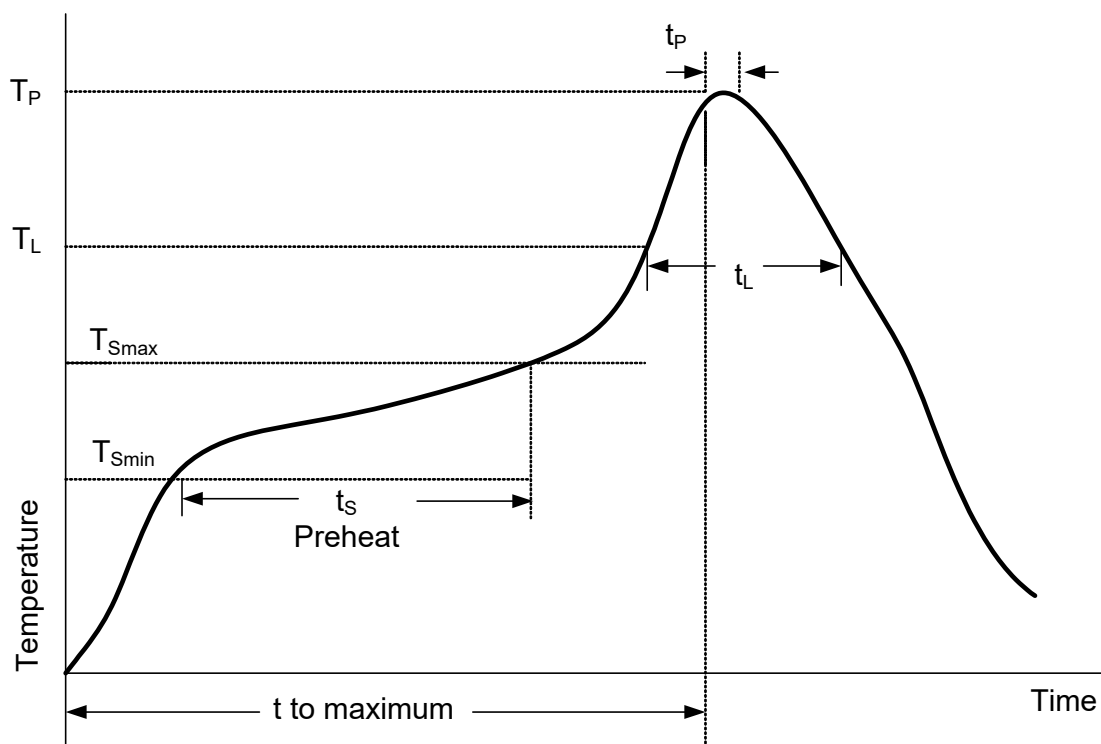


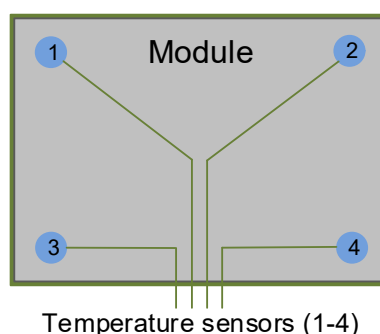
Figure 65: Reflow Profile

4.3 Mounting TX62/TX82 onto the Application Platform

Table 33: Reflow temperature ratings¹

| Profile Feature | Pb-Free Assembly |
|---|--|
| Preheat & Soak Temperature Minimum (T_{Smin}) Temperature Maximum (T_{Smax}) Time (t_{Smin} to t_{Smax}) (t_S) | 150°C 180°C 60-120 seconds |
| Average ramp up rate (T_{Smax} to T_P) | 3K/second max. ² |
| Liquidous temperature (T_L) Time at liquidous (t_L) | 217°C 50-90 seconds |
| Peak package body temperature (T_P) | 245°C +0/-5°C |
| Time (t_P) within 5 °C of the peak package body temperature (T_P) | 30 seconds max. |
| Limited ramp-down rate (T_P - 200°C) Average ramp-down rate from 200°C | 1K-2.5K/second max. ^{2, 3} 3K/second max. ² |
| Time 25°C to maximum temperature | 8 minutes max. |

1. Please note that the reflow profile features and ratings listed above are based on the joint industry standard IPC/JEDEC J-STD-020E, and are as such meant as a general guideline. For more information on reflow profiles and their optimization please refer to [5].
2. Temperatures measured on shielding at each corner. For more information see [5].
During the critical ramp-down phase, (T_P to 200°C), temperature differences between sensors (1,2,3,4) should be as low as possible.



3. Lowest ramp-down rate achievable is also dependent on reflow oven tape and settings used. Use lowest ramp down rate from T_P - 200°C. For more information see [5].

4.3.3.2 Maximum Temperature and Duration

The following limits are recommended for the SMT board-level soldering process to attach the module:

- A maximum module temperature of 245°C. This specifies the temperature as measured at the module's top side.
- A maximum duration of 15 seconds at this temperature.

Please note that while the solder paste manufacturers' recommendations for best temperature and duration for solder reflow should generally be followed, the limits listed above must not be exceeded.

TX62/TX82 is specified for one soldering cycle only. Once TX62/TX82 is removed from the application, the module will very likely be destroyed and cannot be soldered onto another application.

4.3.4 Durability and Mechanical Handling

4.3.4.1 Storage Conditions

TX62/TX82 modules, as delivered in tape and reel carriers, must be stored in sealed, moisture barrier anti-static bags. The conditions stated below are only valid for modules in their original packed state in weather protected, non-temperature-controlled storage locations. Normal storage time under these conditions is 12 months maximum.

Table 34: Storage conditions

| Type | Condition | Unit | Reference |
|--|----------------------------|------------------------------|--|
| Air temperature: Low High | -25 +40 | °C | IPC/JEDEC J-STD-033A |
| Humidity relative: Low High | 10 90 at 40°C | % | IPC/JEDEC J-STD-033A |
| Air pressure: Low High | 70 106 | kPa | IEC TR 60271-3-1: 1K4 IEC TR 60271-3-1: 1K4 |
| Movement of surrounding air | 1.0 | m/s | IEC TR 60271-3-1: 1K4 |
| Water: rain, dripping, icing and frosting | Not allowed | --- | --- |
| Radiation: Solar Heat | 1120 600 | W/m ² | ETS 300 019-2-1: T1.2, IEC 60068-2-2 Bb ETS 300 019-2-1: T1.2, IEC 60068-2-2 Bb |
| Chemically active substances | Not recommended | | IEC TR 60271-3-1: 1C1L |
| Mechanically active substances | Not recommended | | IEC TR 60271-3-1: 1S1 |
| Vibration sinusoidal: Displacement Acceleration Frequency range | 1.5 5 2-9 9-200 | mm m/s ² Hz | IEC TR 60271-3-1: 1M2 |
| Shocks: Shock spectrum Duration Acceleration | semi-sinusoidal 1 50 | ms m/s ² | IEC 60068-2-27 Ea |

4.3.4.2 Processing Life

TX62/TX82 must be soldered to an application within 72 hours after opening the moisture barrier bag (MBB) it was stored in.

As specified in the IPC/JEDEC J-STD-033 Standard, the manufacturing site processing the modules should have ambient temperatures below 30°C and a relative humidity below 60%.

4.3.4.3 Baking

Baking conditions are specified on the moisture sensitivity label attached to each MBB (see [Figure 71](#) for details):

- It is *not necessary* to bake TX62/TX82, if the conditions specified in [Section 4.3.4.1](#) and [Section 4.3.4.2](#) were not exceeded.
- It is *necessary* to bake TX62/TX82, if any condition specified in [Section 4.3.4.1](#) and [Section 4.3.4.2](#) was exceeded.

If baking is necessary, the modules must be put into trays that can be baked to at least 125°C. Devices should not be baked in tape and reel carriers at any temperature.

4.3.4.4 Electrostatic Discharge

Electrostatic discharge (ESD) may lead to irreversible damage for the module. It is therefore advisable to develop measures and methods to counter ESD and to use these to control the electrostatic environment at manufacturing sites.

Please refer to [Section 3.6](#) for further information on electrostatic discharge.

4.4 Packaging

4.4.1 Tape and Reel

The single-feed tape carrier for TX62/TX82 is illustrated in Figure 66. The figure also shows the proper part orientation. The tape width is 24mm and the TX62/TX82 modules are placed on the tape with a 22mm pitch. The reels are 330mm in diameter with a core diameter of 99.50mm. Each reel contains 500 modules.

4.4.1.1 Orientation

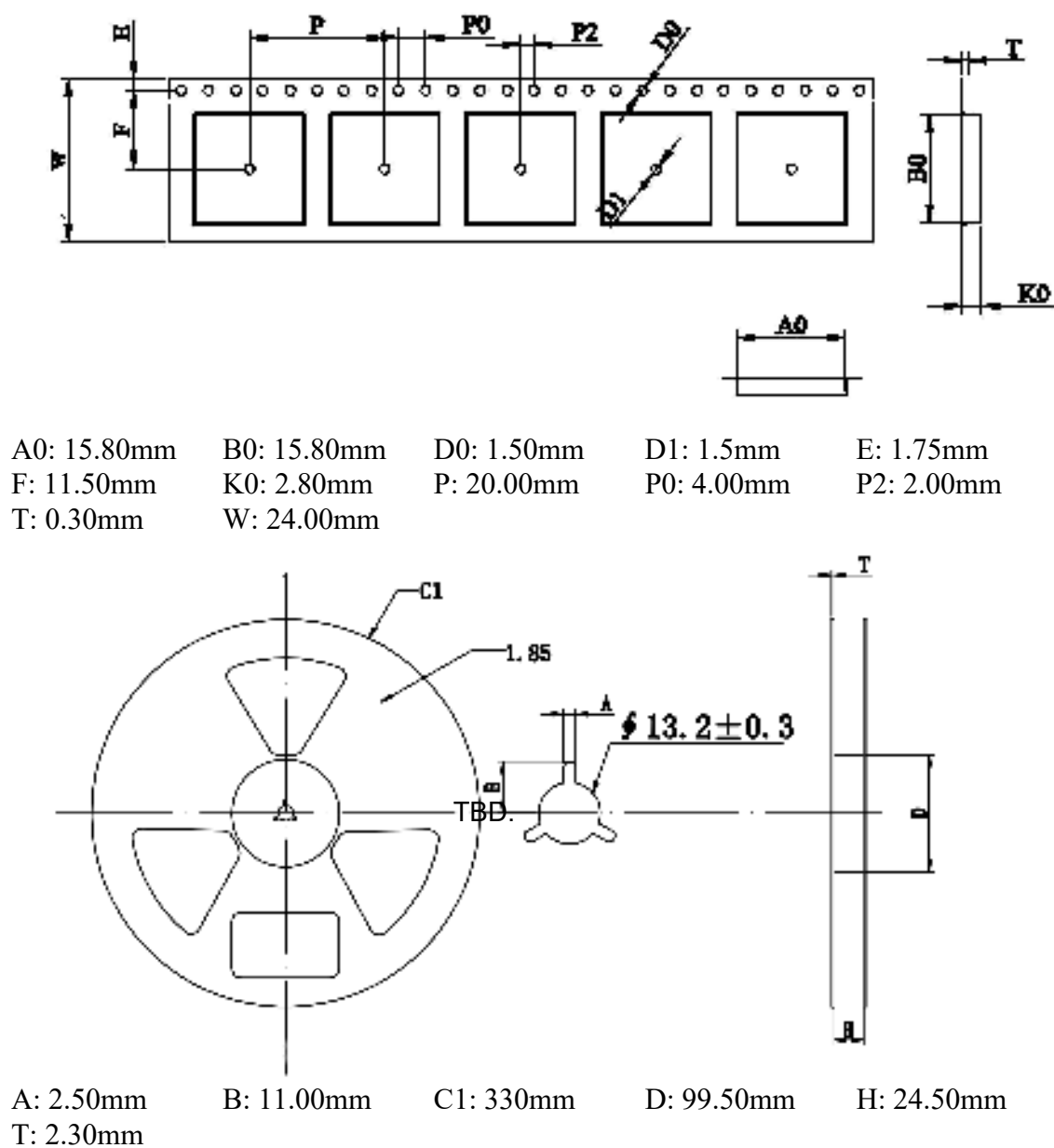


Figure 66: Carrier tape (TX62-W only)

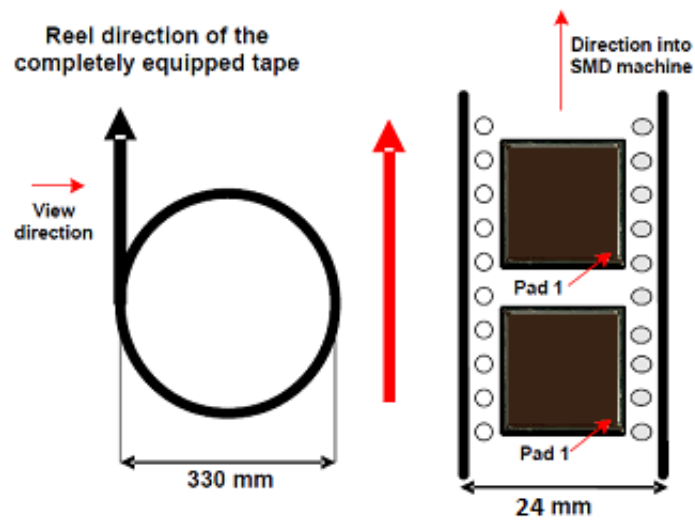


Figure 67: Reel direction (TX62-W only)

4.4.1.2 Barcode Label

A barcode label provides detailed information on the tape and its contents. It is attached to the reel.

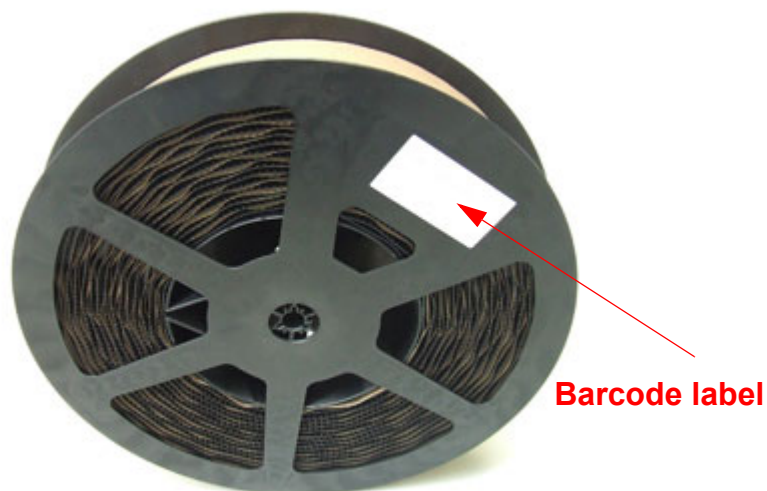


Figure 68: Barcode label on tape reel

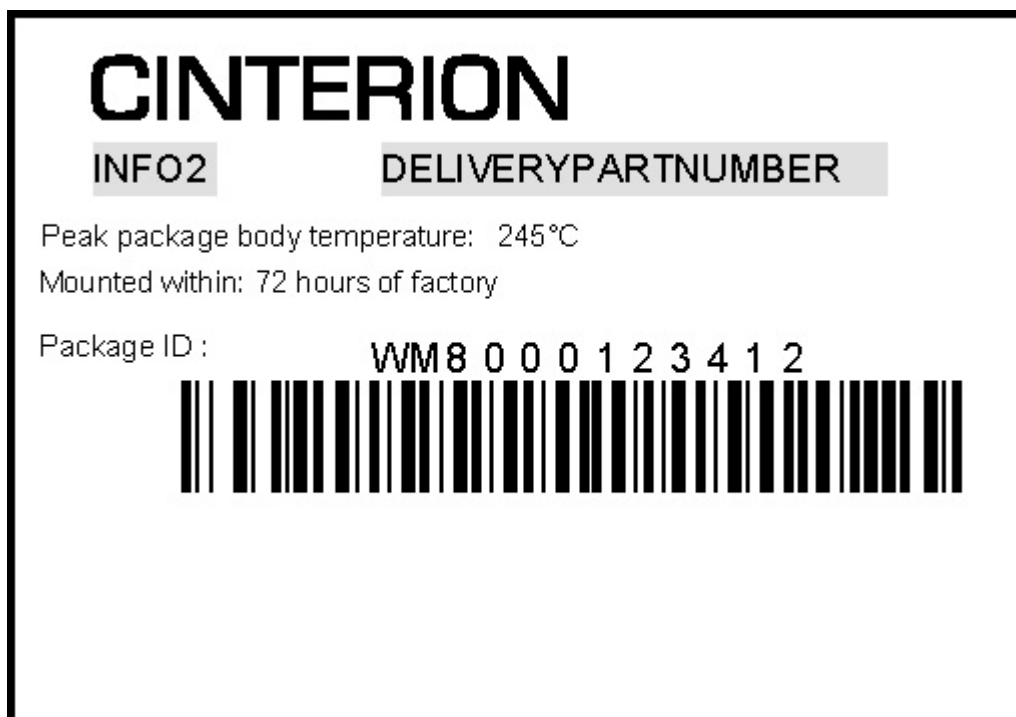


Figure 69: Barcode label on tape reel - layout

Variables on the label are explained in [Table 35](#).

4.4.2 Shipping Materials

TX62/TX82 is distributed in tape and reel carriers. The tape and reel carriers used to distribute TX62/TX82 are packed as described below, including the following required shipping materials:

- Moisture barrier bag, including desiccant and humidity indicator card
- Transportation box

4.4.2.1 Moisture Barrier Bag

The tape reels are stored inside a moisture barrier bag (MBB), together with a humidity indicator card and desiccant pouches - see [Figure 70](#). The bag is ESD protected and delimits moisture transmission. It is vacuum-sealed and should be handled carefully to avoid puncturing or tearing. The bag protects the TX62/TX82 modules from moisture exposure. It should not be opened until the devices are ready to be soldered onto the application.

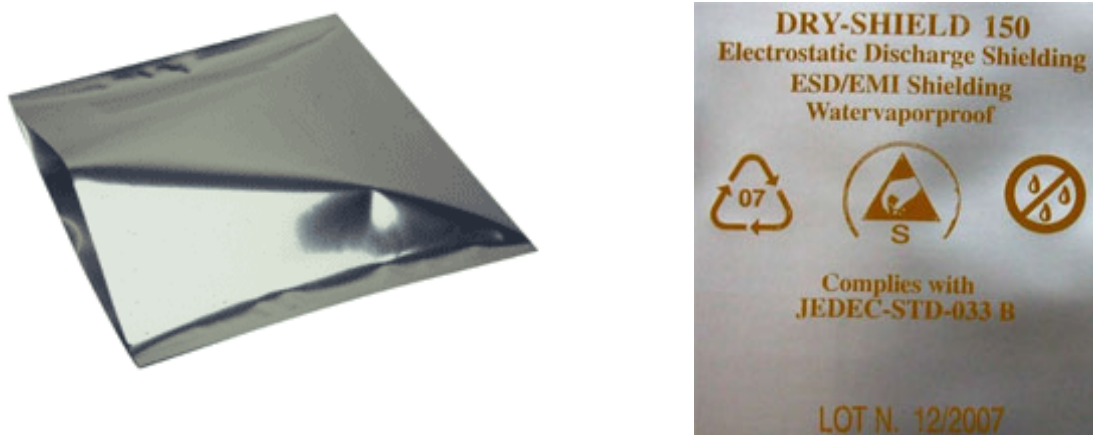


Figure 70: Moisture barrier bag (MBB) with imprint

The label shown in [Figure 71](#) summarizes requirements regarding moisture sensitivity, including shelf life and baking requirements. It is attached to the outside of the moisture barrier bag. Variables on the label are explained in [Table 35](#).




| | | |
|--|--|---|
|  | CAUTION This bag contains MOISTURE-SENSITIVE DEVICES | LEVEL <div style="border: 2px solid black; padding: 10px; display: inline-block; font-size: 2em; font-weight: bold;">4</div> |
| <ol style="list-style-type: none"> 1. Calculated shelf life in sealed bag: 12 months at < 40 °C and < 90% relative humidity (RH) 2. Peak package body temperature: <u>245 °C</u> 3. After bag is opened, devices that will be subject to reflow solder or other high temperature process must be <ol style="list-style-type: none"> a) mounted within: 72 hours of factory conditions < 30 °C / 60% RH b) stored at < 10% <u>RH</u> 4. Devices require bake, before mounting, if: <ol style="list-style-type: none"> a) Humidity Indicator Card is > 10% when read at 23 +/- 5 °C b) 3a or 3b not met 5. If baking is required, refer to IPC/Jedec J-STD-033 for bake procedure Note: The devices are shipped in a non heat-resistant carrier and may not be baked in the carriers 6. The maximum guaranteed soldering cycle of the module is limited to 1 cycle | | |
| Bag Seal Date: <u>DD.MM.YYYY</u> | | |
| Note: MSL level and body temperature defined by IPC/JEDEC J-STD-020 | | |
| <h1 style="margin: 0;">CINTERION</h1> | | |
| INFO-2 | DELIVERYPARTNUMBER | |
| Peak package body temperature: <u>245°C</u> | | |
| Qty. : <u>000</u> | | |
| Bag Seal Date (DDMMYYYY) : DDMMYYYY | | |
|  | | |
| Package ID: WM8000123412 | | |
|  | | |

Figure 71: Moisture Sensitivity Label

4.4 Packaging

MBBs contain one or more desiccant pouches to absorb moisture that may be in the bag. The humidity indicator card described below should be used to determine whether the enclosed components have absorbed an excessive amount of moisture.

The desiccant pouches should not be baked or reused once removed from the MBB.

The humidity indicator card is a moisture indicator and is included in the MBB to show the approximate relative humidity level within the bag. Sample humidity cards are shown in [Figure 72](#). If the components have been exposed to moisture above the recommended limits, the units will have to be rebaked.

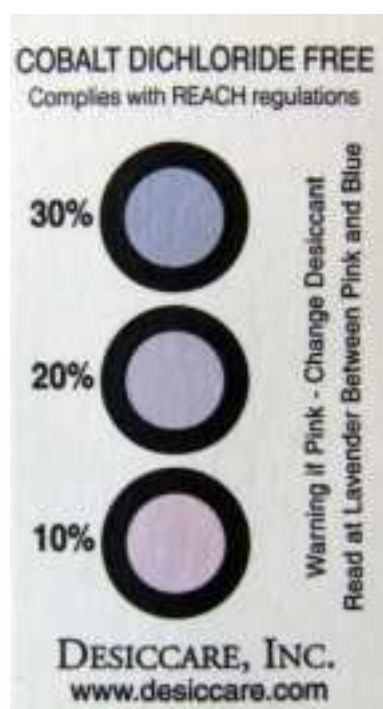


Figure 72: Humidity Indicator Card - HIC

A baking is required if the humidity indicator inside the bag indicates 10% RH or more.

4.4.2.2 Transportation Box

Tape and reel carriers are distributed in a box, marked with a barcode label for identification purposes. A box contains two reels with 500 modules each.

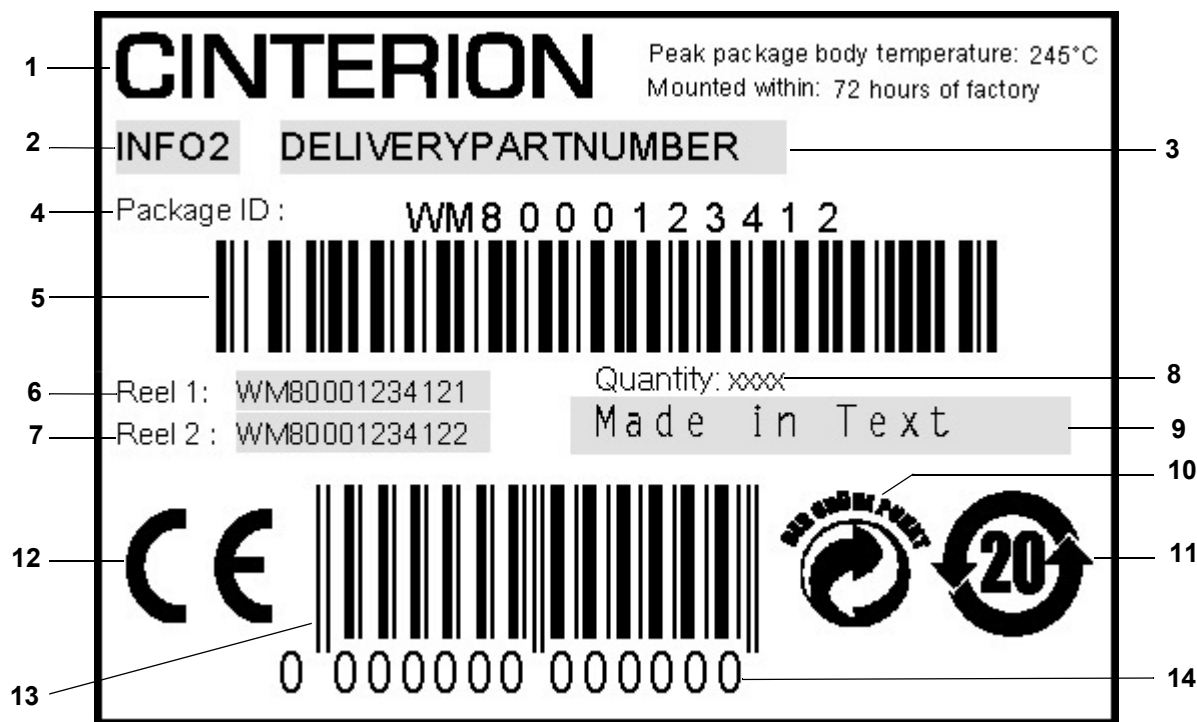


Figure 73: Sample of VP box label

Table 35: VP Box label information

| No. | Information |
|-----|--|
| 1 | Cinterion logo |
| 2 | Product name |
| 3 | Product ordering number |
| 4 | Package ID number of VP box (format may vary depending on the product) |
| 5 | Package ID barcode (Code 128) |
| 6 | Package ID Reel 1 (format may vary depending on the product) |
| 7 | Package ID Reel 2 (format may vary depending on the product) |
| 8 | Quantity of the modules inside the VP box (max. 1000 pcs) |
| 9 | Country of production |
| 10 | Der Grüne Punkt (Green Dot) symbol |
| 11 | Chinese RoHS symbol (see Table 40) |
| 12 | CE logo (CE mark on VP box label is present only for modules with CE imprinted on the shielding) |
| 13 | European Article Number (EAN-13) barcode |
| 14 | European Article Number, consists of 13 digits (EAN-13) |

4.4.3 Trays (TBD)

If small module quantities are required, e.g., for test and evaluation purposes, TX62/TX82 may be distributed in trays (for dimensions see [Figure 77](#)). The small quantity trays are an alternative to the single-feed tape carriers normally used. However, the trays are not designed for machine processing. They contain modules to be (hand) soldered onto an external application

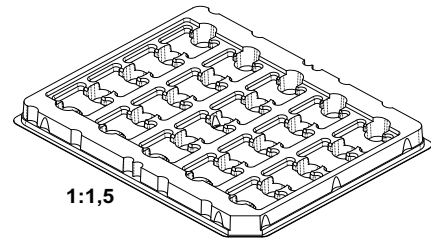


Figure 74: Small quantity tray

Trays are packed and shipped in the same way as tape carriers, including a moisture barrier bag with desiccant and humidity indicator card as well as a transportation box (see also [Section 4.4.2](#)).



Figure 75: Tray to ship odd module amounts



Figure 76: Trays with packaging materials

T.B.D.

Figure 77: Tray dimensions (TBD.)

5 Regulatory and Type Approval Information

5.1 Directives and Standards

TX62/TX82 is designed to comply with the directives and standards listed below.

It is the responsibility of the application manufacturer to ensure compliance of the final product with all provisions of the applicable directives and standards as well as with the technical specifications provided in the "Cinterion® TX62-W/TX82-W Hardware Interface Description".¹

Table 36: Directives




| | |
|--|--|
| 2014/53/EU | Directive of the European Parliament and of the Council of 16 April 2014 on the harmonisation of the laws of the Member States relating to the making available on the market of radio equipment and repealing Directive 1999/5/EC. The product is labeled with the CE conformity mark  |
| 2002/95/EC (RoHS 1) 2011/65/EC (RoHS 2) | Directive of the European Parliament and of the Council of 27 January 2003 (and revised on 8 June 2011) on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS)  |
| 1907/2006/EC (REACH) | Regulation (EC) No 1907/2006 of the European Parliament and of the Council of 18 December 2006 concerning the Registration, Evaluation, Authorisation and Restriction of Chemicals (REACH), establishing a European Chemicals Agency, amending Directive 1999/45/EC and repealing Council Regulation (EEC) No 793/93 and Commission Regulation (EC) No 1488/94 as well as Council Directive 76/769/EEC and Commission Directives 91/155/EEC, 93/67/EEC, 93/105/EC and 2000/21/EC. Cinterion® modules comply with the REACH regulation that specifies a content of less than 0.1% per substance mentioned in the SVHC candidate list (Release 16.06.2014). |

Table 37: Standards of North American type approval

| | |
|------------------------------------|--|
| CFR Title 47 | Code of Federal Regulations, Part 22 and Part 24 (Telecommunications, PCS); US Equipment Authorization FCC |
| OET Bulletin 65 (Edition 97-01) | Evaluating Compliance with FCC Guidelines for Human Exposure to Radiofrequency Electromagnetic Fields |
| UL 62368-1 | Audio/video, information and communication technology equipment - Part 1: Safety requirements (for details see Section 5.1.1)  |
| NAPRD.03 V5.35 | Overview of PCS Type certification review board Mobile Equipment Type Certification and IMEI control PCS Type Certification Review board (PTCRB) |
| RSS132 (Issue2) RSS133 (Issue5) | Canadian Standard |

1. Manufacturers of applications which can be used in the US shall ensure that their applications have a PTCRB approval. For this purpose they can refer to the PTCRB approval of the respective module.

Table 38: Standards of European type approval

| | |
|--------------------------------------|---|
| 3GPP TS 51.010-1 | Digital cellular telecommunications system (Release 7); Mobile Station (MS) conformance specification; |
| GCF-CC V3.71 | Global Certification Forum - Certification Criteria |
| ETSI EN 301 511 V12.5.1 | Global System for Mobile communications (GSM); Mobile Stations (MS) equipment; Harmonized Standard covering the essential requirements of article 3.2 of Directive 2014/53/EU |
| ETSI EN 301 908-1 V11.1.1 | IMT cellular networks; Harmonised Standard covering the essential requirements of article 3.2 of the Directive 2014/53/EU; Part 1: Introduction and common requirements |
| ETSI EN 301 908-2 V11.1.2 | IMT cellular networks; Harmonised Standard covering the essential requirements of article 3.2 of the Directive 2014/53/EU; Part 2: CDMA Direct Spread (UTRA FDD) User Equipment (UE) |
| ETSI EN 301 489-52 V1.1.0 | Electromagnetic Compatibility (EMC) standard for radio equipment and services; Part 52: Specific conditions for Cellular Communication Mobile and portable (UE) radio and ancillary equipment; Harmonized Standard covering the essential requirements of article 3.1(b) of Directive 2014/53/EU |
| Draft ETSI EN 301 489-01 V2.2.0 | ElectroMagnetic Compatibility (EMC) standard for radio equipment and services; Part 1: Common technical requirements; Harmonized Standard covering the essential requirements of article 3.1(b) of Directive 2014/53/EU and the essential requirements of article 6 of Directive 2014/30/EU |
| ETSI EN 301489-19 V2.1.0 | ElectroMagnetic Compatibility (EMC) standard for radio equipment and services; Part 19: Specific conditions for Receive Only Mobile Earth Stations (ROMES) operating in the 1,5 GHz band providing data communications and GNSS receivers operating in the RNSS band (ROGNSS) providing positioning, navigation, and timing data; Harmonised Standard covering the essential requirements of article 3.1(b) of Directive 2014/53/EU |
| ETSI EN 303 413 V1.1.1 | Satellite Earth Stations and Systems (SES); Global Navigation Satellite System (GNSS) receivers; Radio equipment operating in the 1 164 MHz to 1 300 MHz and 1 559 MHz to 1 610 MHz frequency bands; Harmonised Standard covering the essential requirements of article 3.2 of Directive 2014/53/EU |
| IEC 62368-1 (EN 62368-1, UL 62368-1) | Audio/video, information and communication technology equipment - Part 1: Safety requirements (for details see Section 5.1.1) |

Table 39: Requirements of quality

| | |
|---------------|--|
| IEC 60068 | Environmental testing |
| DIN EN 60529 | IP codes |
| EN 62311:2008 | Assessment of electronic and electrical equipment related to human exposure restrictions for electromagnetic fields (0 Hz - 300 GHz) |

Table 40: Standards of the Ministry of Information Industry of the People's Republic of China

| | |
|-----------------|--|
| SJ/T 11363-2006 | "Requirements for Concentration Limits for Certain Hazardous Substances in Electronic Information Products" (2006-06). |
| SJ/T 11364-2006 | <p>"Marking for Control of Pollution Caused by Electronic Information Products" (2006-06).</p> <p>According to the "Chinese Administration on the Control of Pollution caused by Electronic Information Products" (ACPEIP) the EPUP, i.e., Environmental Protection Use Period, of this product is 20 years as per the symbol shown here, unless otherwise marked. The EPUP is valid only as long as the product is operated within the operating limits described in the Thales Hardware Interface Description.</p> <p>Please see Table 41 for an overview of toxic or hazardous substances or elements that might be contained in product parts in concentrations above the limits defined by SJ/T 11363-2006.</p> |

**Table 41:** Toxic or hazardous substances or elements with defined concentration limits

| 部件名称 Name of the part | 有毒有害物质或元素 Hazardous substances | | | | | |
|--|--------------------------------|-----------|-----------|-----------------|---------------|-----------------|
| | 铅 (Pb) | 汞 (Hg) | 镉 (Cd) | 六价铬 (Cr(VI)) | 多溴联苯 (PBB) | 多溴二苯醚 (PBDE) |
| 金属部件 (Metal Parts) | ○ | ○ | ○ | ○ | ○ | ○ |
| 电路模块 (Circuit Modules) | X | ○ | ○ | ○ | ○ | ○ |
| 电缆及电缆组件 (Cables and Cable Assemblies) | ○ | ○ | ○ | ○ | ○ | ○ |
| 塑料和聚合物部件 (Plastic and Polymeric parts) | ○ | ○ | ○ | ○ | ○ | ○ |
| <p>○: 表示该有毒有害物质在该部件所有均质材料中的含量均在SJ/T11363-2006 标准规定的限量要求以下。 Indicates that this toxic or hazardous substance contained in all of the homogeneous materials for this part is below the limit requirement in SJ/T11363-2006.</p> <p>X: 表示该有毒有害物质至少在该部件的某一均质材料中的含量超出SJ/T11363-2006标准规定的限量要求。 Indicates that this toxic or hazardous substance contained in at least one of the homogeneous materials used for this part <i>might exceed</i> the limit requirement in SJ/T11363-2006.</p> | | | | | | |

5.1.1 IEC 62368-1 Classification

With respect to the safety requirements for audio/video, information and communication technology equipment defined by the hazard based product safety standard for ICT and AV equipment - i.e., **IEC-62368-1 (EN 62368-1, UL 62368-1)** - Cinterion® modules are classified as shown below:

Standalone operation of the modules is not possible. Modules will always be incorporated in an external application (Customer Product).

Customer understands and is responsible that the product incorporating the Cinterion® module must be designed to be compliant with IEC-62368-1 (EN 62368-1, UL 62368-1) to ensure protection against hazards and injuries. When operating the Cinterion® module the external application (Customer Product) must provide safeguards not to exceed the power limits given by classification to Power Source Class 1 (15 Watts) under normal operating conditions, abnormal conditions, or in the presence of a single fault. When using a battery power supply the external application must provide safeguards not to exceed the limits defined by PS-1, as well. The external application (Customer Product) must take measures to limit the power, the voltage or the current, respectively, if required, and must provide safeguards to protect ordinary persons against pain or injury caused by the voltage/current.

In case of a usage of the Cinterion® module not in accordance with the specifications or in single fault condition the external application (Customer Product) must be capable to withstand levels according to ES-1 / PS-1 also on all ports that are initially intended for signaling or audio, e.g., USB, RS-232, GPIOs, SPI, earphone and microphone interfaces.

In addition, the external application (Customer Product) must be designed in a way to distribute thermal energy generated by the intended operation of the Cinterion® module. In case of high temperature operation, the external application must provide safeguards to protect ordinary persons against pain or injury caused by the heat.

Table 42: IEC 62368-1 Classification

| Source of Energy | Class | Limits |
|--|-------|--|
| Electrical energy source | ES-1 | The Cinterion® modules contain no electrical energy source - especially no battery. The electrical components and circuits have to be externally power supplied: DC either smaller 60 V Or less than 2 mA AC up to 1kHz smaller 30 V-rms or 42.4 V peak AC above 100kHz smaller 70 V rms |
| Power Source (potential ignition source causing fire) | PS-1 | Power source provided by the external application must not exceed 15W, even under worst case and any single fault condition defined by IEC-62368-1: Section 6.2.2.3. |

Table 42: IEC 62368-1 Classification

| Source of Energy | Class | Limits |
|--|-------|--|
| Hazardous Substances, Chemical reaction | -- | <p>Under regular conditions, the Cinterion® module does not contain any chemically reactive substances, and no chemical energy source, especially no battery.</p> <p>Module is compliant with RoHS and REACH (see above).</p> <p>In very rare cases however - under abnormal conditions (i.e. wrong supply voltage, burned module) or in the presence of single electrical component faults (i.e. shortcut) - health hazardous substances might be released if the worst comes to the worst.</p> |
| Kinetic / mechanical energy source | MS-1 | <p>The Cinterion® modules have no sharp edges and corners, no moving parts, no loosening, exploding or imploding parts.</p> <p>The mass is well below 1kg.</p> |
| Thermal energy source | TS-2 | <p>Under normal operating conditions, abnormal operating conditions or single fault conditions the temperature does not exceed +100°C on the metal surface (shielding)</p> |
| Radiated energy source | RS-1 | <p>The Cinterion® module does not contain a radiant energy source, any lasers, lamps, LEDs, X-Ray emitting components or acoustic couplers.</p> |

5.2 SAR requirements specific to portable mobiles

Mobile phones, PDAs or other portable transmitters and receivers incorporating a module must be in accordance with the guidelines for human exposure to radio frequency energy. This requires the Specific Absorption Rate (SAR) of portable TX62/TX82 based applications to be evaluated and approved for compliance with national and/or international regulations.

Since the SAR value varies significantly with the individual product design manufacturers are advised to submit their product for approval if designed for portable use. For European and US markets the relevant directives are mentioned below. The manufacturer of the end device is in the responsibility to provide clear installation and operating instructions for the user, including the minimum separation distance required to maintain compliance with SAR and/or RF field strength limits, as well as any special usage conditions required to do so, such as a required accessory, the proper orientation of the device, the max antenna gain for detachable antennas, or other relevant criteria. It is the responsibility of the manufacturer of the final product to verify whether or not further standards, recommendations or directives are in force outside these areas.

Products intended for sale on US markets

ES 59005/ANSI C95.1 Considerations for evaluation of human exposure to Electromagnetic Fields (EMFs) from Mobile Telecommunication Equipment (MTE) in the frequency range 30MHz - 6GHz

Products intended for sale on European markets

| | |
|---------------|---|
| EN 50360 | Product standard to demonstrate the compliance of mobile phones with the basic restrictions related to human exposure to electromagnetic fields (300MHz - 3GHz) |
| EN 62311:2008 | Assessment of electronic and electrical equipment related to human exposure restrictions for electromagnetic fields (0 Hz - 300 GHz) |

Please note that SAR requirements are specific only for portable devices and not for mobile devices as defined below:

- **Portable device:**
A portable device is defined as a transmitting device designed to be used so that the radiating structure(s) of the device is/are within 20 centimeters of the body of the user.
- **Mobile device:**
A mobile device is defined as a transmitting device designed to be used in other than fixed locations and to generally be used in such a way that a separation distance of at least 20 centimeters is normally maintained between the transmitter's radiating structure(s) and the body of the user or nearby persons. In this context, the term "fixed location" means that the device is physically secured at one location and is not able to be easily moved to another location.

5.3 Reference Equipment for Type Approval

The Thales reference setup submitted to type approve TX62/TX82 (including a special approval adapter for the DSB75) is shown in the following figure¹:

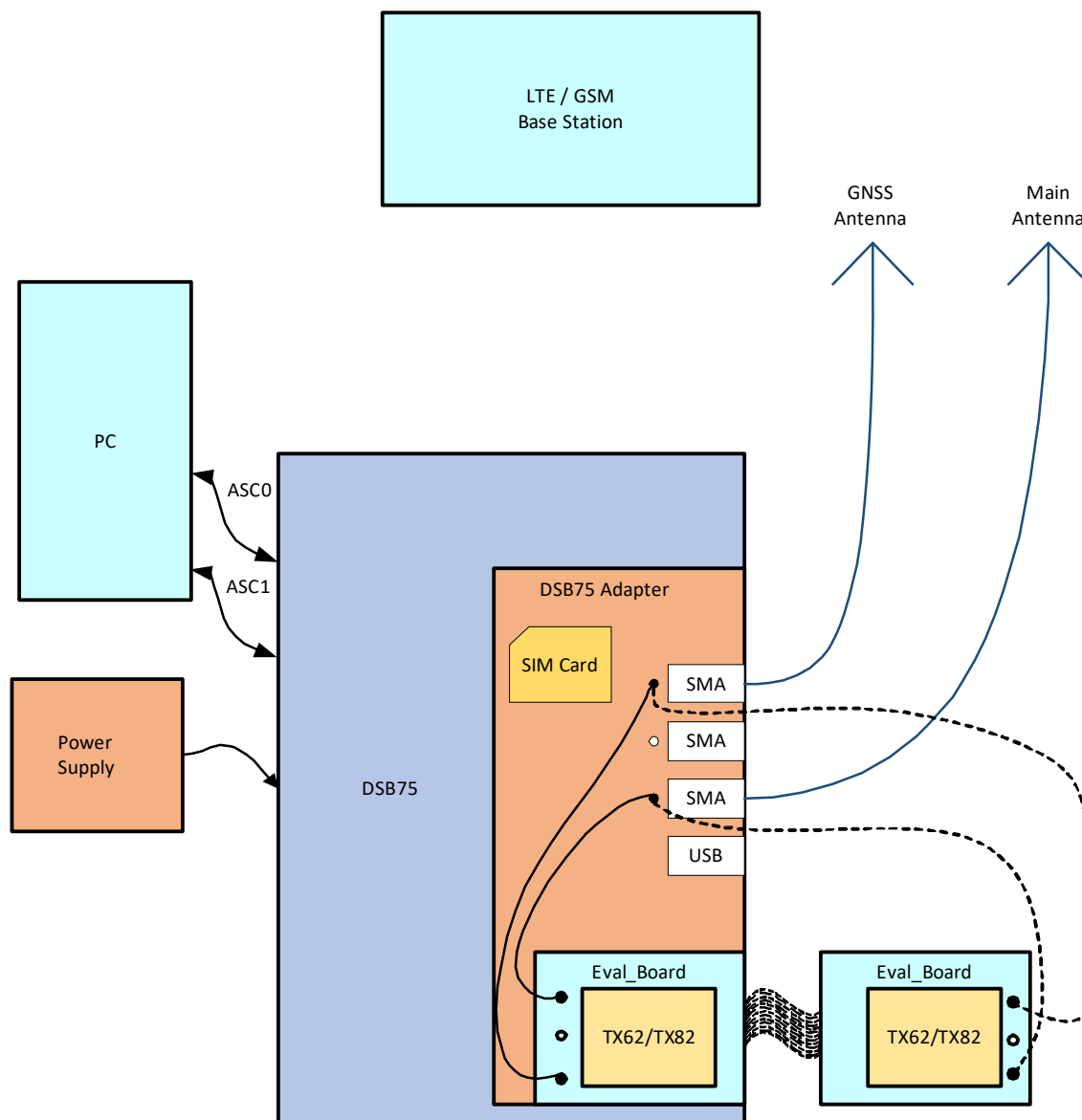


Figure 78: Reference equipment for type approval

1. For RF performance tests a mini-SMT/U.FL to SMA adapter with attached 6dB coaxial attenuator is chosen to connect the evaluation module directly to the LTE/GSM/GNSS test equipment instead of employing the SMA antenna connectors on the TX62/TX82-DSB75 adapter as shown in Figure 78. The following products are recommended:

Hirose SMA-Jack/U.FL-Plug conversion adapter HRMJ-U.FLP(40)

(for details see <http://www.hirose-connectors.com/> or <http://www.farnell.com/>)

Aeroflex Weinschel Fixed Coaxial Attenuator Model 3T/4T

(for details see <http://www.aeroflex.com/ams/weinschel/pdfs/wmod3&4T.pdf>)

5.4 Compliance with FCC and ISED Rules and Regulations

The Equipment Authorization Certification for the Thales reference application described in [Section 5.3](#) will be registered under the following identifiers:

FCC Identifier: QIPTX82-W

ISED Certification Number: 7830A-TX82W

Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPTX62-W

ISED Certification Number: 7830A-TX62W

Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPTX62-W-B

ISED Certification Number: 7830A-TX62WB

Granted to THALES DIS AIS Deutschland GmbH

FCC Identifier: QIPTX82-W-B

ISED Certification Number: 7830A-TX82WB

Granted to THALES DIS AIS Deutschland GmbH

Manufacturers of mobile or fixed devices incorporating TX62/TX82 modules are authorized to use the FCC Grants and ISED Certificates of the TX62/TX82 modules for their own final products according to the conditions referenced in these documents. In this case, an FCC/ IC label of the module shall be visible from the outside, or the host device shall bear a second label stating "Contains FCC ID: QIPTX82-W" or "Contains FCC ID: QIPTX82-W-B" or "Contains FCC ID: QIPTX62-W" or "Contains FCC ID: QIPTX62-W-B", and accordingly "Contains IC: 7830A-TX-82W" or "Contains IC: 7830A-TX82WB" or "Contains IC: 7830A-TX62W" or "Contains IC: 7830A-TX62WB". The integration is limited to fixed or mobile categorized host devices, where a separation distance between the antenna and any person of min. 20cm can be assured during normal operating conditions.

This device complies with part 15 of the FCC Rules. Operation is subject to the following two conditions: (1) This device may not cause harmful interference, and (2) this device must accept any interference received, including interference that may cause undesired operation.

For mobile and fixed operation configurations the antenna gain, including cable loss, must not exceed the limits listed in the following [Table 43](#), [Table 45](#), and [Table 46](#) for FCC and/or ISED.

Table 43: Antenna gain limits for FCC and ISED for TX82-W

| Maximum gain in operating band | FCC limit | ISED limit | All limits | Unit |
|--------------------------------|-----------|------------|------------|------|
| LTE Band 2 | 11.01 | 11.01 | 11.01 | dBi |
| LTE Band 4 | 8.00 | 8.00 | 8.00 | dBi |
| LTE Band 5 | 12.41 | 9.10 | 9.10 | dBi |
| LTE Band 12 | 11.70 | 8.61 | 8.61 | dBi |
| LTE Band 13 | 12.16 | 8.93 | 8.93 | dBi |
| LTE Band 25 | 11.01 | 11.01 | 11.01 | dBi |
| LTE Band 26 | 12.41 | 9.10 | 9.10 | dBi |
| LTE Band 66 | 8.00 | 8.00 | 8.00 | dBi |
| LTE Band 71 | 11.47 | 8.45 | 8.45 | dBi |
| LTE Band 85 | 11.60 | 8.61 | 8.61 | dBi |
| GSM850 | 8.60 | 5.30 | 5.30 | dBi |

5.4 Compliance with FCC and ISED Rules and Regulations

Table 43: Antenna gain limits for FCC and ISED for TX82-W

| Maximum gain in operating band | FCC limit | ISED limit | All limits | Unit |
|--------------------------------|-----------|------------|------------|------|
| PCS1900 | 10.20 | 10.20 | 10.20 | dBi |

Table 44: Antenna gain limits for FCC and ISED for TX82-W-B - TBD.

| Maximum gain in operating band | FCC limit | ISED limit | All limits | Unit |
|--------------------------------|-----------|------------|------------|------|
| LTE Band 2 | | | | dBi |
| LTE Band 4 | | | | dBi |
| LTE Band 5 | | | | dBi |
| LTE Band 12 | | | | dBi |
| LTE Band 13 | | | | dBi |
| LTE Band 25 | | | | dBi |
| LTE Band 26 | | | | dBi |
| LTE Band 66 | | | | dBi |
| GSM850 | | | | dBi |
| PCS1900 | | | | dBi |

Table 45: Antenna gain limits for FCC and ISED for TX62-W

| Maximum gain in operating band | FCC limit | ISED limit | All limits | Unit |
|--------------------------------|-----------|------------|------------|------|
| LTE Band 2 | 11.01 | 11.01 | 11.01 | dBi |
| LTE Band 4 | 8.00 | 8.00 | 8.00 | dBi |
| LTE Band 5 | 12.41 | 9.10 | 9.10 | dBi |
| LTE Band 12 | 11.70 | 8.61 | 8.61 | dBi |
| LTE Band 13 | 12.16 | 8.93 | 8.93 | dBi |
| LTE Band 25 | 11.01 | 11.01 | 11.01 | dBi |
| LTE Band 26 | 12.41 | 9.10 | 9.10 | dBi |
| LTE Band 66 | 8.00 | 8.00 | 8.00 | dBi |
| LTE Band 71 | 11.47 | 8.45 | 8.45 | dBi |
| LTE Band 85 | 11.60 | 8.61 | 8.61 | dBi |

Table 46: Antenna gain limits for FCC and ISED for TX62-W-B

| Maximum gain in operating band | FCC limit | ISED limit | All limits | Unit |
|--------------------------------|-----------|------------|------------|------|
| LTE Band 2 | 8.01 | 8.01 | 8.01 | dBi |
| LTE Band 4 | 5.00 | 5.00 | 5.00 | dBi |
| LTE Band 5 | 9.41 | 6.10 | 6.10 | dBi |
| LTE Band 8 | 9.70 | --- | 9.70 | dBi |
| LTE Band 12 | 8.70 | 5.61 | 5.61 | dBi |
| LTE Band 13 | 9.16 | 5.93 | 5.93 | dBi |
| LTE Band 25 | 8.01 | 8.01 | 8.01 | dBi |

5.4 Compliance with FCC and ISED Rules and Regulations

Table 46: Antenna gain limits for FCC and ISED for TX62-W-B

| Maximum gain in operating band | FCC limit | ISED limit | All limits | Unit |
|--------------------------------|-----------|------------|------------|------|
| LTE Band 26 | 9.41 | 6.10 | 6.10 | dBi |
| LTE Band 66 | 5.00 | 5.00 | 5.00 | dBi |
| LTE Band 71 | 8.47 | 5.45 | 5.45 | dBi |
| LTE Band 85 | 8.60 | 5.61 | 5.61 | dBi |

IMPORTANT:

Manufacturers of portable applications incorporating TX62/TX82 modules are required to have their final product certified and apply for their own FCC Grant and ISED Certificate related to the specific portable mobile. This is mandatory to meet the SAR requirements for portable mobiles (see [Section 5.2](#) for detail).

Changes or modifications not expressly approved by the party responsible for compliance could void the user's authority to operate the equipment.

Note: This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to part 15 of the FCC Rules and with ISED license-exempt RSS standard(s). These limits are designed to provide reasonable protection against harmful interference in a residential installation. This equipment generates, uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one or more of the following measures:

- Reorient or relocate the receiving antenna.
- Increase the separation between the equipment and receiver.
- Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- Consult the dealer or an experienced radio/TV technician for help.

This Class B digital apparatus complies with Canadian ICES-003.

If Canadian approval is requested for devices incorporating TX62/TX82 modules the below notes will have to be provided in the English and French language in the final user documentation. Manufacturers/OEM Integrators must ensure that the final user documentation does not contain any information on how to install or remove the module from the final product.

Notes (ISED):

(EN) This Class B digital apparatus complies with Canadian ICES-003 and RSS-210. Operation is subject to the following two conditions: (1) this device may not cause interference, and (2) this device must accept any interference, including interference that may cause undesired operation of the device.

(FR) Cet appareil numérique de classe B est conforme aux normes canadiennes ICES-003 et RSS-210. Son fonctionnement est soumis aux deux conditions suivantes: (1) cet appareil ne doit pas causer d'interférence et (2) cet appareil doit accepter toute interférence, notamment les interférences qui peuvent affecter son fonctionnement.

(EN) Radio frequency (RF) Exposure Information

The radiated output power of the Wireless Device is below the Innovation, Science and Economic Development Canada (ISED) radio frequency exposure limits. The Wireless Device should be used in such a manner such that the potential for human contact during normal operation is minimized.

This device has also been evaluated and shown compliant with the ISED RF Exposure limits under mobile exposure conditions. (antennas are greater than 20cm from a person's body).

(FR) Informations concernant l'exposition aux fréquences radio (RF)

La puissance de sortie émise par l'appareil de sans fil est inférieure à la limite d'exposition aux fréquences radio d'Innovation, Sciences et Développement économique Canada (ISDE). Utilisez l'appareil de sans fil de façon à minimiser les contacts humains lors du fonctionnement normal.

Ce périphérique a également été évalué et démontré conforme aux limites d'exposition aux RF d'ISDE dans des conditions d'exposition à des appareils mobiles (les antennes se situent à moins de 20cm du corps d'une personne).

5.5 Compliance with Korean Rules and Regulations (TX62-W-B)

The TX62-W-B reference application described in [Section 5.3](#) complies with the requirements of the Korean Certification (KC).

The certificate granted in accordance with KC has the identifier:

R-C-QIP-TX62-W-B



Identifier and the KC (certification) logo are part of the module's label.

Please note that TX62-W-B is has been certified under Clause 2, Article 58-2 of the Radio Waves Act as described in [Figure 79](#).



Figure 79: Radio equipment certification

6 Document Information

6.1 Revision History

Preceding document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200c

New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" **v01.200d**

| Chapter | What is new |
|---------|-------------------------------------|
| 5.4 | Table 43 band 85 information added. |

Preceding document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200b

New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200c

| Chapter | What is new |
|---------------------|---|
| Throughout document | Revised Figure 24, Figure 37, Figure 39, and Figure 40 to indicate High/Low signal level. |
| 2.1.2 | Revised V_{Imin} for VUSB_IN. |
| 4.3.3.1 | Revised reflow profile. |

Preceding document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200a

New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200b

| Chapter | What is new |
|---------------------|---|
| Throughout document | Revised support for LTE Cat NB1/2 as well as selected frequency bands for TX62-W-C. |
| 2.1 | Added note for output power regarding duty cycle for Cat M1 UL signals (TX62-W-C). |
| 2.1.11.3 | Revised complete section on fast shutdown. |
| 3.2.1.1 | Revised ON startup timing description. |
| 3.2.2.2 | Revised EMERG_RST timing description. |
| 3.2.4.1 | Revised module switch off timing description. |
| 3.4.1 | Revised output power setting for Band 31 and 72 (TX62-W-C; 26dBm --> 23dBm) |
| 7.1 | Updated ordering information for TX62-W-C. |

Preceding document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200

New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200a

| Chapter | What is new |
|---------------------|--|
| Throughout document | Added TX82-W-B as supported product variant. |
| 2.3.3 | Revised horizontal accuracy rating. |
| 7.1 | Updated ordering information. |

Preceding document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.000

New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.200

6.1 Revision History

| Chapter | What is new |
|-----------------------|--|
| 3.4.1 | Updated power supply ratings for TX62-W-C. |
| 4.2 | Updated section showing mechanical dimensions. |

Preceding document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.026b
 New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v01.000

| Chapter | What is new |
|--|--|
| Throughout document | Added new Variant: TX62-W-C. |
| 2.1.2 , 3.2.1.1 | Revised high level pulse width for ON signal (1ms --> 30ms). |
| 2.1.6.1 | Revised Figure 15 showing enhanced ESD protection for SIM interface. |
| 2.1.7 | Added configuration of dual mode. |
| 2.1.11.3 | Added note on FST_SHDN line becoming active only 3 seconds after module startup. |
| 2.4 | Revised Figure 34 . |
| 3.2.1.1 | Added pull-down resistor in Figure 36 . |
| 3.2.1.2 | New section Automatic Power On . |
| 3.2.4.1 | Clarified description of regular switch off behavior. Added note mentioning differences in switch of timing between Cat M1 and Cat NB1/2. |
| 4.2 | Updated section showing mechanical dimensions. |
| 4.3 | Added note regarding placement of external components. |
| 5.4 | Added Table 43 , Table 45 , and Table 46 with FCC and ISED antenna gain limits. |
| 5.5 | New section Compliance with Korean Rules and Regulations (TX62-W-B) . |
| 7.2 | Updated module label information. |

Preceding document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.026a
 New document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.026b

| Chapter | What is new |
|---|--|
| 2.1.1 | Revised G15/G16 pad assignments, and removed superfluous footnote in Table 3 . |
| 2.1.2 | Revised Table 4 : No internal pull up resistors for I ² C lines. |
| 2.1.4 , 2.1.5 | Added note below Figure 11 and Figure 13 explaining dotted lines. |
| 2.1.7 | Revised Figure 16 . Added Figure 17 showing how to connect eUICC to module's SIM interface lines. |
| 2.1.8.1 | Revised GPIO availability with embedded processing option, and adapted whole document accordingly. |
| 2.2.1 | Removed "Max." column from Table 11 and Table 12 . |
| 3.2.2.2 | Revised description of the emergency restart process. |
| 3.2.4.1 | Added note that worst fast shutdown time cannot be specified. |
| 3.4.1 | Added power supply ratings for TX62-W-B and TX82-W. |

6.1 Revision History

| Chapter | What is new |
|-----------------------|---|
| 5.1 | Replaced UL 60950 with UL 62368-1 in Table 37 . |
| 5.1.1 | Completed Table 42 regarding hazardous substances, chemical reaction. |
| 5.2 | Added remark regarding responsibility of the end device manufacturer. |

Preceding document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.026

New document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.026a

| Chapter | What is new |
|-----------------------|--|
| 3.4.1 | Added power supply ratings for TX62-W. |

Preceding document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.022a

New document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.026

| Chapter | What is new |
|-----------------------|---|
| 1.1 | Revised version of TX62-W-B |
| 2.1.8 | Revised Figure 19 |
| 5.1 | Added REACH directive to Table 36 |
| 5.1 | Change Safety Standard to IEC 62368-1 in Table 38 |
| 5.1.1 | New chapter regarding IEC 62368-1 Classification |
| 7.1 | Revised ordering and module label numbers in Table 47 |

Preceding document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.022

New document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.022a

| Chapter | What is new |
|-------------------------|---|
| Throughout document | Adapted GSM voltage range (3.1V...4.6V) |
| 1.4 | Revised block diagrams Figure 3 , Figure 4 , and Figure 5 . |
| 2.1.4 | Revised Figure 11 , and changed Table 18 accordingly. |
| 2.2.1 | Revised receiver input sensitivity ratings in Table 11 and Table 12 . |
| 3.2.2.2 | Revised Figure 39 . |

Preceding document: "Cinterion® TXx2-W Hardware Interface Description" v00.016

New document: "Cinterion® TX62-W(-B)/TX82-W Hardware Interface Description" v00.022

| Chapter | What is new |
|-----------------------|--|
| Throughout document | Added details about the embedded processing option. Revised supported footprint for TX62-W-B. Replaced MIM with eUICC. |
| 2.1.2 | Added signal properties for eUICC interface lines. |
| 2.1.4 | Revised Figure 11 . |

6.1 Revision History

| | |
|---------|--|
| 4.3.1.1 | Revised stencil shown in Figure 64 . |
| 7.1 | Updated ordering information. |

Preceding document: "Cinterion® TXx2-W Hardware Interface Description" v00.002

New document: "Cinterion® TXx2-W Hardware Interface Description" v00.016

| Chapter | What is new |
|---------------------|--|
| Throughout document | Added product TX82-W and TX62-W-B |
| 1.2 | Added GPIO to Key Feature at a Glance |
| 2.1.1 | Added Table 2 for Pad Assignment of additional Pads of TX82-W |
| 2.1.1 | Revised Pad Assignment regarding GPIO in Table 2 , Table 3 , Figure 7 and Figure 8 |
| 2.1.2 | Revised Signal Properties regarding GPIO in Table 4 |
| 2.1.8 | Added new chapter for GPIO |
| 2.4 | Revised Sample Application regarding GPIO and USB in Figure 34 |
| 3.2.3 | Revised Table 18 regarding GPIO, corrected some signal states |
| 3.7 | Revised Table 31 regarding GPIO, removed USB signals |
| 6.1 | Revised changes for document version 00.002 |

Preceding document: "Cinterion® TXx2-W Hardware Interface Description" v00.200a

New document: "Cinterion® TXx2-W Hardware Interface Description" v00.002

| Chapter | What is new |
|---------------------|--|
| Throughout document | Removed product TX82-W, thus the document version number restarted to 00.002 |
| 1.2, 2.1.2, 3.4.1 | Changed minimum BATT _{+BB} from 2.5V to 2.55V in Table 4 and Table 23 |
| 1.2, 4.1 | Changed hight of the module in Feature at a Glance and in Figure 54 and Figure 55 |
| 2.1.2 | Revised ON signal description in Table 4 |
| 2.1.6 | Added in Figure 14 hint where to place the capacitors |
| 2.1.6.1 | Added hint where to place the capacitors |
| 2.1.7 | Revised Figure 16 added reference to chapter 2.1.6.1 |
| 2.2.1 | Updated Table 11 |
| 2.2.3 | Revised Figure 28 , Figure 29 , Figure 30 , Figure 31 and Figure 32 according to the footprint of TX62-W |
| 3.4.3 | Revised chapter and Figure 51 regarding GND reference point |
| 3.7 | Added placement of capacitors in Table 31 for SIM interface signals |
| 4.1 | Revised Figure 56 |

6.1 Revision History

| Chapter | What is new |
|---------|---|
| 4.3.1.1 | Changed Stencil thickness to 110µm and Stencil pattern in Figure 63 |
| 4.4.1.1 | Revised Figure 66 and Figure 67 |

Preceding document: "Cinterion® TXX2-W Hardware Interface Description" v00.200

New document: "Cinterion® TXX2-W Hardware Interface Description" v00.200a

| Chapter | What is new |
|---------|--|
| 1.2 | Removed extended voltage range and changed eUICC size MFF2 to MFF-XS |
| 1.3 | Revised Figure 1 regarding eUICC size |
| 1.4 | Removed in Figure 3 signal ADC2 |
| 2.1.2 | Removed extended voltage range in Table 4 |
| 2.4 | Removed in Figure 34 wrong PAD numbers |
| 3.4.1 | Removed extended voltage range in Table 23 |
| 4.2 | Revised Figure 57 |

Preceding document: "Cinterion® TXX2-W Hardware Interface Description" v00.038

New document: "Cinterion® TXX2-W Hardware Interface Description" v00.200

| Chapter | What is new |
|---------------------|--|
| - | New document layout |
| Throughout document | Removed LTE Bd14. Renamed LTE Bd4 (AWS --> AWS-1), LTE Bd66 (1700MHz --> AWS-3). Added support for optional eUICC interface. |
| 1.2 | Added references from key feature list to appropriate document sections. |
| 1.2 | Added support for Cinterion® IoT Module services (MODS) as key feature. |
| 2.1.1 | Revised Note 2 of Table 3 |
| 2.1.2 | Revised Table 4 related to power supply |
| 2.1.2.1 | Added absolute maximum ratings for digital lines in normal operation. |
| 2.1.7 | New section eUICC Interface . |
| 2.1.11.2 | Adapted power indication circuit shown in Figure 23 . |
| 2.1.11.3 | Revised fast shutdown description. |
| 2.3.1 | Added note that concurrent GNSS and GSM/LTE operations are not supported. |
| 2.3.2 | Revised description for active GNSS antenna and Figure 33 |
| 2.3.3 | Revised Table 14 listing GNSS antenna interface characteristics. |
| 2.4 | Revised Figure 34 |
| 3.2.3 | Revised section Signal States after Startup including Table 14 . |

| Chapter | What is new |
|-------------------------|--|
| 3.4.1 | Revised Table 23 related to power supply |
| 4.2 | New section Mechanical Dimensions of TX82-W, TX82-W-B, TX62-W-B and TX62-W-C |
| 4.3.1.1 | Added Land pattern and Stencil for TX82-W |

New document: "Cinterion® TX62-W/TX82-W Hardware Interface Description" v00.038

| Chapter | What is new |
|---------|-------------------------|
| -- | Initial document setup. |

6.2 Related Documents

- [1] TX62/TX82 AT Command Set
- [2] TX62/TX82 Release Note
- [3] Universal Serial Bus Specification Revision 2.0, April 27, 2000
- [4] Application Note 40: Thermal Solutions for Cinterion® TXx2-W Applications
- [5] Application Note 48: SMT Module Integration
- [6] Differences between Selected Cinterion® Modules, Hardware Migration Guide, v11
- [7] Cinterion® IoT Suite User Guide for TXx2-W modules
- [8] [Cinterion® IoT Suite Online Documentation](#)
- [9] Cinterion® IoT SDK User Guide, v01

6.3 Terms and Abbreviations

| Abbreviation | Description |
|--------------|--|
| ADC | Analog-to-digital converter |
| AGC | Automatic Gain Control |
| ANSI | American National Standards Institute |
| ARFCN | Absolute Radio Frequency Channel Number |
| ARP | Antenna Reference Point |
| ASC0/ASC1 | Asynchronous Controller. Abbreviations used for first and second serial interface of TX62/TX82 |
| B | Thermistor Constant |
| BER | Bit Error Rate |
| BTS | Base Transceiver Station |
| CB or CBM | Cell Broadcast Message |
| CE | Conformité Européene (European Conformity) |
| CHAP | Challenge Handshake Authentication Protocol |
| CPU | Central Processing Unit |
| CS | Coding Scheme |
| CSD | Circuit Switched Data |

6.3 Terms and Abbreviations

| Abbreviation | Description |
|--------------|--|
| CTS | Clear to Send |
| DAC | Digital-to-Analog Converter |
| DAI | Digital Audio Interface |
| dBm0 | Digital level, 3.14dBm0 corresponds to full scale, see ITU G.711, A-law |
| DCE | Data Communication Equipment (typically modems, e.g. Thales module) |
| DCS 1800 | Digital Cellular System, also referred to as PCN |
| DRX | Discontinuous Reception |
| DSB | Development Support Box |
| DSP | Digital Signal Processor |
| DSR | Data Set Ready |
| DRX | Discontinuous Reception |
| DTE | Data Terminal Equipment (typically computer, terminal, printer or, for example, GSM application) |
| DTR | Data Terminal Ready |
| DTX | Discontinuous Transmission |
| EFR | Enhanced Full Rate |
| EGSM | Enhanced GSM |
| EIRP | Equivalent Isotropic Radiated Power |
| EMC | Electromagnetic Compatibility |
| EMI | Electromagnetic Interference |
| ERP | Effective Radiated Power |
| ESD | Electrostatic Discharge |
| ETS | European Telecommunication Standard |
| FCC | Federal Communications Commission (U.S.) |
| FDMA | Frequency Division Multiple Access |
| FR | Full Rate |
| GMSK | Gaussian Minimum Shift Keying |
| GPRS | General Packet Radio Service |
| GSM | Global Standard for Mobile Communications |
| HiZ | High Impedance |
| HR | Half Rate |
| I/O | Input/Output |
| IC | Integrated Circuit |
| IMEI | International Mobile Equipment Identity |
| ISO | International Standards Organization |
| ITU | International Telecommunications Union |
| kbps | kbits per second |
| LED | Light Emitting Diode |

6.3 Terms and Abbreviations







| Abbreviation | Description |
|--------------|--|
| Li-Ion/Li+ | Lithium-Ion |
| Li battery | Rechargeable Lithium Ion or Lithium Polymer battery |
| LPM | Link Power Management |
| Mbps | Mbits per second |
| MMI | Man Machine Interface |
| MO | Mobile Originated |
| MS | Mobile Station (GSM module), also referred to as TE |
| MSISDN | Mobile Station International ISDN number |
| MT | Mobile Terminated |
| NTC | Negative Temperature Coefficient |
| OEM | Original Equipment Manufacturer |
| PA | Power Amplifier |
| PAP | Password Authentication Protocol |
| PBCCH | Packet Switched Broadcast Control Channel |
| PCB | Printed Circuit Board |
| PCL | Power Control Level or Paging Cycle Length |
| PCM | Pulse Code Modulation |
| PCN | Personal Communications Network, also referred to as DCS 1800 |
| PDU | Protocol Data Unit |
| PLL | Phase Locked Loop |
| PPP | Point-to-point protocol |
| PSK | Phase Shift Keying |
| PSU | Power Supply Unit |
| PTW | Paging Time Window |
| R&TTE | Radio and Telecommunication Terminal Equipment |
| RAM | Random Access Memory |
| RF | Radio Frequency |
| RLS | Radio Link Stability |
| RMS | Root Mean Square (value) |
| RoHS | Restriction of the use of certain hazardous substances in electrical and electronic equipment. |
| ROM | Read-only Memory |
| RTC | Real Time Clock |
| RTS | Request to Send |
| Rx | Receive Direction |
| SAR | Specific Absorption Rate |
| SAW | Surface Acoustic Wave |
| SELV | Safety Extra Low Voltage |

6.3 Terms and Abbreviations

| Abbreviation | Description |
|--------------|---|
| SIM | Subscriber Identification Module |
| SMD | Surface Mount Device |
| SMS | Short Message Service |
| SMT | Surface Mount Technology |
| SPI | Serial Peripheral Interface |
| SRAM | Static Random Access Memory |
| TA | Terminal adapter (e.g. GSM module) |
| TDMA | Time Division Multiple Access |
| TE | Terminal Equipment, also referred to as DTE |
| TLS | Transport Layer Security |
| Tx | Transmit Direction |
| UART | Universal asynchronous receiver-transmitter |
| URC | Unsolicited Result Code |
| USSD | Unstructured Supplementary Service Data |
| VSWR | Voltage Standing Wave Ratio |

6.4 Safety Precaution Notes

The following safety precautions must be observed during all phases of the operation, usage, service or repair of any cellular terminal or mobile incorporating TX62/TX82. Manufacturers of the cellular terminal are advised to convey the following safety information to users and operating personnel and to incorporate these guidelines into all manuals supplied with the product. Failure to comply with these precautions violates safety standards of design, manufacture and intended use of the product. Thales assumes no liability for customer's failure to comply with these precautions.

| | |
|---|--|
|  | When in a hospital or other health care facility, observe the restrictions on the use of mobiles. Switch the cellular terminal or mobile off, if instructed to do so by the guidelines posted in sensitive areas. Medical equipment may be sensitive to RF energy. The operation of cardiac pacemakers, other implanted medical equipment and hearing aids can be affected by interference from cellular terminals or mobiles placed close to the device. If in doubt about potential danger, contact the physician or the manufacturer of the device to verify that the equipment is properly shielded. Pacemaker patients are advised to keep their hand-held mobile away from the pacemaker, while it is on. |
|  | Switch off the cellular terminal or mobile before boarding an aircraft. Make sure it cannot be switched on inadvertently. The operation of wireless appliances in an aircraft is forbidden to prevent interference with communications systems. Failure to observe these instructions may lead to the suspension or denial of cellular services to the offender, legal action, or both. |
|  | Do not operate the cellular terminal or mobile in the presence of flammable gases or fumes. Switch off the cellular terminal when you are near petrol stations, fuel depots, chemical plants or where blasting operations are in progress. Operation of any electrical equipment in potentially explosive atmospheres can constitute a safety hazard. |
|  | Your cellular terminal or mobile receives and transmits radio frequency energy while switched on. Remember that interference can occur if it is used close to TV sets, radios, computers or inadequately shielded equipment. Follow any special regulations and always switch off the cellular terminal or mobile wherever forbidden, or when you suspect that it may cause interference or danger. |
|  | Road safety comes first! Do not use a hand-held cellular terminal or mobile when driving a vehicle, unless it is securely mounted in a holder for speakerphone operation. Before making a call with a hand-held terminal or mobile, park the vehicle. Speakerphones must be installed by qualified personnel. Faulty installation or operation can constitute a safety hazard. |
|  | IMPORTANT! Cellular terminals or mobiles operate using radio signals and cellular networks. Because of this, connection cannot be guaranteed at all times under all conditions. Therefore, you should never rely solely upon any wireless device for essential communications, for example emergency calls. Remember, in order to make or receive calls, the cellular terminal or mobile must be switched on and in a service area with adequate cellular signal strength. Some networks do not allow for emergency calls if certain network services or phone features are in use (e.g. lock functions, fixed dialing etc.). You may need to deactivate those features before you can make an emergency call. Some networks require that a valid SIM card be properly inserted in the cellular terminal or mobile. |

7 Appendix

7.1 List of Parts and Accessories

Table 47: List of parts and accessories

| Description | Supplier | Ordering information |
|-------------|----------|--|
| TX62-W | Thales | <p>Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6300-A130 Module label number¹: S30960-S6300-A130-1</p> <p>Standard module with AT&T and Verizon approval Thales IMEI: Packaging unit (ordering) number: L30960-N6300-B130 Module label number¹: S30960-S6300-B130-1</p> <p>Standard module with embedded MFF-XS eUICC Thales IMEI: Packaging unit (ordering) number: L30900-N6307-A140 Module label number¹: S30900-S6307-A140-1</p> <p>Customer IMEI mode: Packaging unit (ordering) number: L30960-N6305-A130 Module label number¹: S30960-S6305-A130-1</p> |
| TX62-W-B | Thales | <p>Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6650-A130 Module label number¹: S30960-S6650-A130-1</p> <p>Standard module with AT&T and Verizon approval Thales IMEI: Packaging unit (ordering) number: L30960-N6650-B130 Module label number¹: S30960-S6650-B130-1</p> <p>Standard module (Korean variant) Thales IMEI: Packaging unit (ordering) number: L30960-N6650-K100 Module label number¹: S30960-S6650-K100-1</p> <p>Standard module with embedded MFF-XS eUICC Thales IMEI: Packaging unit (ordering) number: L30900-N6657-A140 Module label number¹: S30900-S6657-A140-1</p> <p>Customer IMEI mode: Packaging unit (ordering) number: L30960-N6655-A130 Module label number¹: S30960-S6655-A130-1</p> |
| TX62-W-C | Thales | <p>Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6660-A200 Module label number¹: L30960-N6660-A200-1</p> |

7.1 List of Parts and Accessories

Table 47: List of parts and accessories

| Description | Supplier | Ordering information |
|-----------------------------------|----------|--|
| TX82-W | Thales | <p>Standard module Thales IMEI: Packaging unit (ordering) number: L30960-N6600-A130 Module label number¹: S30960-S6600-A130-1.</p> <p>Standard module with AT&T and Verizon approval Thales IMEI: Packaging unit (ordering) number: L30960-N6600-B130 Module label number¹: S30960-S6600-B130-1.</p> <p>Standard module with embedded MFF-XS eUICC Thales IMEI: Packaging unit (ordering) number: L30900-N6607-A140 Module label number¹: S30900-S6607-A140-1</p> <p>Customer IMEI mode: Packaging unit (ordering) number: L30960-N6605-A130 Module label number¹: S30960-S6605-A130-1</p> |
| TX82-W-B | Thales | <p>Standard module Thales IMEI: Packaging unit (ordering) number: TBD. Module label number¹: TBD.</p> <p>Standard module with embedded MFF-XS eUICC Thales IMEI: Packaging unit (ordering) number: TBD. Module label number¹: TBD.</p> <p>Customer IMEI mode: Packaging unit (ordering) number: TBD. Module label number¹: TBD.</p> |
| TX62-W Evaluation Module | Thales | Standard module Ordering number: L30960-N6301-A100 |
| TX62-W-B Evaluation Module | Thales | Standard module Ordering number: L30960-N6651-A100 |
| TX62-W-C Evaluation Module | Thales | Standard module Ordering number: L30960-N6661-A200 |
| TX82-W Evaluation Module | Thales | <p>Standard module Ordering number: L30960-N6601-A100</p> <p>Standard module with embedded MFF-XS eUICC Ordering number: L30900-N6608-A140</p> |
| TX82-W Evaluation Module | Thales | Standard module Ordering number: TBD. |
| DSB75 Evaluation Kit | Thales | Ordering number: L36880-N8811-A100 |
| DSB Mini Compact Evaluation Board | Thales | Ordering number: L30960-N0030-A100 |

7.1 List of Parts and Accessories

Table 47: List of parts and accessories

| Description | Supplier | Ordering information |
|---|----------|--|
| LGA DevKit | Thales | LGA DevKit consists of Cinterion® LGA DevKit T Base PCB: Ordering number: L30960-N0113-A100 Cinterion® LGA DevKit Socket T: Ordering number: L30960-N0114-A100 |
| EVAL DSB Adapter for mounting TX62/TX82 evaluation modules onto DSB75 | Thales | Ordering number: L30960-N0100-A100 |
| SIM card holder incl. push button ejector and slide-in tray | Molex | Ordering numbers: 91228 91236 Sales contacts are listed in Table 48 . |

1. Note: At the discretion of Thales, module label information can either be laser engraved on the module's shielding or be printed on a label adhered to the module's shielding.

Table 48: Molex sales contacts (subject to change)

| | | |
|--|--|--|
| Molex For further information please click: http://www.molex.com | Molex Deutschland GmbH Otto-Hahn-Str. 1b 69190 Walldorf Germany Phone: +49-6227-3091-0 Fax: +49-6227-3091-8100 Email: mxgermany@molex.com | American Headquarters Lisle, Illinois 60532 U.S.A. Phone: +1-800-78MOLEX Fax: +1-630-969-1352 |
| Molex China Distributors Beijing, Room 1311, Tower B, COFCO Plaza No. 8, Jian Guo Men Nei Street, 100005 Beijing P.R. China Phone: +86-10-6526-9628 Fax: +86-10-6526-9730 | Molex Singapore Pte. Ltd. 110, International Road Jurong Town, Singapore 629174 Phone: +65-6-268-6868 Fax: +65-6-265-6044 | Molex Japan Co. Ltd. 1-5-4 Fukami-Higashi, Yamato-City, Kanagawa, 242-8585 Japan Phone: +81-46-265-2325 Fax: +81-46-265-2365 |

7.2 Module Label Information

The label engraved on the top of TX62/TX82 comprises the following information.

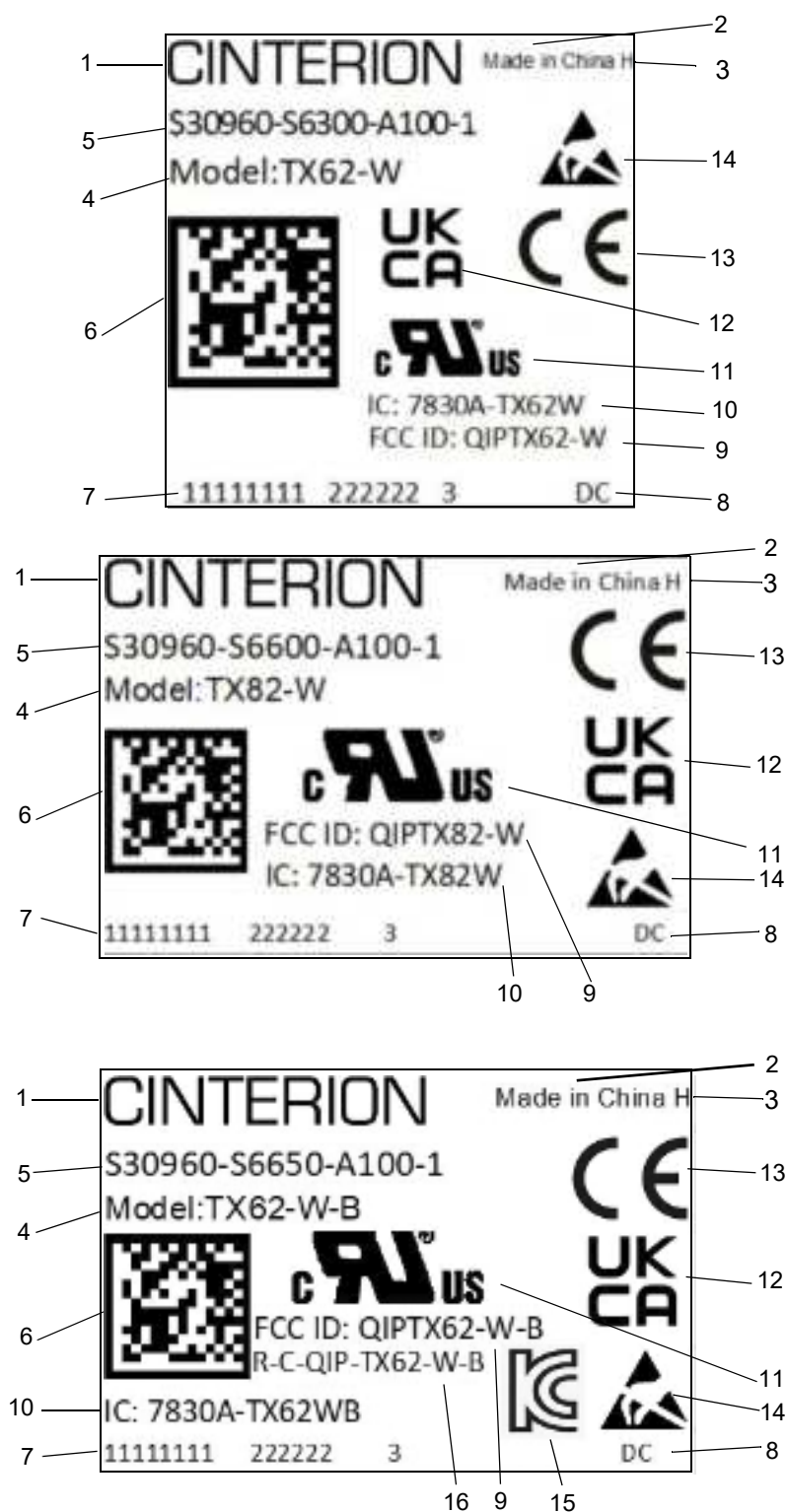
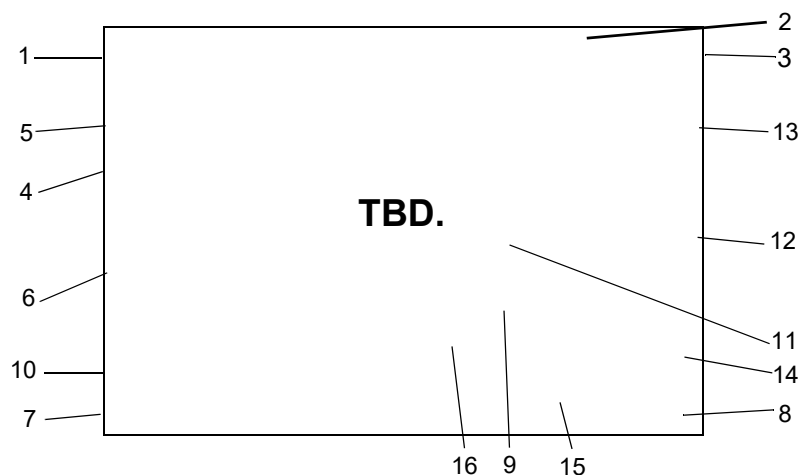


Figure 80: TX62/TX82/TX62-W-B label

**Figure 81:** TX82-W-B label**Table 49:** TX62/TX82 label information

| No. | |
|-----|---|
| 1 | Cinterion logo |
| 2 | Manufacturing country (e.g., “Made in China”) |
| 3 | Factory code (e.g. “H”) |
| 4 | Product name/variant (e.g., “TX62-W”) |
| 5 | Product order code |
| 6 | Manufacturer 2D barcode |
| 7 | Product IMEI |
| 8 | 2-digit date code of product production (for decoding see Table 50 below) |
| 9 | FCC ID |
| 10 | IC ID |
| 11 | Underwriters Laboratories (UL) mark |
| 12 | United Kingdom Conformity Assessed (UKCA) mark |
| 13 | European Conformity (CE) mark |
| 14 | Electrostatic-sensitive device symbol |
| 15 | Korean Certification (KC) mark |
| 16 | Korean Certification Identifier |

Table 50: Date code table

| Date Code | | | | | | | | | | | | |
|-----------|------|------|------|------|------|------|------|------|-------|------|------|------|
| Code | L | M | N | P | R | S | T | U | V | W | X | A |
| Year | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 | 2025 | 2026 | 2027 | 2028 | 2029 | 2030 |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |
| Month | Jan. | Feb. | Mar. | Apr. | May | June | July | Aug. | Sept. | Oct. | Nov. | Dec. |



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